# Structure prediction for cobalt-rich decagonal A IC oN ifrom pair potentials 

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#### Abstract

A system atic, decoration-based technique to discover the atom ic structure of a decagonal quasicrystal, given pair potentials and experim entally m easured lattice constants, is applied to the \basic" cobalt-rich decagonalA l-C o-N iquasicrystal. First lattice-gas M onte C arlo sim ulations are perform ed, assum ing the atom ic sites are vertices of a rhom bus tiling $w$ ith edge 2.45 A . This phase is found to be dom inated by 13A diam eter decagon-shaped clusters, each with a pentagon of C 0 atom s at the center. T hese, and another sm aller cluster, decorate vertices of a \binary tiling" with rhom bus edge 10.4A. Further sim ulations with a restricted site list show that A larrangem ents on the borders of the 13A decagon cluster form H exagon, B oat, and Star tiles w ith edge 2.45A; they indicate speci c sites for Co versus N i atom s , and how the structure adapts to sm all com position changes. In the second half of the paper, relaxation (augm ented by molecular dynam ics annealing) is used to obtain realistic structures. The dom inant new feature is a set of linear \channels" attractive to A latom s and running transverse to the layers. E ach is typically occupied by three atom s in four layers, im plying puckering and a spontaneous period doubling to c 8 A. Puckering favors pentagonal long range order of the cluster orientations. O ur sim ulation captures $m$ ost features of the related $W$-A 1 C oN i crystal, except for its pentagonalbipyram id $m$ otif.


PACS num bers: 61.44 Br , $Q$ uasicrystals 61.50 Lt , 61.66 D k , of speci c crystalline solids : [Alloys] $64.60 . \mathrm{C} \mathrm{n}$ transform ations;

## I. INTRODUCTION

This paper recounts the results of a pro ject to sim ulate the structure of decagonal quasicrystal A lum inum N ickel-C obalt $\mathrm{d}(\mathrm{A} \mathbb{C} \circ \mathrm{N}$ i) in the \basic $\mathrm{C} \circ$ " (cobalt rich) phase purely from energy $m$ inim ization principles. Of the equilibrium decagonal quasicrystals, $d(A \mathbb{C} \circ N$ i) has (in som eofitsm odi cations) the highest structuralquality and has received the $m$ ost study. Studies of the phase diagram indicate that, e.g., decagonald ( $\mathrm{Al}_{72: 5} \mathrm{Co}_{18} \mathrm{~N}$ ig:5) is stable (at higher tem peratures only), whereas d(A $\mathbb{C} \circ$ ) is m etastable on $\mathrm{Hy}^{\frac{4}{4}}$.

Recently, a com putational approach w as proposed for discovering the atom ic structure of any decagonal quasicrystal, given no in form ation except a set of pair potentials, the quasilattice constant, and the periodic lattice constant; it was applied rst to $d(A \mathbb{C} \circ \mathrm{~N}$ i) in the \basic N i" phase,13,14. In the study described here (and brie $y$ reported elsew here ${ }^{15,16}$ ), the sam e approach is applied to \basic Co" for the rst tim e, and shown to work. As in the \basic $N$ i" case, our nal structure description is in term $s$ of a supertiling $w$ ith a large quasilattice constant, but here di erent clusters and tiles enter than in the \basic N i" case.

Since the sensitivity of the structure to the precise com position is one of the issues in this paper (e.g. in Sec IIIG, and since know n structures of crystalline \approxim ant" phases greatly ilhum inated ourunderstanding of the related quasicrystals in the past, we shallpause to review what is known in the A l-C O-N iphase diagram.

The decagonalportion of the A l-C o-N iphase diagram is fragm ented into severalm odi cations occupying sm all dom ains. ${ }^{1,2}$. O fthese, those show ing the sim plest di raction pattems are the so-called \basic N ickel" phase near the N i-rich com position $\mathrm{A} \mathrm{l}_{10} \mathrm{C}_{\mathrm{o}_{10}} \mathrm{~N}$ i$\dot{\text { in }}_{0}$ and so-called $\backslash$ ba-
sic C obalt" near the C o-rich com position A ho $_{0} \mathrm{C} \mathrm{O}_{20} \mathrm{~N}$ i $\mathrm{i}_{1} 0$. Several high-resolution $X$ ray structure determ inations were carried out for the \basic $N$ i" phase ${ }^{3}$, but studies of the \basic Co" phase have lagged. An interesting aspect of the Co-rich portion of the phase diagram is the vefold (rather than tenfold) symmetric decagonal phase, ${ }^{5}$. in particular $d\left(\mathrm{Al}_{2: 5} \mathrm{CO}_{20} \mathrm{~N}\right.$ is:5 $)$ and $d\left(A I_{2: 5} \mathrm{Co}_{19} \mathrm{Ni}_{8: 5}\right)^{\frac{6}{n}}$, also $\left.d\left(\mathrm{Al}_{1: 5} \mathrm{Co}_{25: 5} \mathrm{~N}_{3}\right)^{\prime}\right)^{7}$. This and other C o-rich m odi cations show superstructure di raction peaks, indicating $m$ odulations of the $\backslash$ basic" structure: $d\left(\mathrm{~A}_{72: 5} \mathrm{C}_{17: 5} \mathrm{~N}\right.$ in $\left._{10}\right)$, sim ilar to the $\backslash$ vefold" mod i cation ${ }^{2}$, and $d\left(\mathrm{~A}_{1} \mathrm{CO}_{20} \mathrm{~N} \mathrm{i}_{9}\right)$, which has a period of 61A in one direction and thus was called the lonedim ensional quasicrystal" ${ }^{8}$. Throughout the phase diagram, the quasilattice constant $a_{0}$ is close to $2: 45 \mathrm{~A}$.
$T$ here is a solved periodic crystal approxim ant of $\backslash$ basic $C \circ ", W$ (A IC ON i) structure ${ }^{9}$. There are further m odi cations near to the \basic N i" com position as well as near $d\left(A h_{0} C_{O_{15}} \mathrm{~N}_{15}\right.$, and another (partially solved) approxim ant ${ }^{10}$, w ith unit cell37:5A $\quad 39: 5 \mathrm{~A} \quad 8 \mathrm{~A}$, and com position $\mathrm{Al}_{1} \mathrm{C}_{14: 5} \mathrm{~N} \mathrm{i}_{14: 5}$. The \basic Co" phase has a 4:08A stacking period, like \basic $N$ i", but it show sm uch stronger di use scattering than \basic N i" 11,12 in such a way as to indicate a localdoubling of the c periodicity (to 8:16A); the known large approxim ants also have c 8A. Water in this paper (Sec. V A 2), we shall address the stabilizing e ects of this period doubling.]

O ur general technique is the same as those used in the previous work on \basic N i" ${ }^{13,14,17}$. W e begin with a sm all-scale rhom bus tiling and discover generalm otifs and pattems. These pattems usually have a geom etry consistent with an in ated Penrose tiling: we de ne a new model using that tiling, and the pattems observed at the sm all scale are prom oted to be fundam ental objects on the in ated tiling. By restricting con gurations
and increasing the size of fundam ental ob jects, we can run sim ulations on larger and larger unit cells w ithout excess degrees of freedom, speeding up the M M C process considerably.
$T$ he outline of the paper is as follow s. A fter review ing the technique and the inform ation needed in its set-up (Sec.III) , we present initial results in Sec.III from M onte C arlo lattioe-gas sim ulations using a discrete site-list, both $w$ th the initialedge- $a_{0}$ rom biand also w ith $a_{0}-$ edge bilayer mombi; in particular, the whole structure is built from two cluster modifs \{ the 13A decagon and the Star cluster. Next, Sec. IV codi es this by describing an ideal decoration, which requires speci cation of the 13A decagon orientations as well as the optim um placem ent of a subset of easily $m$ oved $A$ latom $s$.

In Sec. V, we pass on to m olecular dynam ics and relaxation studies that break free of the discrete-site lists; these revealtroughs (w hich we call \channels") in the potential energies felt by A latom swhich lead to local disruption of the layering of the atom $s$, and a breaking of the tw o-layer peridiocity assum ed in previous sections. H ere and in Secs, V I and V II, w e take up the correlations in the atom $\mathrm{s}^{\prime}$ displacem ents, and also how this determ ines the an ordering of the orientations of 13A decagon clusters which reduces the system 's sym m etry to pentagonal. W e conclude $w$ ith an application to $W$ ( $A \mathbb{C} \circ N$ i), the bestknown approxim ant of C o-rich quasicrystal $d(A \mathbb{C} \circ \mathrm{~N}$ i), in Sec. VIII, and a discussion (Sec. IX of the key results and the lim its on their validity.

## II. METHODSAND INPUT INFORMATION

In this section, we lay out the procedures of the sim ulation, as well as the assum ptions and facts that all our results depend on.

## A. M ethods

O ur m ethods are a com bination of $M$ etropolis $M$ onte Carlo (MMC), relaxation, and molecular dynam ics (MD).We rst perform MMC on a set of xed sites. We create this set by $m$ ake use of a tiling of $P$ enrose rhom bi on each layer and by placing atom ic sites on each of the rhom biusing a decoration. Fig. 1 show s $P$ enrose rhom bi and tw o decorations that we use. See A ppendix A for a $m$ ore detailed description of the decoration and tiling.]

Penrose rhombus tilings (even random ones) have a natural in ation rule whereby the same space can be retiled w therhom biw hose edges are a pow er of the golden ratio $\quad(\overline{5}+1)=2 \quad 1: 618 \mathrm{~m}$ ultiplied by the orginal edge length. In this paper, we will m ake use of rhom bi w th edges $\mathrm{a}_{0}=2: 45 \mathrm{~A}, \mathrm{a}_{0} 3.9 \mathrm{~A}$, and ${ }^{3} \mathrm{a}_{0} 10.4$; we shall also mention a sim ilar tiling with edges ${ }^{2} \mathrm{a}_{0}$ that applies to the $N$ i-rich $d(A \mathbb{N} i C o$ ) phase, a structure closely related to the one we are investigating.


FIG. 1: These two con gurations of Penrose mombi, with edge $a_{0} \quad 2: 46 \mathrm{~A}$, can be ipped $w$ ith respect to their asym $m$ etric axes as a $w$ ay to $m$ ove sites around.

A unit cell can be tiled in $m$ any di erent ways $w$ ith the sam e num ber of Penrose rhom bi; this is physically im portant since the di erent tilings correspond to $m$ any di erent con gurations ofatom ic sites that are consistent w ith the sam e physicalcelland the assum ptions based on the lattice constants. To explore this degree of freedom, we perform MMC on the rhombic tiles by using rearrangem ents of three $P$ enrose rhom bi (and the atom s on them ) that preserve their collective hexagon outline. T he two rhombus con gurations forwhich this is possible are show $n$ in $F$ ig. 1 .

The M MC is perform ed on a tem perature schedule speci ed by the beginning and ending inverse tem peratures $=1=\mathrm{k}_{\mathrm{B}} \mathrm{T}$ along w ith an inverse tem perature step
. At each tem perature step, a set num ber of M M C operations per site are perform ed. A fter we nd a conguration with this \xed-site" m ethod, we can rem ove the site list restriction, and use relaxation and MD to nd a structure that is m ore energetically favorable by our potentials.

W hy is our m ethod to start w ith tilings, decorations, and discrete sites, and iterate this (as outlined in the Introduction), rather than im m ediately perform M D ? T he reason is that the energy surface of $d(A \mathbb{C} \circ N$ i) in conguration space contains $m$ any local energy m inim a. A pure M D program would be alm ost certain to be trapped in a glassy con guration. Even with a sm all num ber of atom s and a sim pler set of potentials, extrem ely long M D coolings w ere necessary in order to produce recognizable (but still quite defective) quasicrystals by brute forœe. ${ }^{18}$ ]

## B. Input in form ation

The only experim ental inputs into the procedure are lattice constants, com position, and and density; the only theoretical input is the pair potentials. For the initial trials, one $m$ ust also $m$ ake a discrete choice of which size of mom bus to use $\{$ the quasilattice constant of a decagonal tiling is de ned only module factors of and one must decide how $m$ any atom ic layers are to be sim ulated.

| $A \cdot B$ | $\mathrm{R}_{0}^{0: 1 \mathrm{eV}}$ (A) | (i) | $\mathrm{R}_{\mathrm{i}}$ (A) | $\mathrm{V}_{\mathrm{A}} \mathrm{B}\left(\mathrm{R}_{\mathrm{i}}\right)(\mathrm{eV})$ |
| :---: | :---: | :---: | :---: | :---: |
| A 1-A 1 | 2.62 | (0) | 2.49 | +0.351 (hc) |
| A 1-Co | 2.00 | (0) | 2.30 | -0 285 (hc) |
|  |  | (1) | 2.38 | -0.302 |
|  |  | (2) | 4.44 | -0.035 |
| A L-N i | 2.02 | (0) | 225 | -0.152 (hc) |
|  |  | (1) | 2.38 | -0.192 |
|  |  | (2) | 4.37 | -0.030 |
| $\mathrm{Co-Co}$ | 2.48 | (0) | 2.73 | +0.045 (hc) |
|  |  | (1) | 2.68 | + 0.040 |
|  |  | (2) | 4.49 | -0.091 |
|  |  | (3) | 6.44 | -0.033 |
| $\mathrm{Co-N} \mathrm{i}$ | 2.48 | (0) | 2.62 | +0.050 (hc) |
|  |  | (1) | 2.67 | + 0.044 |
|  |  | (2) | 4.42 | -0.081 |
|  |  | (3) | 6.39 | -0.029 |
| N i-N i | 2.46 | (0) | 2.63 | + 0.051 (hc) |
|  |  | (1) | 2.64 | + 0.051 |
|  |  | (2) | 4.34 | -0.075 |
|  |  | (3) | 6.30 | -0.027 |

TABLE I: Pair potential $m$ in $\dot{m}$ a $R_{i}$ for $A \operatorname{lCo}-N$ i. $T$ he $\backslash(0) "$ well is the hard core radius, de ned as the $m$ inim um radius actually found in a relaxation (after $m$ olecular dynam ics annealing) of an example con guration; $R_{0}^{0: 1 \mathrm{eV}}$ is de ned by $\mathrm{V}_{A} \quad\left(\quad\left(\mathrm{R}_{0}^{0: 1 \mathrm{eV}}\right)=\right.$ $+0: 1 \mathrm{eV} . \mathrm{M}$ in im a are listed only for $\mathrm{J}_{\mathrm{A}}$ в $\left(\mathrm{R}_{\mathrm{i}}\right) \mathrm{j}>0.025 \mathrm{eV}$.

## 1. P air potentials

$T$ he six pair potentials (for the combinations of $A l$, C 0 , and N i) were generated using M oriarty's \G eneralized P seudopotential Theory"19, as modi ed using results from ab initio calculations to add a repulsion correcting the forces betw een TM - TM nearest neighbors ${ }^{20}$, attributed to $m$ any-body term $s$ beyond the pair term $s$ given by GPT.A standard cuto radius of 7 A was nor$m$ ally used. Even m odi ed, the potentials are im perfect in their unreliable handling of TM - TM nearest neighbors and their neglect of three-body interactions ${ }^{21}$.

The sam e potentials $m$ ay be used over the interesting com position range, even though they im plicitly depend on electron density, because the lattice constants fortunately com pensate so as to keep the electron density nearly constant (over this range). A $m$ a jor post hoc justi cation for the pair potentials is the correct prediction of binary and temary phase diagram $s^{22}$. In particular, the (corrected) temary GPT potentials predict the correct C o-N i chem ical ordering in the approxim ant $X\left(A l_{g}[C \circ, N i]_{4}\right)^{24}$ and it seem $s$ in $W$ (A $1 \mathrm{C} \circ \mathrm{N} i^{25}$.
$R$ adiiat which these potentials have $m$ in im a are given in Table 1 , as well as a \hardcore" radius. $\mathbb{P}$ lots of the sam e potentials are in Fig. 1 of Ref.13.] A s w as noted previously ${ }^{13,23}$ the salient features of such potentials are (i) a very strong A l-TM nearest-neighbor well, which is 1.5 tim es as strong for $A 1-C \circ$ as for $A 1-N i ;$ (ii) a rather
strong TM -TM second neighborw ell [TM-TM rst neighbors are unfavorable because they would deprive TM of A lneighbors] (iii) no A l-A linteraction to speak of except the hard core.

A cartoon recipe for an optim um structure is (i) satisfy the TM-TM interactions by a relatively uniform spacing of TM atom s (ii) place as many Al as possible in the A l-TM rst wells, lim ited by the A l-A l hardcore. In principle, the A I-TM optim ization $m$ ight constrain the TM TM lattice, but in fact the considerable freedom in placing A l's allow s these tasks to be separated. (T he m ain operation of the A l-A l constraints is presum ably to select a subset of TM arrangem ents, which would be practically degenerate ifonly the TM -TM potentials w ere taken into account.)

## 2. Cell, lattice constant, density and com position

D ecagonal quasicrystals are quasiperiodic (at least on average) in just tw o dim ensions. In this decagonalplane, we assum e the atom ic con guration can be described reasonably well by a tiling of Penrose rhombi w ith edge length $a_{0}=2: 45 \mathrm{~A}$ quasilattioe constant, which is experim entally determ ined. In the dim ension norm al to the quasiperiodic plane, the c-axis, the quasicrystal repeats after a num ber of two-dim ensional quasiperiodic layers are stacked on top of each other w ith a uniform separation $\mathrm{c}=2=2: 04 \mathrm{~A}$ taken from experim ent.

Periodic boundary conditions are alw ays adopted in all three dim ensions: the constraint that this be consistent with a rhom bus tiling perm its only a discrete fam ily of sim ulation cells. The cell sizes we chose are especially favorable since they perm it a tiling which is close to having ve-fold sym $m$ etry [in the frequency of the various orientations of rhom bi or other ob jects in the tiling $W$ e label our unit cells by their dim ensions, a b c, where the stacking period (alm ost alw ays 4.08A, and often om itted) com es last (see Table III). The largest part of our studies were done on the $\backslash 32$ 23" cell, which conveniently has dim ensions large enough to accom odate a variety of (dis) ordered arrangem ents, but sm all enough to be tractable. W e too rarely used the $\backslash 20 \quad 38 "$ cell, which has exactly the sam e area, but a m ore elongated shape. The 2023 cell has an area sm aller by ${ }^{1}$ than the standard 32 23; we call it \halfw " as we used it less often than the \W -cell". That was so called since it has the sam e dim ensions as the approxim ant $W-A \mathbb{C} \circ \mathrm{~N}$ i; we em ployed the \W -cell" even when not trying to predict the $W$-phase structure, for it too has a convenient size. W e m ade the least use of the $\backslash 20 \quad 20$ centered", which is quite sm all (half the 3223 cell). For a special purpose we once used the $12 \quad 14$ cell, which is shorter by a factor ${ }^{1}$ in each direction than the \halfw " cell; we call it the $\backslash \mathrm{A}_{\mathrm{H}_{3} \mathrm{C} \mathrm{O}_{4} " \text { cell, as } \text { 五 is the sam e size as the }}$ orthorhom bic variant of that crystal.

The \basic Co" phase of ( $\mathrm{A} \mathbb{N}$ iC o) is experim entally know $n$ to have a period $c^{0}=2 c=8: 16 \mathrm{~A}$, but $\{$ up till the

| N am e | sym m etry | (A) | b (A) |  |
| :---: | :---: | :---: | :---: | :---: |
| 3223 \standard" | rectangular | 32.01 | 23.25 | (90) |
| 2020 centered | oblique | 19.78 | 19.78 | 72 |
| 2038 \elongated" | rectangular | 19.78 | 37.62 | (90) |
| 2023 \halff " | rectangular | 19.78 | 23.25 | (90) |
| 4023 \W -¢ell' | rectangular | 39.56 | 23.25 | (90) |
| $12 \quad 14 \backslash \mathrm{~A} \mathrm{H}{ }_{3} \mathrm{CO}_{4}{ }^{\prime \prime}$ | rectangular | 12.22 | 14.37 | (90) |

TABLE II: Unit cells used in this work. N ote the 2020 is the prim itive cell of the 3223 œentered rectangular lattice, but in an oblique lattice setting so as to give prim itive vectors a and b correctly (w ith angle betw een them).
relaxation studies of Sec. V \{ we alw ays sim ulated a cell w ith a period c. In other words, our philosophy (as in Ref. (13) w as to discover as $m$ any features as possible in the sim plest (4.08A period) fram ew ork, and only later to investigate deviations from this. A partial justi cation is that an approxim ate 4.08 A periodicity is expected, and found: $m$ any of the atom $s$ do repeat $w$ th that period, m odulo sm all o sets. Ideally, though, one should only take the layer spacing from experim ent, and investigate cells with di erent numbers of layers, so as to let the sim ulation reveal any additional $m$ odulations that $m$ ay increase the period.

M ost of our sim ulations used a standard density ${ }^{26}$ of 0.068 atom $\mathrm{s} / \mathrm{A}^{3}$ and a com position $\mathrm{A} 1_{0} \mathrm{C} \mathrm{O}_{20} \mathrm{~N}$ in 0 . Variations of a few percent were tried for special purposes; in particular, our $W$ (A $1 C$ oN i) sim ulation (Sec. V IIII) used density 0.071 atom $\mathrm{s} / \mathrm{A}^{3}$ and com position $\mathrm{A} \mathrm{r}_{2} \mathrm{C} \mathrm{O}_{21} \mathrm{~N}$ i. .

In sim ulations speci cally exploring the e ect of atom density, we varied it over a range of roughly $0: 066 \mathrm{~A}^{3}$ to $0: 074 A^{3}$; this is unphysically loose at one extrem e, and unphysically ovenpacked at the other. A range of roughly $0: 066 \mathrm{~A}^{3}$ to $0: 072 \mathrm{~A}^{3}$ is intemally \legitim ate"; our diagnostic for this is that the run-to-run variance of the energy should not be too large. If we took into account com petition w ith other structures in the A IN i-C o phase diagram, or if we used the densities appearing in actual approxim ant phases, presum ably the density range w ould be much smaller. The actual w phase ${ }^{9}$ has a reported density $0.0708 \mathrm{~A}^{3}$, or $0.0703 \mathrm{~A}^{3}$ when fractional occupancies are best resolved ${ }^{25}$. The atom ic density in som e decagonal approxim ants is $0.0724 \mathrm{~A}^{3}$ for $\mathrm{A}_{5} \mathrm{C} 0,0.0695$ $A^{3}$ for $\mathrm{Al}_{13} \mathrm{Co}_{4}$ (in the mC 32 structure variant using the standard nom enclature ${ }^{60}$ ), or $0.0687 \mathrm{~A}^{3}$ for $\mathrm{Al}_{3} \mathrm{Ni}$.

## III. FIXED-SITESIMULATIONS

In this section, we describe two stages of M etropolis $M$ onte $C$ arlo sim ulations using discrete site lists, and the key structure $m$ otifs that em erged from them. It is im portant to note that in this kind of run, we are not averaging quantities over the ensem ble, nor are we analyzing the nal con guration after the low est-tem perature anneal. Instead, we pick out the lowest-energy con gura-

| M odel | A 1 (\%) | C○ (\%) | Ni (\%) | density |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Standard in itial | 70 | 20 | 10 | 0.068 x |  |  |
| W ( A IC on i) | 71.7 | 20.8 | 7.5 | $0.070 x$ |  |  |
| $\backslash \mathrm{basic} \mathrm{N}$ i" ideal | 70.0 | 9.3 | 20.7 | 0.0706 |  |  |
| idealized W -cell | 70.1 | 22.4 | 7.5 | $0.071 x$ |  |  |

TABLE III: C om position and density com parison for various structure $m$ odels. Experim ental densities are surprisingly hard to $m$ easure accurately, and com position of the ideal crystal structure is rarely identical to actual com positions of the sam ples. (Sources: \Basic N i", Ref.13, Sec. III B ; W -A IC oN i, Ref. 9.25 .)


F IG . 2: [C olor] T ypical result of M onte C arlo sim ulation using 2.45A edge tiles, on the 3223 tiling. The com position is $A l_{0: 700} \mathrm{C}_{00: 198} \mathrm{~N} i_{0}: 101$, w ith 207 atom $s$ in the cell, and the unrelaxed energy is $-0.4419 \mathrm{eV} /$ atom . B lack circles are Ni , blue are Co, and gray are A l. The [red] lines are a visualaid to $m$ ark A l-A lneighbors in di erent layers, separated by 2.45 A in projection. These $m$ ostly form a hexagon-boat-star-decagon tiling as described in Sec. IV. O uter rings of 13A decagons can be m ade out, as well as Star chusters, but have $m$ any im perfections, e.g. \short" (2.25A) A lCo bonds (see A pp.B1.)
tion which has appeared during the entire run. This procedure, since it singles out the low-energy uctuations, $m$ ay give $m$ eaningfulresults even when perform ed at surprisingly high tem peratures. ${ }^{29}$

## A. Exploratory sim ulation using sm all tiles

A series of annealing sim ulations and relaxations at the levelw ere perform ed using the edge $\mathrm{a}_{0}$ rhom bi. M ost of these runs were done on the $3223 \quad 4$ unit cell with
 dard atom ic density of 0.0682 atom $s / A^{3}$. That unit cell was sm all enough that it was not com putationally prohibitive to sim ulate, yet large enough that m otifs could form w ithout strong constraints by the periodic boundary conditions 30 O ur aim at this stage is to allow the con gurations as much freedom as possible to discover
the correct local pattems appropriate to this com position. $W$ ith the atom $s$ restricted to tile-based sites and the composition and density xed at our standard values ${ }^{26}$, there still seem ed to be su cient freedom to nd good localorder, as there had been in the \basic N i" sim ulation ${ }^{13}$ (and in much earlier lattioe-gas sim ulations ${ }^{31}$ ).

To de ne a M onte Carlo sweep for the 2.45A edge tiling, we m ust delve into som e technicalities. A s we just noted, there are two basic kinds of updates, Swaps of atom s betw een sites and tile- ips. A \sw eep" is taken to have one attem pted site-sw ap for each \short bond", dened as any pair of (candidate) sites separated by less than 3A. In addition, every sweep contained 1 attem pted swap per $\backslash$ long bond", de ned to have a separation of 3 \{ 5 A . O ur standard 2.45A tile sim ulation on the 3223 cell had 680 candidate sites (occupied by about 210 atom s), w th about 9.5 short bonds per site and about 67 long bonds per site. F inally , each sw eep also had 02 attem pted tile ips per tile vertex.
A annealing tem perature schedule typically began at
$=4$ and decreased to $=20$ in increm ents of $=1$ or $0: 5$, where is $m$ easured in (eV ) ${ }^{1}$. At each tem perature, 100-200 sw eeps w ere perform ed. T he low est energy encountered during each annealing w as saved. (A sim ilar search $m$ ethod w as used in $R$ ef.27.) The annealing cycle was repeated 20 tim es; the whole set of annealings took about 5 hr on an AM D A thlon 2.1 GHz processor. Sim ulations were run w th di erent tem perature schedules, but the results w ere not noticeably di erent.

It should be rem arked that the low est tem peratures would have been m ore appropriate for a determ in istic decoration forcing a good atom ic structure, so that quite sm all energy di erences are being explored. In these exploratory 2.45 A tile simulations, even $=2 \mathrm{eV}^{1}$ (about three tim es the $m$ elting tem perature) can give good structures (keep in $m$ ind that the best con guration is saved from each annealing.) $N$ ote that the tile- ip degrees of freedom freeze out while the tem perature is still high. W hich atom con gurations are available at lower tem peratures depends sensitively on the site-list.

N o con guration found by M C annealing (even on the 4A tiling, see Subsec. IIIE) had energy as low as the idealized tiling in F ig. 7 . W e believe this is an artifact of the very lim ited sitelist. The TM arrangem ent freezes at $m$ edium tem peratures and becom es frozen at low tem peratures, as the only M C m oves with a sm all energy di erence are Al hops to a vacant site (w ith \{ perhaps \{ Co/Niswaps at som ew hat higher tem peratures). A site which is good for a TM is generally not good for Al, and vioe versa, so there are no low -energy A I/TM sw aps; a rearrangem ent of $m$ ore than two atom $s$ is needed to accom plish such a change.

A typical result is shown in $F$ ig. [2; this has total content $A h_{45} \mathrm{C}_{41} \mathrm{~N}$ i $_{21}$ corresponding to our standard conditions. Them ost striking feature was that the TM atom $s$ organized into a well-pattemed sublattioe, rem in iscent (in $z$-pro jection) to the packing of pentagons, stars, and partialstars which is one of the canonical representations
of Penrose's tiling ${ }^{32}$ The TM atom $s$ con gured them selves to be $4: 5 \mathrm{~A}$ apart, inviting a speculation that the longer range pattems are enforced by the TM -TM interactions, while the Al atoms ow around like hard spheres and 11 in the gaps. Indeed, there were di erent \freezing tem peratures" for the TM -TM quasilattice and the A LTM interactions: that is, the TM $-T M$ lattice is w ell established at a tem perature $m$ uch higher than that necessary to rearrange the A latom s .

Sim ilar TM pattems are seen in allA l-TM decagonals ( w ith m any variations having to do w ith the placem ent of the tw O TM species and the larger-scale arrangem ent of these large pentagons). So as to best highlight this tiling-like netw ork (and other $m$ edium -range structural features) to the eye, our graphics processing was auto$m$ atically set to show a line connecting every pair of TM atom $s$ in di erent layers and separated by ao $4: \mathrm{AA}$ in-layer.

A strikinge ect at this stage is how the A latom s in the tw o layers organize them selves into a one-layer netw ork ( w ith edge 2.45A: see F ig Z) . The even vertices are all in one layer and odd vertices $w$ ithin the other layer, so this represents a kind of sym $m$ etry-breaking and long-range order that has propagated through the entire sim ulation cell. In fact, we can already recognize the 2.45A-edge D ecagon $H$ exagon $B$ oat-Star (D HBS) tiling, to be elaborated in Sec. IV B. A long w ith this order, and probably driving it, the TM atom salso obey this altemation, except they go in the opposite layer to the layer A lw ould have gone into. Am ong other things, that produces large num bers ofTM $-T M$ pairs in di erent layers, separated by
(2:45) $\quad 4:(\mathrm{A}$ in-plane and hence by 4.5 A , as described in the previous two paragraphs.
B. Fundam ental cluster $m$ otifs

1. 13A decagon cluster

It becam e apparent that at the $\mathrm{A} \mathfrak{r}_{0} \mathrm{C}_{20} \mathrm{~N}_{1} \mathrm{i}_{10}$ com position, our pair potentials favor the creation of $m$ any $\mathrm{A} \mathrm{I}_{5} \mathrm{TM}_{5}$ rings surrounded by two m ore concentric rings w ith approxim ate vefold and screw decagonal sym metry. The object as a whole will be called the \13A decagon" (13AD) for its diam eter ( $\left.2^{2} \mathrm{a}_{0} \quad 12: 8 \mathrm{~A}\right)$.

These tiles are decorated by a site list which favors (but does not absolutely force) a 13A decagon to appear when M etropolis M onte C arlo is perform ed. N otioe the signi cantly decreased site list and enchanced ordering, as com pared w the version of 13A $D$ in (a).

## 1. At the center there is a single A latom.

2. R ing 1 is ten atom $\mathrm{s}\left(\mathrm{A}_{5} \mathrm{TM}_{5}\right)$ that we call the $5 \&$ 5' cluster. In projection, they form a decagon, but they altemate in layer, so the sym $m$ etry elem ent of the colum n is $10_{5}=\mathrm{m}$. T he sites in the sam e layer as the centralA lare (alm ost alw ays) TM sites; the other ve sites are nom ally A I.


FIG.3: (a)13A decagon created on the 2.45 A random rhom bus tiling at 0:068A ${ }^{3}$ point density A 上 $_{0} \mathrm{C} \mathrm{O}_{20} \mathrm{~N}$ i10 com position. Sm allem pty circles denote unoccupied sites. Large and sm all circles are atom $s$ located in the upper and low er layers, respectively. (D ouble circles are overlapping circles in two layers.) B lack color denotes N i, dark gray C o, and light gray A l. (b)A 13A decagon form ed on the 4.0A tiling and divided into 4.0A scale $P$ enrose tiles. H ere and in (a), arrow s point to atom sites (all in ring 2.5 or ring 3) that violate the cluster's 5 m sym m etry. (c) A Star cluster created on the 4.0A tiling. Only the darker atom s are considered part of the Star cluster; the lightened atom s belong to adjacent Star clusters or 13A D s.
3. R ing 2 consists of another ten A latom s; in $z$ projection, each atom is along a ray through an atom of $R$ ing 1 (but in the other layer).
4. $R$ ing 3 is on the outer border of the decagon which has edges of length $4: 0 \mathrm{~A}$. In projection, there is a TM atom on each comer altemating in layer (so the actualTM -TM separation is $4: 46 \mathrm{~A})$. These TM atom $s$ sit in the sam e layer as their A l neighbor in $R$ ing 2 . In addition, alm ost every 13A decagon edge has an A latom dividing it in the ratio ${ }^{1}:{ }^{2}$, sitting in the opposite layer from the TM atom on the nearer comer. T hese A latom s are usually but not alw ays) closer to the comer TM 's that are in the sam e layer as the ring 1 TM atom s (see Fig. (3) .
5. Between rings 2 and 3 are candidate sites which are occupied irregularly by Al, which we w ill call collectively ring $2.5^{\prime}$. [T he rules for placem ent of the ring 2.5 and ring 3 Alw ill be explored much later (Sec. IV B) .]

At the stage of the $a_{0}=2: 45 \mathrm{~A}$ tile sim ulation, virtually every 13A D has im perfections, and there are variations
betw een Co/N ior Al/vacant in even the best exam ples; in a typical13A D only 80\% of the atom sconform to the above consensus structure, but that is already su cient to settle w hat the ideal pattem is.

## 2. Star cluster

Filling the spaces betw een the 13A decagons, we identify another 11-atom m otif sim ilar to the $\mathrm{A} \mathrm{I}_{6} \mathrm{CO}_{5}$ center of the 13A D : a pentagonalantiprism, in which one layer is all A l atom s, and the other layer is centered by an A l atom. The di erence is the ve atom $s$ in the second pentagon are only \candidate" TM sites; they have m ixed occupation, w th roughly 60\% TM (usually N i) and $40 \%$ A I. W e shall call this sm allm otif the \Star cluster ", associating it $w$ ith the star-shaped tile that lls the space in a ring of ve adjoining 13A decagons. ( $T$ he atom $s$ along the edges, how ever, are not form ally counted as part of the Star cluster: they nom ally belong either to the outer edge of a 13A decagon cluster, or else to another 11-atom Star chuster.)

Such centers were evident in the 2.45A-edge sim ulations, but they appearm ore clearly as repeated pattems in the 4A-edge simulations. (T hat tiling must $l l$ the space betw een 13A D s by 4A -edge H exagon, B oat, and Star tiles; the intemal vertex of each of those tiles gets a Star cluster centered on it.)

The local sym $m$ etry around the center of a Star cluster is vefold (unlike the tenfold localsym $m$ etry around the 13A D). Adjoining Star chusters actually overlap [if we represent them by the star of ve rhombi as in Fig.[3(c) ] and necessarily have opposite orientations; furthem ore, the respective centralA latom s (and surrounding candidate-TM sites) are in altemate layers. Thus, all Star clusters can be labeled \even" or \odd" according to their orientation.

## C. Relationships of neighboring decagons

T he next step in our generalm ethod, after a chuster m otif is identi ed, is to discover w hat geom eric rules govem the netw ork ofcluster centers. Those rules are usually expressed as a list of allow ed inter-center vectors, which becom e the \linkages" ${ }^{33}$ ofourm odelgeom etry. O ften, a m ild further idealization of this netw ork converts it into random tiling. At that point, one is ready to proceed w ith the next stage of sim ulations, based on decorations of this tiling.

So in the present case, once the 13A decagon is identi ed as the basic cluster of our structure, the question is how two neighboring ones should be positioned. (T he relative orientations of their pentagonal centers will be left to Sec. VII. A s alw ays, the fact that a cluster appears frequently suggests it is favorable energetically, and that one of the geom etric rules should be rule to $m$ axim ize its density. Yet the m ore closely we place clusters,
(a)

(b)



FIG. 4: Possible ways for 13A decagons to adjoin. (a), (b) Unfavorable ways (c) A ctual pattem, form ing the $\backslash B$ inary tiling" (edges show $n$ in gray).
e.g. overlapping, the $m$ ore im perfection (deviation from the ideal, vefold sym $m$ etric arrangem ent) $m$ ust be tolerated in each cluster; w hen the clusters are too close, this cost negates the favorable energy. (N ote that even if the clusters do not appear to overlap, it is conceivable that a further concentric shell should have been included in the de nition of the ideal cluster. In this case, the chusters \{ properly de ned \{ are still classhing.)

W e considered the four candidate linkages in Fig. 4 $(a, b, c)$, but concluded that only the linkages off ig. 4 (c) were valid. O f course, the frequency by which such pattems appeared spontaneously in our sim ulations w as one chue: edge-sharing is the com $m$ onest relationship betw een 13A D s. [C luster relations like F ig. 4 (a,b) did appear on occasion in the 2.45 A tile sim ulations, particularly w hen the sim ulation cell lattice param eters did not perm it a netw ork using only the favorable separations.] Beyond that, we addressed the question m ore quantitatively by ad-hoc tests in which we arranged that a con guration would (or could) include one of the rarer linkage types, and then com pared its energy w ith a con guration having the com $m$ on linkages, or checked which of tw o locations was likelier for another cluster to form. T hese tests are detailed in A ppendix B.

In the Fig.4(a) linkage, cluster centers are separated
${ }^{3} \mathrm{a}_{0}$, and the clusters overlap by a thin $P$ enrose mom bus w ith edge 4A. In tw o places a ring 2 (A l) site of one cluster coincides w ith a ring 3 ( C o) site of the other one, so m odi cations are m andatory for a couple of atom occupancies. This linkage is m otivated by the possibility that the sm all decagon (bounded by the ring 2 Al atom s ) is the key chuster. (Indeed, that decagon, of edge 2.45 A , is one unit of an altemative structural description we shall introduce in Sec. IV.)

Let us forbid overlaps of 13A decagons henceforth, and assum e that the shortest linkage is edge sharing, a length $1: 176^{3} \mathrm{a}_{0} \quad 12: 2 \mathrm{~A}$ (here $1: 176=2 \sin 72$ ) T he densest packing of 13 A D s w ould then ${ }^{34}$ be the vertices of 4A-edge H exagons, B oats, and Fatp $\frac{72}{2}$ mom bi; that would include many separations by $\overline{5}{ }^{2} a_{0} \quad 14: \mathbb{A}$, like the one across a fat mom bus's short diagonal as in Fig. (b) . This linkage also tums out to be disfavorable (A ppendix B). T he reason appears less obvious than in the overlapping cases, where there were atom con icts. O ne view point (adopting the analysis ofSec $\sqrt{I V}$, below ) is that this relationship w ould not allow the space betw een

13A decagon centers to be lled w th 2.45A Hexagons, B oats, and Stars. A m ore direct reason is that at the closest approach, the TM atom son the respective D ecagons's comers (in di erent layers) are separated by just as in layer, or a total distance of 3.19A , which (see Table I) is disfavorable.

W e are left, then, w ith a netw ork in which the angles are multiples $(2=10) n$, where $n \quad 3$. W e believe that the densest possible packing under these constraints is when the 13A D s sitt on the Large sites of a B inary tiling of mombiw ith edge ${ }^{2} 2: 45 \mathrm{~A} \quad 12: 2 \mathrm{~A}$, as in F ig. 4(c). (In this tiling, Large circles sit alw ays on vertiges of the short diagonal of the Fat hexagon and of the long diagonal of the T hin hexagon, and Sm all circles he other way around: this de nes an edge $m$ atching rule that still allow s random tiling freedom ${ }^{37}$.) T he second closest possible separation of cluster centers is $1: 176^{4} a_{0}$ (the long diagonal of the Thin Penrose mom bus). The Star chis ter clusters go on the Sm all sites of the B inary tiling.

It should be noted that, in a sm all or m oderate-sized system, the choice ofperiodic boundary conditions practically determ ines the netw ork of 13A decagons (assum ing the num ber of them is $m$ axim ized). C onsequently, in som e unit cells the placem ent of 13A D linkages is frustrated, while in others it is satis ed. Those cells m islead us, obviously, regarding the proper linkage geom etry; w orse, they $m$ ay $m$ islead us at the prior stage of identifying cluster $m$ otifs.

Thus, is conceivable that certain system shapes w ould favor or disfavor the appearance of 13A D clusters, opposite to the in nite-system behavior at the sam e com position and density. If (as is likely) a signi cant bit of the cluster stabilization energy is in the linkages, and if there is a com peting phase based on other m otifs, then the frustration of 13A D linkages in a particular cell $m$ ight tip the balance tow ard the phase based on the other geom etry.

These considerations show why it w as im portant, even in the earliest stages of our exploration, to explore m oderately large system sizes (a too sm all system would not even contain a m otifas large as the 13A D ); and also why it m ust be veri ed that results are robust against changes in the system shape (ie. periodic boundary e ects). To address this issue, we ran additional sim ulations on the 20384 cell (Tablenl) w ith the sam e volum e and atom content as our standard $32 \quad 23 \quad 4$ sim ulation. The lowest energy con gurations on this tiling also maxim ized occurrences of non-overlapping 13A D s, although extensive annealing w as needed (see A pp. B 2).

In sections IV and V I, we shall consider decoration nules that divide either the 13A decagon network, or the Star chister netw ork, into even and odd clusters. It should be recognized that the $B$ inary tilings that $t$ in the cells in T able II are non-generic from this view point. T he 13A D netw ork has no odd-num bered rings (ifit did, that w ould frustrate any perfectly altemating arrangem ent of cluster orientations). A corollary is that the Star clusters alw ays appear in (even/odd) pains: there is never an
isolated Star cluster，or any odd grouping．
As detailed in A ppendix E，recent structural stud－ ies ${ }^{65,66}$ and sim ulations ${ }^{35}$ suggested a cluster geom etry based on even larger clusters，w ith linkages longer than the edges in our tiling．Our initial sim ulation cells，al－ though $m$ uch larger than those used previously for the \basic Ni＂phase ${ }^{13}$ ，were too sm all to discover such a cluster．A part from the possibility of the PB cluster $m$ otif（Sec V IIIB），the atom ic structure of the large clus－ ter m odels is very sim ilar to ours；in particular，the 20A cluster is just a 13A decagon $w$ ith two additional rings C onsequently the large－clusterm odelm ust be quite close in energy to ours（and to a fam ily of sim ilar structures）， so it is am azing that a clear pattem（as we found in Ap－ pendix E）can ever em erge at the 2．45A stage，even $w$ ith annealing．W e cannot decide at present which structure is optim al for our potentials．

## D ．Relating structure to potentials

In this subsection，we pause to rationalize the stabir－ ity of the $m$ otifs and structural features identi ed so far， in term $s$ of the \salient features＂of the pair potential interactions（noted in Sec．IIB 1）．N otice that，at this stage，no assum ptions need be $m$ ade that atom $s$ in these clusters have stronger energetic binding com pared to the other atom $\mathrm{s}^{42}$ To use clusters as a building block for subsequent structuralm odeling，it su ces that they are the $m$ ost frequent large pattem appearing in the struc－ ture．（It is convenient if the clusters have a high local sym $m$ etry，too．）

W e start out explaining som e general features．First， the TM（ m ostly Co ）atom s are positioned 4.5 A apart， right at the $m$ inim um of the second（and deepest）wellof the potential $V_{C \circ C \circ}(r)$ ．Second，every $C \circ$ atom has as $m$ any A lneighbors aspossible \｛ nine orten \｛ and asm any of those at a distance $R_{1} \quad 2.45 \mathrm{~A}$ ，close to the particu－ larly strong $m$ inim um of $V_{A 1 c}$ 。（ $r$ ）（see Table I）．Such coordination shells are，roughly，solutions of the prob－ lem ofpacking asm any A latom sas possible on a sphere of radius $R_{1}$ ，subject to the constraint of a $m$ inim um A l－A ldistance（hardcore radius）of $R_{0}=2: 6 \mathrm{~A}$ to 2.8 A ， which is an fair idealization of the potential $\mathrm{V}_{\mathrm{Al}}^{\mathrm{Al}} \mathrm{l}$（r）． Furthem ore，since every TM atom is maxim izing its co－ ordination by A latom S，TM－TM neighbor pairs are as rare as possible（and they usually involve Ni ，since the A I－C o well is deeper than the A 1 N iw ell）．T hese features are also true of the \basic $N$ i＂phase and other A l－TM com pounds．

B ased on an electron channeling technique called A L－ CHEM I，辻was claim ed ${ }^{43}$ that for ad（ $\mathrm{A}_{2} \mathrm{Co}_{8} \mathrm{~N} \mathrm{i}_{20}$ ）al－ loy，the $\mathrm{N} i$ and Co atom s are alm ost random ly m ixed on the TM sites．M odeling studies（whether of that N i－ rich com position ${ }^{13}$ ，or the results in this paper for the C o－rich case）suggest that，on the contrary，substantial energies favor speci C sites for N iand $\mathrm{C} \circ$ so the structure is genuinely temary，not pseudobinary．

To rationalize the $d-A \mathbb{C}$ oN istructure in a m ore de－ tailed w ay，w em ust recognize it is locally inhom ogeneous in a sense：it is built from two kinds of sm all $m$ otif $\{$ sm all decagons plus A $\mathrm{g}_{9} \mathrm{C}$ o chusters \｛ which have quite di erent com position and bonding．（A third sm all mo－ tif that is neglected by our approach is the $W$－ A IC oN i pentagon，a kind of pentagonalbipyram id cluster，which w ill be discussed in Sec．V III．）To explain these sm aller $m$ otifs，wem ust anticipate part o the descriptive fram e－ work of Sec．IV，in which a 2．45A－edge \HBS＂tiling will be introduced．

## 1．Sm all decagon

T he heart of the 13A $D$ is a sm aller decagon（edge $\mathrm{a}_{0}=2: 45 \mathrm{~A}$ ），bounded（in projection）by A latom s（ring 2）．This $m$ otif seem $s$ to be particularly characteristic of Co－rich structures．D espite the strong tendency to avoid Co－TM pairs，asmentioned just above，this cluster has a ring of ve Co neighbors．

O ur best explanation is that a conjunction of several A l＇s is required in order to com press the A l－A l bonds as short as 2.57 A ，but that is advantageous since it al－ lows the A l－C o bonds to be correspondingly shortened to 2.45 A ，the bottom of the deep A l－C o potential．The site－energy $m$ ap（see $F$ ig．5）show $s$ that the interactions of the ring－1 Co atom s are not very well satis ed，com－ pared to ring -3 C 0 atom s ．On the other hand，the ring -1 A land（especially）the centralA lare well satis ed．

## 2．The $\mathrm{C} \circ \mathrm{Al}$ g coordination shell

Thism otif consists of a pentagon of ve A latom scen－ tered by Coin one layer，capped by tw o m ore A latom s in the layer above and two in the layer below，so the Co atom has coordination 9 by Al．（A com plete pentagon of this sort is centered in each of the 2．45A－edge Star tiles visible in F ig．7．）A ctually，this m otif is alm ost alw ays surrounded（in projection）by a larger pentagon of ve TM，lined up w ith the A lpentagon，but we shallnot treat these Co as part of the $m$ otif．They are（often）centers of neighboring $C$ OA $l_{g}$－type clusters，as described in the next paragraph．

TwoCoAlg m otifs m ight be packed by joining the pen－ tagons with a shared edge（two shared Al），but that w ould create an energetically unfavorable $\mathrm{C} \circ$－C $\circ$ distance $\left(R_{\mathrm{C} \circ \mathrm{co}}=3: 96 \mathrm{~A}\right)$ ．If instead two pentagons shared a comer（one A lat the midpoint of the Co－C o line），then $\mathrm{R}_{\mathrm{C} \circ} \mathrm{co}=4: 9 \mathrm{~A}$ which is also disfavored．The only way to achieve a favorable $\mathrm{R}_{\mathrm{C} \circ \mathrm{co}} \quad 4: 5 \mathrm{~A}$ is to place the tw O Coin di erent layers，w ith someAlatom sfrom the pentagon around one Cocapping the pentagon around the other Co，and vice versa．That is，m ore or less， the arrangem ent found around the perim eter of every 13A decagon cluster：Finally，if $\mathrm{CoA} \mathrm{l}_{\mathrm{g}} \mathrm{m}$ otifs on the perim eters of two 13A Ds are shared，迆 corresponds to


FIG.5: Site energies for ideal sites in the con guration of Fig. 7. H ere black (white) led symbols indicate a disfavorable (favorable) deviation, com pared to the $m$ ean for that species. Circles are Al, up-pointing triangles are Co, and dow $n$-pointing triangles are $N$ i.
an edge-sharing linkage, and the centers will be 12:2A apart, consistent w iththe 10.4A -edge B inary tiling (Subsec IIID.

The CoAlg m otif was equally im portant in the \basic Ni" phase ${ }^{13}$.

## 3. Site energies m ap

A diagnostic which was usefil in prior investigations using pair potentials ${ }^{36}$ is the \site energy" for site $i$,

$$
\begin{equation*}
E_{i}=\frac{1}{2}_{i}^{X} V_{i j}\left(R_{i j}\right) \tag{1}
\end{equation*}
$$

$w$ here $V_{i j}(R)$ is the proper potential for the species occupying sites $i$ and $j$, and $R_{i j}$ is their separation.

It is revealing to plot $\mathrm{E}_{\mathrm{i}}$ graphically ( F ig . (5) . T he sym bols represent each atom 's site energy $m$ inus the average (over the cell) of the site energies for that species, which is our crude surrogate for the chem icalpotential. T he energies are strikingly non-uniform betw een di erent places in the structure. A $n$ extrem ely good site energy is obtained for the A latom s in the even Star cluster. T he C o atom $s$ on the 13A D perim eter, as expected, are $m$ uch $m$ ore satis ed than those in the interior. The variable A l atom $s$ in the 13A D are the least satis ed, also as expected. The overall picture was not very di erent when this diagnostic is applied to con gurations that, afterM D and relaxation, developed puckering $w$ ith the variable A 1 entering \channels" (see Sec.V)

The con guration shown is taken from the idealized structure m odel of Sec . $\mathbb{I V}$. There is a strong contrast betw een good and bad A l sites; (th is is reduced but not elim inated by relaxation and $m$ olecular dynam ics as in Sec. V). Bad energies are often seen in neighborhoods which are som ew hat \overpacked" by A l atom s; when MD is perform ed (Sec. $V$ ), Al atom $s$ are observed to run from these sites to other places which are $m$ issing

A latom s. (For exam ple, in the 2.45A -edge D H BS tiling of Sec. IV, three adjacent 2.45A B oats is overpacked; if tw o of them are converted to the com bination Hexagon + Star, energy could be low ed by puckering as in Sec.V.)

## E. 4A rhom bus sim ulations

$T$ he $a_{0}=2: 45 \mathrm{~A}$-tile sim ulations are inadequate, to resolve further details of the atom ic structure, such as the exact occupation of ring $2.5 / 3$, or the interactions betw een 13A D s, as these are decided by sm all energy differences that get overw helm ed by the frequent incorrect occupancies at this level. A new simulation is needed using larger tiles and with a site list reduced as guided by the 2.45 A -tile results It $m$ ight have been appropriate to try an edge $a_{0}$ hexagon-boat-star tiling (as done in Ref.(13). H ow ever, we chose to go directly to an in ated rhom bus tiling w ith edge $a_{0} \mathbb{A}$, which is convenient for decom posing the 13A decagons (as they have the sam e edge).
$T$ he starting point is that space is tiled w ith large ${ }^{3} \mathrm{a}_{0}$ edge length rhombi in a binary tiling ${ }^{37}$ The Large disk vertices (which have a local ten-fold sym $m$ etry) are then the centers of the 13A D, as argued in Subsec. IIIC. On the actual sim ulation scale ( $a_{0} 4:(A)$ ), each 13A $D$ is represented by ve fat rhom bi arranged in a star, w ith ve thin rhom bi surrounding them to form a decagon $w$ th ve-fold sym $m$ etric contents. A decagon in the 4. AA scale rhom bus decom position is show $n$ in $F$ ig. 3(b).

A s com pared to the $2: 45 \mathrm{~A}$ site list, (i) instead ofhaving independent tilings in the tw o layers, we now have just one; (ii) the altemation in layers betw een the sites separated by a $2: 45 \mathrm{~A}$ edge is now buitt in; (iii) there are not $m$ any places w here the site list allow s even a possibility of close distances; (iv) a large fraction of the candidate sites get occupied \{ the only question is which species. Thus, the 4 :OA site list is partw ay to being a determ inistic rule. It should be em phasized that this 4.0A decoration is not well de ned on an arbitrary rhom bustiling since the inated ( ${ }^{3} \mathrm{a}_{0}$ ) tiling m ust follow a binary tiling schem e . The decoratable tilings are a sub-ensem ble of the rhom bus random tilings.

The rhom bioutside the 13A D s are grouped into 4Aedge H exagon, B oat, and Star tiles (a Star chister is centered on the interior rhom bus vertex of each of these tiles). For exam ple, tow ards the left side of $F$ ig. प(c), two 4A Stars are seen w th an overlap (shaped like a \bow tie") that is resolved by converting either one to a Boat. This decoration of the 4A rhom bi produces a slightly di erent sitelist, depending on which way such overlaps are resolved, but this did not seem to $m$ ake a di erence for the sites which are actually occupied 40 W e shalloccasionally refer to this version of the 4.0 A rhom bus tiling as the $\backslash 4.0 \mathrm{~A}$ D HBS" tiling.

The $a_{0}$ scale tiling and site list can be naturally de ated back to a-edge Penrose tiles, and these in tum can always grouped into a $a_{0}=2: 45 \mathrm{~A}$-edge

D ecagon-H exagon-B oat-Star (D H BS) tiling which is used in Sec. IV and later as a basis of description.
$T h$ is stage of $M$ etropolis sim ulation uses only atom sw aps, tile ips being disallowed (they would alm ost always be rejected). W e enforce a reduced site list, but do not $x$ any occupation: any atom (or note) m ay occupy any sit. The initial inverse tem perature was typically
$=10$ or $=20$, and increm ents were $=1$ or $0: 5$ in the 4.0 A -tile annealing runs. ${ }^{41}$ (H igher tem peratures are not needed since in the $4: 0 \mathrm{~A}$ sim ulations, it is very easy for TM atom $s$ to nd their ideal' sites.) The reduced tem perature $m$ akes the A loccupancy less random than before.

## 1. U se of toy H am iltonian to generate tilings

To generate appropriate tilings of 4.0A as a basis for these second-stage lattioe-gas sim ulations, we perform ed pure tile- ip MC simulations using an arti cial \tile H am iltonian" as a trick. The m ain term in the H am iltonian was $\mathrm{N}_{\text {star }}$ : here $\mathrm{N}_{\text {star }}$ is the count of star-decagons of 4A rhom bithat are bound to \level 0" $(=0)$ sites, using the nom enclature of A pp. A. (T he level 0 condition ensures that such decagons cannot overlap, but only share edges.)

In e ect, then, we are $m$ axim izing the density of nonoverlapping 13A decagons, w the constraint that the spaces between 13A D s are alw ays tiled w ith 4A -edge HBS tiles. Every resulting tiling (even in very large cells) was alw ays B inary tiling w th edge ${ }^{3} \mathrm{a}_{0}=10: 4 \mathrm{~A}$ as described in Sec.IIIC, w ith a star-decagon on every Large vertex and a star of ve fat rhom bi on every Sm all vertex. W e conjecture that $m$ axim izing the frequency of non-overlapping star-decagons rigorously forces a B inary supertiling; $m$ any other exam ples are know $n$ in which $m$ axim ization of a local pattem leads to a (random) supertiling, decorated w ith sm aller tiles. ${ }^{27,28}$
$T$ here is a large ensem ble of degenerate ground states of this $H$ am iltonian, which di er (i) in the B inary tiling netw ork, and (ii) the detailed lling of the 4 HBS tiles betw een the star-decagons. A dditional term s were used to rem ove the second kind of degeneracy so that every $B$ inary tiling w as stilldegenerate, but there w as a unique (or nearly unique) decom position of every $B$ inary tiling con guration into 4 rhombi.

In the Binary tilingss ${ }^{37}$, the Sm all vertices $m$ ay occur isolated, but m ost often form chains. In the \halfw " (or $W$ ) unit cell ( $F$ ig. [4(d), the chains are unbounded (extending in the y direction), whereas in the 3223 cell and also the 2038 cell the chains are just two vertices long.

## 2. Results of $4: 0 \mathrm{~A}$ edge sim ulations

The post-hoc justi cation of the 4.0 A tile decoration is is that its con gurations have an energy typically about
0.006 eV /atom lower than a 2.45 A result such as Fig. $\mathbf{2}$, even though it has a reduced site list. (T hese low er energy con gurationsw ere found in less tim e and at a low ertem perature, too, than on the 2.45A tiling.) On the 2038 tiling, the actual low energy con gurations found after a 2.45A -level run of long duration are sim ilar to the those in $F$ ig. 1 of $R$ ef. 15, which was created from $4: 0 \mathrm{~A}$ sim $u-$ lations.
$T$ his suggests to us that this lim ited ensem ble includes all of the low est-energy states of the original ensem ble; the rem oval of som e sites sim ply keeps the M C from getting stuck in localw ells of som ew hat higher energy. T he $m$ ost problem atic issue of local environm ents excluded by the site-list reduction was the \short" A l-C o bonds, discussed in A ppendix B 1 .

W e found the 13A decagon to be robust, form ing in our usual $32 \quad 23$ cell over a range of com positions $\mathrm{A} b_{0: 7} \mathrm{Co}_{0}: 3 \mathrm{x} \mathrm{N}_{\mathrm{k}}$ for $\mathrm{x}=0: 05$ to $0: 15$ (w ith the standard density), and also over a range of atom densities 0.066 to 0.076 . A $^{3}$ (at the standard composition A $b_{0: 7} \mathrm{Co}_{0: 2} \mathrm{~N} \mathrm{i}_{0: 1}$ ). (T hese were later checked by $\operatorname{sim} u-$ lations w th the sam e atom content on the 4.0A scale tiling of Subsec. IIIE.) In the $\backslash W$ ( $\mathrm{A} \mathbb{1}$ oN i)" unit aell, 13A D s were checked to apppear at densities 0.069 to 0.072 w ith com position $A l_{0: 718} C 0_{0: 211} \mathrm{~N} i_{0}: 071$. A dditionally, we con m ed 13A D form ation when the potentials were cuto at radius 10A as well as the standard 7A, or w th standard conditions in every unit all from Tabl I.

W e can now go beyond the idealized description of idealized chusters, to note som e tendencies for variations (especially the TM placem ent). A though these $m$ ay be expressed in the language of a nule, they are at this point only statisticalbiases (prim arily based on our $23 \quad 32 \quad 4$ unit cellw ith our standard com position and density, and $m$ ostly using sim ulations on the 4A-tiling site list of Sec. IIIE.) Only in Sec. IV will these observations be tumed into actual rules.

A though we presented rings $2,2.5$, and 3 as having 10fold sym $m$ etry, that is an oversim pli cation and $m$ any site occupations get $m$ odulated according to the orientation of the core TM pentagon; (Thus it will not be surprising that a long-range order of the orientations develops, as detailed in Sec. VI.) In particular, the ring 3 A 1 atom s along the decagon's edges usually are placed in a layer di erent from that of the ring 1 TM atom S , which $m$ eans that (in pro jection) these A lare altemately displaced clockw ise and counterclockw ise from the bond center. H ow ever, whenever N ioccupies a ring-3 TM site, both the adjacent ring-3 A latom s tend to adopt the sites in the opposite layer, at a distance of 2.54 A from the Ni , regardless of the core orientation. $\mathbb{N}$ ote the adjacent ring-3 TM sites are very likely $\mathrm{C} \circ$, and this displacem ent puts the A lCo distance to 2.45 A , nearly the bottom of the A I-C o w ellw hich beats the the A IN iattraction.) Finally, ifw e draw a line from the center ofa 13A D through an A latom in ring 1 and extend it through the vertex of the 13A D, the site im $m$ ediately outside of the decagon along this line (in projection) has a preference for TM
w th very strong tendencies tow ards N i. (If not occupied by N i or $\mathrm{C} \circ$, such sites are m ost often $\mathrm{A} l$ rather than vacant.) This induces a relationship between the core orientation and the placem ent of the Star clusters that are richer in N i.

C hanges in the net A ldensity \{ forced, in our sim ulations, when we changed the overalldensity while keeping stoichiom etry constant \{ are accom m odated by the 2.5 ring. (T he Star cluster is less exible: it has a xed num ber of atom s.) To anticipate Sec. $\mathbb{I V}$, the ring $2.5 / 3$ A l's can be altematively described as the vertioes of a D ecagon $H$ exagon $B$ oat-Star tiling w ith edge 2.45A, and the A lcount can be increased by replacing H exagons and Stars by B oats.

## F. E ects of TM com position changes

$T$ he TM sites in the 13A decagon (found in ring 1 and ring 3) are norm ally Co (and otherw ise are alw ays N i) $T$ his $w$ as checked by a special series of lattioe-gas $M$ onte C arlo runs in which only Ni / C o sw aps w ere enabled; this con m ed a C o preference in ring 1. H ow ever, when there is an excess of N iatom s \{ because either the N i fraction or the overalldensity has been increased \{ N iatom s start to appear in ring 2.5 of the 13A D (in which case the nearby A latom s behave som ew hat di erently from their regular pattems). Excess N i atom s even enter som $e$ ring 1 TM sites, in which case the neighboring ring 2.5 (Al) sites are less likely to be occupied (as expected, in light of the pow erfiula l-C o potential).

W hen N iatom s are added at the expense of C 0 , they typically substitute rst for $\mathrm{C} \circ(3)$ on the boundary of a 13A D, on sites adjacent to N i of a Star cluster. This presum ably dismupts the puckering units that w ould otherw ise be centered on (som e of) those Co's.

W e observed how N i atom s are inconporated without decreasing $\mathrm{C} \circ$, when the atom density was varied while the sam e lattice constant and the standard com position $\mathrm{A} \mathrm{h}_{0} \mathrm{CO}_{20} \mathrm{~N}$ in 0 were m aintained. In this case, Ni atom s typically enter ring 2.5 in the 13A decagon, creating a localpattem ofTM occupations that w e call the \arrow ." $T$ his is convenient to describe in the language of the 4A mom bustiling. Say that a 13A D comer site is lined up w th $\mathrm{a} \mathrm{C} \circ$ (1) [ring 1] site and occupied by $\mathrm{N} i$, and also has am N i nearest neighbor in an ad jacent Star cluster: call these sites $\mathrm{Ni}(3)$ and $\mathrm{Ni}(\mathrm{s})$, respectively. Then additional $\backslash N i(2.5) "$ sites appear inside the 13A $D$, in the sam e layer as the $\mathrm{Ni}(3)$. The head of the $\backslash$ arrow " is the 72 angle that $\mathrm{Ni}(\mathrm{s}) \mathrm{m}$ akes w th the two $\mathrm{Ni}(2.5)$, as in F ig. 6 .

The ve TM's $\mathbb{N i}(3)+2 \mathrm{Ni}(2.5)+2 \mathrm{Co}(1)]$ form a regular pentagon, centered on the $\mathrm{A}(2)$ of the sam e layer. This $A l(2)$ is also surrounded by $A l(1)+2 A l(2)+2 A l(3)$ in the other layer, so the com bination is an $A I_{6}(T M)_{5}$ just like the core of a 13A decagon, except that only two of the TM 's are Co, and also the pentagon of ve Al's is quite distorted in this case.

The density threshold, above which \arrow s" appear,


FIG.6: [color] \A rrow" con guration athigh Nidensity. This pattem is seen at low er right, on the edge of a 13A decagon in which one $\mathrm{Co}(1)$ from the inner ring has been converted to N i. The overall atom density $\left(0.074 \mathrm{~A}^{3}\right)$ is som ew hat above the physical range. At a $m$ ore realistic density, it appears the sam e \arrow" con gurations and N i substitutions occur, but much less frequently. The lines in this gure connect pairs of TM atom $s$ in di erent layers and separated by 4A in the xy plane. T he color conventions for species are the sam e as F ig. 2 .
was $0.068 \mathrm{~A}^{3}$ for the 3223 tiling, and $0.071 \mathrm{~A}^{3}$ for for the $W$-all tiling. The di erence $m$ ight be due to our enforcing the standard stoichiom etry in both cells, although the ideal $N$ i. 0 ratio $m$ ust di er since the Star cluster:13A D ratio for these cells is, respectively 1:1 and $2: 1$.

N iatom s are very often found in Star clusters. W hen two Star clusters adjoin, it $m$ akes a pair of candidateTM sites from the respective Star clusters, and these often form a N iNN i pair. H ow ever, these candidate-TM sites have a large num ber of A l neighbors, hence one of these is viable site for Co occupation (in which case the other becom es Al). In general, 2.5A TM-TM bonds, wherever they are found, will usually be N iNN i since this $m$ axim izes the num ber of $2.5 \mathrm{~A} \mathrm{~A}-\mathrm{C} \circ$ contacts (recall the A $1-C$ o well is deepest, A 1-N i being only the second deepest well)
G. C om parison to $N$ i-rich decoration

In this subsection, we com pare our present results to previous work on the \basic $N$ i". phase ${ }^{13,14,17}$.

O ur path at this point is actually som ew hat di erent from that taken for the basic $N$ i structure ${ }^{13}$. In the case of $\backslash$ basic $N$ i", a hexagon-boat-star (HBS) tiling with a 2:45A edge length was used in the analog of our second stage sim ulations. T his was follow ed by a third stage using an in ated HBS tiling w th edges ${ }^{2} a_{0} \quad 6: 5 \mathrm{~A}$ (w ith a determ inistic decoration). That description was sim ple, because (to a good approxim ation) the decoration w as context-independent, i.e. has the sam e approxim ate energy independent of which tiles w ere adjacent. Speci cally, alledges w ere decorated in the sam e w ay, and there was no strong constraint relating the A latom sin the tile interiors to the surrounding tiles. This rule was checked by a sim ulation at the ideal com position, and the result-
ing con gurations were identical to the ideal decoration, apart from one or two defects per sim ulation œell.
$T$ hat tem plate cannot be completely transferred for our Co-rich phase. In this case, it is harder to neglect instances of $\mathrm{Co} / \mathrm{N}$ i substitution. In particular, though the TM atom $s$ on the boundary of the decagon ob ject should be idealized as C o, there are specialenvironm ents in which they clearly are converted to Ni , which introduces a context-dependence into the decoration. A lso, there are com plicated rules forA latom s around the outer border of the decagon (i.e. in rings 2.5 and 3), as well as for the occupation of TM atom $s$ in the ve candidate sites of the Star cluster. T hese degrees of freedom interact w ith the tiling geom etry, as well as each other.

O ur choice for \basic Co" second stage was to go directly to the 4.0A DHBS tiling of Sec. IIIE (which is essentially a 10A edge B inary tiling), thus building in an assum ption of the frequency and low energy of the 13A decagon cluster. W e were not really able to reach a third stage sim ulation, which properly would have required a complete understanding of puckering and its interactions. Indeed, in Sec. IV] we will present a determ inistic decoration rule, for a particular com position, taking into account the tendencies noted in Sec.IIIE and Sec IIIF. But this rule is m ore speculative than the \basic N i" rule of Ref. 13 , in particular no M C sim ulation reproduced its energy (they were higher, by at least a sm allenergy

## 1. C om petition of basic-N i and decagon based structures

W e now tum to the physical question of the com petition betw een the B asic- N i and B asic-C o structure variants in the A HCoN i phase diagram . The \basic N i" phasse is de ned by frequent $N$ iN inearest-neighborpairs (form ing zigzag chains along the z directions), and $\mathrm{C} \circ$ at centers of a HBS tiling w ith edge $a_{0} \quad 2: 45 \mathrm{~A}$, w ithout any 5-fold sym m etric $m$ otif; whereas \basic $C o "$ is de-
ned by the two types of 11 -atom pentagonal clusters that form the centers of 13A decagons and Star clusters. Now, in Subsec. IIIF, it is described how added N i atom s appear inside the 13A D as Ni(2.5), adjacent to $\mathrm{C} \circ$ (3). If we also replace this $\mathrm{C} \circ(3)!\mathrm{Ni}(3)$, we get a N i-N ipair (TM in a pair alw ays tends to be N ito free up C o to havem ore A lneighbors, since A l-C o has a stronger bond than A HNi as we have repeatedly rem arked.) It is indistinguishable from the characteristic N iN ipair in the $\backslash$ basic $N$ i" phase of $d-A \mathbb{N}$ iC $c^{13}$. In other words, the $m$ otifs of that phase are appearing continuously as the com position gets richer in Ni . [In the language of the 2.45A -edge-D HBS sm alltiling introduced in Sec. IV, the sm all tile around that TM (3) m ust becom e a H exagon, like the tile in the \basic N i" decoration ${ }^{13}$.]

W e incom pletely explored this com petition by som e variations in the site list, in the unit cell size/shape, or in com position. It appears there is a barrier betw een the basic-N i and basic-C o structures in our sim ulations,
perhaps a therm odynam ic barrier or perhapsm erely a kinetic one due to our handling of the degrees of freedom. Thus, there is no assurance that sim ple brute-force sim $u-$ lation w ill reach the best state. T he only reliable criterion is to anneal each com peting phase to a $m$ inim um -enegy state, and com pare the respective energy values.

W e used the $12 \quad 14$ sim ulation cell for a direct study of the com petition of the \basic N i" and \basic $\mathrm{C} \circ$ " kind of structure; they were found to be practically degenerate in energy throughout the Ni C o com position range. But in a sim ilar sim ulation in the standard 3223 œell, the preference for the $\mathrm{A}_{6} \mathrm{C}_{5}$ rings was much stronger. O ur interpretation is that the $\mathrm{A}_{6} \mathrm{C} \mathrm{O}_{5}$ cluster is not robustly stable by itself, but only when surrounded by the other rings of the 13A decagon. Since the 1214 unit cell is too sm all to allow a proper ring 3, the full bene $t$ of the 13A D arrangem ent is lost and the balance is tilted tow ards the \basic $N$ i" type of structure, which is built of sm aller (2.45A-edge HBS) tiles and has no frustration in a cell this size.

It is interesting to note here that the theoretical phase boundary found by Ref. 35 in the A l-C o-N i com position space, running roughly from A 上 $_{6} \mathrm{CO}_{24}$ to A h $_{0} \mathrm{~N}_{30}$, corresponds fairly well to the dom ain ${ }^{44}$ in which decagonal A l-C o-N i is them odynam ically stable. In other words, $d(A \mathbb{I C} \circ \mathrm{~N}$ i) occurs at all only when the two com peting structure types are close in energy.

A useful diagnostic for the phase com petition was used by H iram atsu and Ishi i35, which m ight be called the weighted di erenced pair distribution function. O ne takes the di erence of the pair distribution function (as a function of radius) betw een two com peting phases, and $\mathrm{m} u$ ultiplies it by the pair potentials. The large positive and negative peaks then reveal which potential wells favorwhich kind ofstructure. The dom inant contributions tumed out to be A 1-TM nearest-neighbor wells favoring the decagon-based structure, and A l-A l nearest-neighbor repulsion favoring the basic -N istructure.

## 2. 20 A decagons?

W e have just observed that using the wrong size of unit cell $m$ ight spuriously exclude the optim al type of tile or cluster. T hus we m ay well w orry whether even our standard unit cells are large enough to obtain the m ost correct structure.

U nfortunately, it is not feasible to sim ulate larger cells using the 2.45 A random-tiling lattioe-gas. It would be necessary instead to devise a new decoration, which is m ore constrained than the 2.45A sitelist of Sec. IIIA but less constrained than the 4 A rhom bus decoration of Sec.IIIE. A Itematively, as som e con jectured atom ic structures are available based on 20 A decagons (see A ppendix E , one $m$ ight design a decoration which can represent structures built of either 13 A decagons or 20A decagons.

The same caveat (about the unit cell size) applies to earlier work by some of us on the \basic Ni i" modi cation ${ }^{13}$ In that case, too, electron $m$ icroscopy studies had suggested structure models having 20A diam eter clusters w ith pentagonal sym m etry ${ }^{66}$.

## IV. IDEALIZED DECORATION

In this section, we present an explicit m odel structure, derived by idealizing the sim ulation results of Sec.III, as a decoration of a 10.5 A -edge B inary tiling. Such idealizations are necessarily speculative $\{$ they go beyond the sim ulation observations that inspire them ; nevertheless, they are im portant for several reasons. First, they m ake available an explicit $m$ odel for decoration or di raction. It is trivial to construct a quasiperiodic B inary tiling; decoration of this speci es a quasiperiodic atom ic structure, which $m$ ay be expressed as a cut through a vedim ensional structure, and com pared to other models form ulated that way $3,45,49$. (It should not be forgotten that the rules also allow the decoration of random tilings, which am ong other things can be used to sim ulate di use scattering.)

Second, we hope that a well-de ned rule for chem ical occupancy corresponds to an energy $m$ inim um, in that all the good sites for a particular species are used, and no $m$ ore. For this reason, it is quite natural that an idealized $m$ odel has a som ew hat di erent stoichiom etry and/or density than the sim ulations it was abstracted from. O nce we have an idealmodel, the e ect of sm all density or com position variations $m$ ay be described by reference to it. T he ultim ate validation of an idealized m odel is that it provides a low er energy than any sim ulations w ith the sam e atom content (and low er than other idealized $m$ odels we m ay try).

Them ain issue in passing to a com plete rule is to system atize the A larrangem ents in rings 2.5 and 3 of the 13A decagon (which are apparently irregular, and surely not vefold sym $m$ etric), and secondarily the TM arrange$m$ ents in the Star chuster. This will im pel the introduction (Subsec. IV B of yet another tiling, the 2.45 A -edge decagon-hexagon-boat-star (D HBS) tiling.

It should be recognized that the details of variable A 1 around the edge of the 13A decagon are crucially modied by relaxation, as w ill.be reported in Secs $V$ and $V$ II. $N$ evertheless, we rst describe the structure as it em erges w ithin the xed-site list because (i) this is the path that our $m$ ethod necessarily leads us along; (ii) m ost of the structure ideas of the xed-site list have echoes in the m ore realistic relaxed arrangem ents. In particular, the ring 2.5 and ring 3 pattems (including short bonds) becom e the \channels" for A 1 atom s of Subsec. V C; the 2.45A HBS tiles in Subsec. IV and the puckering units of Subsec. V IIB are centered on the sam e Co chains; and
nally, the xed-site explanation of the \ferrom agnetic" order of 13A decagon orientations is closely related to the puckering explanation (Sec.VI).
A. Inputs for the decoration rules

Next we give the starting assum ptions (based on Sec. III) which consist of (i) guidelines for the best local environm ents, given the (fairly arti cial) assum ption of the xed-site; (ii) the underlying tile geom etry which is to be decorated.

## 1. Guidelines for atom placem ent

The description inferred from M C runs left undecided (i) the choige of $\mathrm{C} \circ$ versus N ion sites designated $\backslash \mathrm{TM}{ }^{\prime \prime}$ in the 13A D ; (ii) the choige of $\mathrm{Ni}, \mathrm{C}$ o, or A lon the sites designated \candidate TM " in the Star chuster; (iii) the location of A l sites in rings 2.5 and 3 of the 13A D. We seek the $m$ inim um energy choices, guided by the salient features of the pair potentials in Table $\mathbb{1}$ and by the typicalcon gurations resulting from sim ulations on the 4. (A tiles (Sec. IIIE 2). To resolve details, we also used spot tests (in which selected atom swere ipped by hand) and the site energy function (Sec. IIID 3).

G uideline 1, the strongest one, is the TM -TM superlattice, w ith separations $4: 5 \mathrm{~A}$. N ote that though A $1-T M$ potentials are stronger than TM -TM, the negligible A lA l potential seem $s$ to allow the TM $-T M$ interaction to dom inate the TM placem ent. This spacing should be enforced particularly for $\mathrm{Co-C} \mathrm{\circ}$, since that potential is som ew hat stronger than C o- N i or N iN i.

G uideline 2 is to $m$ axim ize num ber (and optim ize the distance) of nearest-neighbor A l-C o contacts, since this potential well is very favorable. A corollary is that TM TM nearest neighbor pairs tend to be Ni C o or Ni N i ( $w$ ith the glaring exception of ve Coin the 13A D's core), so as to increase AlCo at the expense of A l-N i bonds. (This last fact is $m$ ore im portant in a $N$ i-rich com position ${ }^{13}$.)

G uideline 3 is that in the central ring of the Star cluster, the favorable location for Ni (occasionally Co ) is on the line joining its center to that of an adjacent 13A decagon, whenever that line passes over an Al (rather than a TM) atom in ring 1 of the 13A D. ( $T$ hat line is an edge of a 10.5 A binary tiling rhom bus).
2. B inary $H$ exagon $B$ oat-Star tiling

Follow ing Subsecs. IIIB and IIIC, our decoration is based on a packing of 13A decagon clusters and Star clusters on the 10.5A -edge binary tiling. W e anticipate the results of Sec. VI by orienting the 13A decagons all the sam e way. This has strong im plications for the Star clusters. T he latter sit on \sm all" vertioes of the B inary tiling, which (as is well known) divide bipartitely into \even" and \odd"sublattioes: every 10.5A rhom bus has one vertex of either kind. Because of the 13A decagon's
vefold symm etric core, the adjacent even Star clusters are not related to it the sam e as adjacent odd Star


FIG.7: Idealized atom decoration for a bilayer (c 4A) structure on the 4023 tiling, given an arrangem ent of 13A decagons (shown by light lines). A tom species and layer are identi ed by sam e convention as in earlier gures. The 13A decagon edges are m ostly covered by 2.45A Stars and Boats, shaded gray, which specify the placem ent of A 1 atom $s$ in the D ecagon's ring 2.5 and ring 3 . The sites along the lines connecting adjacent Star clusters are TM (Nion the even glue cluster and Co on the odd one), as m arked by arrows. The even Star clusters (norm ally) have Ni in the directions tow ards the nearest $D$ ecagons, as pointed out by dotted lines; these also m ark edges of the 10.5 A B inary H BS tiles.
clusters. W hen the 13A D cores are all oriented the sam e, then the Star clusters of one sublattice \{ we shall call it E ven \{ have every candidate TM site aligned with ring-1 A lof the adjacent 13A D which boy Guideline 3) is favorable for TM occupancy. On the other hand, in the O dd Star clusters the only sites favorable for TM are the ones adjoining a TM - lled site in the adjacent even Star cluster; the rest of the sites are favorable for A 1.

The strong even/odd distinction, and the lack of a prom inent pattem on the Odd Star clusters, inspires a slightly di erent way of representing the 10.5 A tile geom etry. If one erases the vertices that center the $O$ dd Star clusters, and the binary-tiling edges that connect to them, the rem ainding vertioes and edges form a hexagon-boat-star tiling w ith 10.5 A edges. T his de nes a random tiling $m$ odel called the \B inary HBS tiling". (Ref. 25 introduced this term, for a di erent A l-C o-N i decoration using 4A -edge tiles, but it has im plicitly appeared in som e prior decagonalm odels.) This is not equivalent to the ordinary random HBS tiling, since it is still constrained by additionalcolorings of the vertioes as \large" or \sm all", carried over from the B inary tiling. H ow ever, it is essentially equivalent to the random $B$ inary tiling, since there is a 2 -to- 1 correspondence betw een the tile con gurations (depending on which sublattice of $\backslash$ sm all" vertices is designated \even").

The B inary HBS tiling, like the cluster orientations, has only a vefold symmetry, implying a pentagonal

| 2.45A tile | $\begin{array}{\|c\|} \hline \text { C ontent } \\ \text { A l Co N i } \end{array}$ | In 10.5 A tiles Fat Skinny | $\begin{aligned} & \text { A lnbrs. } \\ & \text { (each TM ) } \end{aligned}$ |
| :---: | :---: | :---: | :---: |
| D ecagon | $10 \quad 50$ | 0.602 | $4+6$ |
| Even Star C luster | $10 \quad 5 \quad 5$ | 020.4 | $3+4$ |
| H exagon | $3 \begin{array}{lll}3 & 1 & 0\end{array}$ | 00 | $3+6$ |
| B oat | $\begin{array}{lll}5 & 1 & 0\end{array}$ | 30 | $4+6$ |
| Star | $\begin{array}{llll}6 & 1 & 0\end{array}$ | 01 | $5+4$ |

TABLE IV : A tom content for decoration in $F$ ig. 7. The nam es are for tile ob jects in the 2.45A -edge D HBS tiling. For the counts in colum $n$ 1, A lon the tile comers are apportioned according to the comer angle. The num bers of each tile ob ject in the 10.5 A -edge $B$ inary tiling rhom bi are also given. T he last colum n gives the A 1 coordination of the TM atom ( s ) $\mathrm{m}+2 \mathrm{n}$ where m A lneighbors are in the sam e layer at 2.45A, and 2n A lneighbors are in the ad jacent layers at 2.54 A .
space group for the quasicrystal.
B. The 2.45A D ecagon $H$ exagon $B$ oat-Star tiling

N ow we introduce yet another tiling. Its edges are $a_{0}=2: 45 A$, as in the initial stage single-layer rhom bus tiling, but these tiles are 8A diam eter D ecagons, as well as H exagons, B oats, and Stars, so we call this the \D HBS" tiling. (See Fig.7). The vertices are decorated w ith A latom S , in the even (odd) layers for even (odd) vertices. The 8 A decagon ( w ith edge 2.45A) is a subset of the 13A decagon; its perim eter (vertex) atom s are the ring 2 Al from the 13A decagon. Each even Star cluster is represented by ve 2.45 A Hexagons in a star arrangem ent; since these $H$ exagons are decorated di erently from the regular kind, this com bined unit will be treated as a separate kind of tiling ob ject called $\backslash$ E ven Star cluster". (An O dd Star chuster center is just a corner where three 2.45A B oats or Stars m eet.) The 8A decagons and E ven Star clusters, which are xed once a 10.5A B inary HBS tiling is speci ed, are show $n$ in white in F ig. 7 .

The rem ainder ofspace $\{$ that is, the 13A decagon borders $\{$ becom es tiled w ith $2.45 \mathrm{~A} H$ exagon/B oat/Startiles (show n shaded in Fig.7. The extemalvertioes of the H BS tiles represent allA l(2) [ring 2 of the 13A D], allA l sites in the Star cluster, and allA 1(3) [ring 3]. Each HBS tile interior includes one $\mathrm{C} \circ$ on its \intemal vertex" (form ed when the HBS tile is subdivided into rhom bi), and also Al site (s): one per H exagon, two in each B oat or Star. $T$ hese last A lsites represent allA $1(2.5)$ in the 13A D and all A l on candidate-TM sites of the Star cluster. Thus, the placem ent of HBS tiles directly determ ines that of the ring 3 Al , but not of the ring 2.5 Al . The Even Star type hexagon is a special case: its two intemal sites are $\mathrm{C} \circ-\mathrm{N}$ i in the decoration of F ig. 7 but in others (see Subsec. IV E w ould be N i-N i.

It should be em phasied that the above description is not just a reform ulation of the observations in Sec. IIIbut is, in fact, an additional insight into the $m$ otifs em erging
from the lattice-gas $M$ onte C arlo on the 4.0A rhombi. The 2.45A DHBS tiling is not just used to describe the nearly ground-state structures (which are the focus of this section), but also the less optim alcon gurations that were our typical best snapshot from a M onte C arlo run (at the 4.0A stage), or the con gurations found when density and com position are som ew hat changed, such as in Fig.6. D espite $m$ any irregularities, alm ost the entire space between D ecagons decomposes into HBS tiles. O ne di erence from the description given above is that, in these im perfect con gurations, the Even Star cluster grouping of 2.45A H exagons is seen less; also, either Hexagon lling (TM-TM or Al-TM) may occur anyw here.

It w illl be noticed that all our decorations of the H BS tiles are identical to those in the \basic $N$ i" structure ${ }^{13}$. $T$ he im portant di erence is that in \basic $N$ i", there w ere no 8A D ecagons: the HBS tiles lled space by them selves. $T$ his suggests that, asN icontent is increased, conceivably the \basic Co" structure evolves sm oothly to the \basic N i" structure by lling less of space by $8 A$ decagons, and m ore of it by HBS tiles.

## 1. Optim ization am ong HBS tilings

The next question is to single out the DHBS tilings w th the low est energies. The particular A lcon guration depicted in F ig. 7 was obtained by adjusting A l corresponding to di erent 2.45A HBS tilings to optim ize the energy in this (40 23) unit cell. All the tilings being com pared had equal num bers of A l-C o rst-w ell bonds, aswellas TM atom $s$ in the sam e positions, so any energy di erences $m$ ust be due to the second well of $V_{A 1} 1 \mathrm{~m}$ (which is about $1 / 9$ as strong as the rst well, see Table Il). The total energy di erence betw een two of these states is estim ated to be of order $10\{50 \mathrm{meV}$.

W e can interpret the result in the light of G uideline 2 from Subsec. IV A 1, together with the last column of T able ITI. T he largest energy tem is proportional to the num ber of A l-T M (especially A l-C o) bonds; w ith the xed sites available, the bond distances are either $2: 45 \mathrm{~A}$ (in the sam e layer) or $2: 54 \mathrm{~A}$ (interlayer); the A $1-$ Co potential is stronger at the form er separation, leading in principle to sm aller energy di erences even $w$ ith the sam e num ber of A l-C o bonds. N ow, C o centering any HBS tile has a good Alcoordination (9 or 10), but this is best in the 2.45A B oat cluster \{ m ainly because that has $m$ ore A latom s. H enœ, the num ber of B oats should be $m$ axim ized, as is the case in $F$ ig. 7. (Recall that tile rearrangem ents allow us to trade 2 B oats $\$$ H exagon + Star in an HBS tiling.)
$T$ he TM in the 2.45 A Hexagon tile has a sm aller num ber $Z_{A 1}$ of $A 1$ neighbors. Thus, if Ni concentration is increased at the expense of Co , the Ni atom s will rst occupy these TM sites (on account of the strong A 1-C o attraction). A lso, where TM -TM neighbors are forced, this tends to occur in 2.45A H exagon tiles. For exam ple,
the \arrow " m otif of induced by increased N i concentrations just consists of three successive 2.45A H exagons on the border of the 13A decagon, each of them having a TM -TM interior occupation (See Fig. (6).

## 2. Pentagonal bipyram id $m$ otif?

The com parison of nearest-neighbor A l coordinations m issed one im portant fact: a 2.45A Star tile is generally part ofa largerm otifw ith pentagonal sym $m$ etry. Em pirically, it is invariably surrounded by a pentagon of TM atom $s$ (at 4.46A) in the other layer than the centralTM. $T$ his $m$ eans that Star tiles are strongly biased to be on the ve 13A decagon comers that line up radially $w$ ith a $\mathrm{Cos}(1)$ (of the core), and not the other ve comers. [I hat $\mathrm{Co}(1)$ is needed to com plete the outlying TM pentagon.]

In projection, the ve TM atom ssurrounding the Star, togetherw ith the ve A latom sat its outer points, form a decagon of radius 8 A . The other ve Alatom s on the Star's border tum out to lie in \channels", in the ter$m$ inology of the follow ing section (see Sec. V C), which im plies that in a relaxed (and m ore realistic) structure, these atom s displace out of their layer. The 5 A l+ 5 TM atom $s$ form ing the outlying decagon all sitt in the same layer which tums out to becom e a m irror (non puckering) layer upon relaxation. In the end, the totalm otif is sim ply the \pentagonal bipyram id", a fam iliar motif in decagonal structure 23,38.

## 3. A ltemate description using 4 A DHBS tiles

The decoration depicted in Fig. 7 has 5 N i+ 5 Co on the intemal sites of the E ven Star C luster, which ensures that the 13A decagons have purely Co atoms (never Ni ) on their outer vertioes (ring 3). T he 2.45A Stars and $B$ oats are the $m$ ost favorable locations for $T M$ (C O). The N isite in the even Star cluster is the least favorable of the TM sites in this decoration.

W e pause to express the results in the language of the 4A -edge DHBS tiling. This tiling has been studied in less detail, for it is less handy than the 2.45A DHBS or the 10.5 A B inary HBS tilings, for the follow ing reasons: (i) di erent 4 A HBS tilings, in som e circum stances, can correspond to the sam e atom ic con guration; (ii) W e lose all hope of system atically describing the A l(2.5) atom s. (iii) the Al(3) variability is now represented by arrows along tile edges, the rules for which are unclear. (W e m ight im pose $P$ enrose's $m$ atching rules, on the edges in HBS tiles \{ leaving the 13A D edge as a \w ild card" that $m$ atches anything \{ how ever that probably disagrees w ith the energy $m$ inim ization.)

The 4.0A HBS tiles are of course com binations of 4A mom bi. The 13A D is a tile ob ject, while the space between 13A D s gets covered by 4A Stars, H exagons, or B oats. The tiles \{ at least, w ith the decoration of F ig. 7 $\{$ have Co on every exterior vertex (in altemate layers).
(a)



FIG. 8: (a). M apping from an arrow con guration to the 2.45A -edge HBS tiles in the DHBS tiling. The means that two incom ing arrows, 72 apart, are never allowed. The arrow ed edges belong to the 4.0 A -edge tiling. (b). The 10.5 A -edge B inary HBS tiling (gray edges, intemaledges dashed) with 13A decagonsplaced on it. (N ote that, to accom odate exam ples of all three HBS tiles, a cell would be needed considerably larger than the W -phase cell of Fig.7.) Solid lines m ark edges of the 4.0 A -edge DHBS tiling. Even Star clusters, $m$ arked $w$ th $\backslash+$ ", get represented here by edge 4.0A Star tiles; an odd Star cluster, marked by a $\backslash \mathrm{l}$, is found on the intemal vertex of every 10.5 A H exagon, B oat, or Star tile, and is represented by a 4.0 A tile of the sam e shape. The direction of a light arrow is forced by the orientation of the even Star cluster next to it; the bar blocking that arrow $m$ arks a boundary of the independent arrow subnetw ork on that 10.5 A B inary H BS tile. T he heavy arrow s have variable direction, as described in the text, and determ ine 2.45A HBS tiles, as show $n$ in (a). The black disks $m$ ark sites which are favored (by the core orientations in adjacent 13A decagons) to be the root from which a tree of arrow s em anates, i.e. to be the center of a 2.45A Star tile.

Each 4A HBS tile contains, centered on its \interior vertex", one Star cluster. The 4.0A HBS tiling is shown in Fig. 8 decorating the 10.5 A

It is appropriate here to review what our decoration does in tem s of the originally identi ed 11-atom Star cluster motif, which (roughly speaking) goes with the 4.0A DHBS tiling. The decoration of $F$ ig. 7 places Ni on all ve of the candidate-TM sites of the Even Star clusters; O dd Star clusters receive tw O, one, or zero Co according to whether they occur (see Fig. 8 in a H exagon, B oat, or Star of the 10.5 A B inary HBS tiling; this Co appears next to each neighboring E ven Star cluster.
C. Enum eration of A l placem ents

The packing of space by HBS tiles, which can be done in $m$ any ways, is a convenient way to enum erate (while autom atically enforcing neighbor constraints) allpossible
ways of placing $A$ latom $s$ in rings 2.5 and 3 . This is seen even clearer using the abstraction in F ig. 8 .

1. Enum eration of 2.45 A HBS tiles (and Al(3) placem ents)

In this idealization (see Fig. 8(b)), every edge of a 13A decagon has one Al atom (which is also a vertex of the 2.45A HBS tiles) dividing it (in projection) in the ratio ${ }^{1}$ : ${ }^{2}$. The choice on each edge is represented by an arrow pointing tow ards that A latom, and Fig.8(a) show s the translation from the arrow sto the language of HBS tiles. E very even Star cluster is represented by ve 2.45A hexagons, which in the arrow language translates to a boundary condition of a xed arrow direction (indicated by light-headed arrows in $F$ ig. [8(b)). The netw ork of arrow ed edges has comers of coordination 2 or 3 , the latter being where tw 0 13A decagons share. A the latter comers, it is forbidden for both arrows to point inw ards (the corresponding A latom s w ould be too close).

In enum erating the possible 2.45A HBS tilings, there are several answ ers, because we $m$ ay place varying degrees of constraints on those tilings. First, if we perm it any $m$ ix of $2.45 \mathrm{~A} H / B / S$ tiles, then on every Fat 10.5 A rhom bus in $F$ ig. 8 (b) we could independently orient the three free arrows in any of the six ways allow ed by the 72 constraint: that would give $6,6^{3}=216$, or $6^{5}=7776$ choices on the 10.5 A H exagon, B oat, orStar, respectively.

Let us, how ever, $m$ axim ize the num ber of 2.45 A B oats as justi ed earlier, which means there are no 2.45A hexagons (apart from those com bined into the Even Star cluster ob ject). Then, at every vertex in Fig. 8 , either allarrow spoint outw ards (which m akes a 2.45A Star); or one arrow points inw ards and the rest point out (a 2.45A B oat). N ow, each 10.5A B inary HBS tile has exactly one connected subnetw ork of arrow s. H ence, in every subnetw ork, exactly one vertex $m$ ust have its arrow sallpointing outw ards, and serves as the root of a tree; at the other vertices, the arrow spoint outw ards from that root. T hus, the rem aining freedom in B oat/Star placem ent am ounts to which vertex has the \root" vertex, or equivalently where the unique 2.45A Star gets put. (O n the 10.5 A H exagon, a second 2.45A Star gets forced near the tip with a 13A decagon.) There are four choices to place the \root" per 10.5 A H exagon and ten choices per 10.5 A B oat. But on the 10.5A Star, there are just tw o choices, since there is no \root" in this case \{ the only freedom is whether the arrow s run clockw ise or counterclockw ise in a ring around the center.

W e have not yet taken into account an additionalfactor that reduces the degeneracy of the H B S netw ork: nam ely, the 2.45A Star is preferentially located on the ve vertices of the 13A decagon $\{m$ arked w ith black dots in $F$ ig. 8 \{ that are aligned w ith the core $\mathrm{C} \circ(1)$ pentagon. C ounting the black dots in each large ( 10.5 A ) HBS tile, we nd three choiges in the large H exagon, seven choioes in the B oat, and (for the sam e reason asbefore) just tw o choioes in the Star. A Star and a H exagon together would thus
have $23=6$ choices; but the sam e area converted into tw o B oats has $7^{2}=49$ choices. Thus, if the entropy of these nearly degenerate arrangem ents plays a role \{ and it must at $\mathrm{T}>0$, in a xed-site lattice gas sim ulation $\{$ it assuredly favors the $m$ axim um possible content of B oats in the 10.5 A -edge B inary HBS tiling.

## 2. E num erating internalAl (ring 2.5) placem ents

The intemalA l's in the B oat have alw ays been placed in the (unique) sym $m$ etrical arrangem ent. In the $2.45 \mathrm{~A}-$ edge Star, there are ve possible placem ents of the two intemalA 1 ; we insist on the rule that there be one internalA lnear to each 8A D ecagon that the 2.45A Star adjoins, since this adds one A l-C o bond. [T he bond is $w$ ith $C o(1)$ from the 13A $D$ 's core; such A l's were counted in the coordination 4+ 6 listed for the $\mathrm{C} \circ$ (1) in T able $\mathbb{I V}$. In the case of a 2.45 A Star betw een two 8A D ecagons, this rule still leaves freedom am ong three of the ve placem ent choices; w e think they are virtually degenerate, since they all have exactly the sam e counts of nearest-neighbor distances.
$T$ he freedom in the 2.45A -edge $H$ exagon is som ew hat di erent, being associated with the two ways ofbreaking it into rhombi. O ur Co placem ent rule would say the 13A D comermust be the Co site; in the speci c version of that decoration illustrated in Fig. 7 and tallied in Table IV there are no H exagons at all, so their internal decoration is a moot question. The Coplacem ent rule also applies to the Even Star cluster type hexagon, even though its other interior vertex is Ni . (In reality, the Even Star cluster hexagon would $m$ ore naturally be occupied by N i-N i rather than C o-N i: see Sec. IV E.)
$T$ he resolution of the rem aining near-degeneracy of the 2.45A structures not only depends on tiny energy differences, but quite likely the optim al placem ent of the \root" vertex breaks the local m irror sym $m$ etry of the B oat or H exagon tile: then the absolute ground state would depend on interactions (at an even $m$ ore $m$ inus cule energy scale) betw een the \root" vertex placem ents on neighboring tiles.

It would not $m$ ake sense to pursue these intricate details, for the real behavior of the ring $2.5 / 3 \mathrm{Al}$ atom s (which dom inated this section) is actually govemed by \puckering" as explained in Sec.V. Since the puckered structure is still built out of 2.45A D HBS tiles, the general fram ew ork rem ains valid, but our detailed enum eration is not, since a di erent subset of the 2.45A D HBS tilings $m$ ay be preferred. $W$ e have not investigated that as far as we took the xed-site case in this section, but we can guess that the degeneracy resolution is at least equally intricate.

## D . Stoich iom etry of the decoration

It is easy to nd the num ber offat and Skinny binary tiling rhom bi at the 10.5 A scale for a unit cell, and also in an in nite vefold sym $m$ etric tiling (where the num ber ratio of Fat to Skinny is :1). Then if we know what atom $s$ are contained in each 2.45A DHBS tile and how m any of the latter are contained in each 10.5 A rhom bus (both of which are given in Table IV), we can obtain the totalatom contents.

To calculate the num ber of sm all (2.45A ) D HBS tiles on each large ( 10.5 A ) B inary tiling rhom bus, we decom pose both of these into sm all (2.45A) mom bi. The edges of the tw o kinds of rhom biiare in the ratio ${ }^{3}: 1$, so their areas are in the ratio ${ }^{6}=8+5=13+8{ }^{1}$; fiurther$m$ ore, the area of a Fat and Skinny rhom bus on the sam e scale are in the ratio :1. For exam ple, each large Fat rhom bus decom poses into 13 sm allFat rhom bi+ 8 sm all Skinny rhombi. The sm all (8A) D ecagon accounts for 5 Fat + 5 Skinny sm all rhombi; the Even Star combination of ve specialsm all H exagons accounts for 5 Fat + 10 Skinny sm all rhom bi. W hen those contributions are subtracted, the rem aining sm all rhom bi are assigned to sm all Star ( 5 sm all Fat rhom bi) and sm all Boat (3 Fat +1 Skinny sm all rhombi). Rem em ber it is possible to convert tw o B oats! sm allStar + sm allH exagon, which converts their atom content to $\mathrm{A}_{10} \mathrm{Co}_{2}!\mathrm{A} \mathrm{l}_{9} \mathrm{CO}_{2}$; that freedom was resolved in T able IV by m inim izing sm all H exagon content (thereby m axim izing $\mathrm{A} l$ content). T he net decoration of 10.5 A tiles is then $\mathrm{A} l_{23} \mathrm{Co}_{7} \mathrm{~N}$ in on the Fat and $\mathrm{Al}_{2} \mathrm{CO}_{4} \mathrm{~N}$ i2 on the Skinny.

If applied to a B inary tiling with vefold symmetry (that is, a quasicrystal having no perp-space strain), the overall stoichiom etry w ould be A $l_{0: 722} \mathrm{C}_{00: 225} \mathrm{~N} \dot{b}_{0}: 053$ That is obviously poorer in Ni than intended, even though the sam e decoration gives the desired stoichiom etry when applied to the large ( 40 23) approxim ant in Fig. 7. The reason an unusually large approxim ant is necessary, in order that both the decoration rule and the stoichiom etry agree w ith that in the quasicrystal lim it, is that the N i and C o placem ents are inhom ogeneous at relatively large scales.
E. A lternative decoration rules

How should we $x$ the unreasonable stoichiom etry of the above-speci ed decoration (when applied to general tilings)? If we review the guidelines from Sec. IV A 1, it $m$ akes sense to convert half of all the 2.45A B oats into Stars and H exagons (the A latom s are a bit ovenpacked $w$ hen B oats are neighbors). It also $m$ akes sense to convert $m$ uch $\{$ say half $\{$ of allC $o$ on the Even Star C luster into Ni (we know TM pairs are strongly favored to be N i-N i). N ow the atom content is $\mathrm{A} \mathrm{l}_{22: 25} \mathrm{CO}_{6: 5} \mathrm{~N}$ i $1: 5$ on the F at and $\mathrm{Al}_{2} \mathrm{Co}_{3} \mathrm{~N}$ is on the Skinny, giving a m ore reasonable net stoichiom etry of $]_{0}: 717 \mathrm{C}_{0}: 186 \mathrm{~N}$ ib:097.

In Sec. 2 of Ref. 16, we speci ed a distinct ideal
decoration, sim ilar to the variation just outlined. Its purpose was not only to accom odate a larger Ni fraction am ong the TM atom s, but especially to decorate 13A decagon clusters of arbitrary orientation. It still uses the 10.5 A -edge B inary tiling w ith 13A D chusters placed on the \large" vertices, and (possibly overlapping) Star clusters placed on \sm all" vertices; but unlike the decoration of Fig .7 , each 13A D has an orientational label which is an independent variable of the tiling. If we lim it ourselves to clusters oriented the sam e way, that rule says (in this section's language) the Even Star cluster object has Ni-N ioccupation on all ve of its H exagons (this includes both those that connect to an Even Star cluster center, and other 2.45A H exagons that reach into a 13A decagon, so $\mathrm{Co} \circ$ (3) on som e of its comers are converted to $\mathrm{Ni}(3)$. The decoration in Ref. 16 w as incom plete, in that no attem pt was $m$ ade to specify the Al(2.5) and A l(3) positions.

## F. 20 A decagons?

O ur story till now has skipped over the possibility of decagonal clusters larger than our 13A decagon. The question is pertinent, as 20A diam eter decagons have often been identi ed in electron $m$ icrographs as the basis of a cluster netw ork. In fact, reexam ination of F ig. 7 reveals that around every 13A D, there is another nearly perfect decagon larger by a factor, so its edges are
${ }^{2} \mathrm{a}_{0}$ and its vertex-to-vertex diam eter is $2^{3} \mathrm{a}_{0}=20: 8 \mathrm{~A}$; these 20A decagons, of course, overlap, wherever the 13A decagons just shared an edge. Each vertex of the outer decagon has an A l: this is either the center ofa Star cluster, or a ring 2 A latom from an adjoining 13A D.Every edge of the outer decagon has two atom $s$ in di erent layers, dividing it in the ratios ${ }^{2}:{ }^{3}:{ }^{2}$; these are usually both TM, but are A I/C o where they belong to ring 1 of the adjoining 13A D.

It should be noted that our xed-sitem odel \{ described this way, via overlapping clusters that cover all of space \{ is practically identical to Burkov's mode ${ }^{46}$. This was inspired by an early structure solution ${ }^{47}$ as well as a con jectured real-space chuster ${ }^{48}$, (based on electron m icroscopy), for $d\left(\mathrm{~A}_{65} \mathrm{Co}_{15} \mathrm{Cu}_{20}\right)$. Burkov's decoration is based on a B inary tiling of edge 10.5 A , the sam e as ours. $T$ his is decorated by overlapping 20A decagons, known as B urkov clusters, which share a decagon edge when situated at the far tips of a Thin mom bus (here they are separated by 19.7A ), or overlap when situated across the short diagonal of a Fat rhom bus.

Burkov's atom sites are nearly the sam e as ours, but the chem ical species are som ew hat di erent (note he m ade no attem pt to distinguish am ong TM species.) M ost im portantly, Burkov's ring 1 consists of ten TM atom $s$, and furtherm ore the Sm all vertices of his B inary tiling (our Star chister sites) are generally decorated by $A 1_{5} \mathrm{TM}_{5}$, whether Even or Odd: thus, his structure m odel is 10 -fold sym m etric where ours is pentagonal.
(T he Sm all vertex decoration $m$ ust be $m$ odi ed where the clusters overlap, and thus ring 4 deviates a bit from 10-fold symmetry.) The $m$ ain other di erence is that Burkov has no ring 2.5 atom s, but has two ring 3 Al atom s on every edge of the 13A D ; if those atom s were allow ed to escape the xed ideal sites, as in Sec V, they w ill probably run to exactly the sam e locations (w ithin \channels") as they did from ourdi erent idealsites. A f ter our studies (of density variations, and relaxations as in Sec. V , it is clear that B urkov's m odel is unphysically \overpacked" w ith A latom s in the last-m entioned places.

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V. RELAXATION AND MOLECULAR
    DYNAM ICSANNEALING
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Up to this point, we have reported analyses of the sim ulations using rigid site positions. This section addresses $m$ ore realistic con gurations of atom $s$ found when the nal results are put through relaxation and $m$ olecular dynam ics (MD). O ur approach is sim ilar to relaxations on the \basic $N$ i" phase ${ }^{14}$. H ow ever, the present case di ens in that the xed-site stage, did not resolve certain alternative con gurations that are nearly indistiguishable in energy, thus we have not yet settled on a set of xeddecoration large tiles. In devising a realistic idealized structure for the \basic Co" case, study of the relaxed structures and energies is inescapable.

In this section, we brie y review the results of relaxations on a bilayer structure, and then consider the effect of relaxations when the sim ulation cell is doubled to
\&A. A subset of atom $s$ undergo signi cant displace$m$ ents out of the planes (\puckering"); the structure (at least, $m$ any A l sites) undergoes a sym $m$ etry breaking to the 8A period. The rem aining subsections are devoted to characterizing this \puckering", and explaining its origin theoretically. The puckering will be the key ingredient of the explanation for the ordering of cluster orientations (Sec. V I Studies of longer-range correlations of the puckering w ill be left to Sec . V II.

O ur standard cycle for these o -ideal-site sim ulations begins w ith a relaxation to $T=0$, in twelve stages of $\mathrm{T}=50 \mathrm{~K}$ each. W e then perform MD w th tem perature around $T=600 \mathrm{~K}$; this is rather low, as our purpose is not to heat the system so much that the gross structure can change, but only to anneal a subsystem of relatively loose atom s. just ne tuning the details. A fter M D, we once again relax the structure to $T=0$. $T$ his cycle as a whole is called relaxation $M$ D-relaxation ( $\mathrm{M} M \mathrm{R}$ ).

## A. R esults of relaxations

U pon relaxation to $\mathrm{T}=0$ [forboth 4 A and 8 A period], we nd that the TM lattioe is quite rigid and displaces only slightly from the ideal positions. The A l atom s, how ever, are sub ject to displacem ents as large as 1.5A. A fter RM R, a few ofthe A latom sdi use a com paratively
large distance of 1 A from their original sites, but their new environm ents are sim ilar to the original (relaxed) ones.

1. 4.08 A periodicity

A s a prelim inary, we relax the sam ebilayers (cell thickness $c=4: 08 \mathrm{~A}$ in the z direction) as were used in the xed-site sim ulations of Sec III. This excludes m ost possibilities of puckering, and prevent the associated energy reduction. Thus, no reliable conclusions can be based on energy di erences that appear in this stage.

The 13A decagon evolves as follow s under relaxations: (i) In ring 1, the A latom sm ove inw ards tow ards (but not all the way to) the lines joining the pro jections of the Co atom s . Thus, in projection, ring 1 \{ initially a decagon (w ith xed sites) \{ becom es $m$ ore pentagonal. (ii) The A latom sform ing ring 2 , unlike most other A l sites under relaxations, retain their positions quite rigidly. (iii) In rings 2.5 and 3, som e A latom s com pletely change position. These m oves usually occur so as to increase the num ber of nearest neighbor ( 2.5 A ) A l-C o bonds.

Under relaxation, the Star clusters are sub ject to num erous adjustm ents which adapt to defects in the 13A decagons or to deviations in the stoichiom etry from ideal. T he idealoccupation in the 13A D involves about a total of twenty A latom $s$ in rings 2.5 and 3. If any 13A decagon is lacking these Alatom s on an edge adjacent to a Star cluster, A l atom s from the Star chusters tend (under relaxation) to $m$ ove tow ards the vacanccy in the 13A D's 2.5 th / 3rd ring. P resum ably this is favored because it form $s$ the $m$ axim um possible num ber ofA lC o nearest neighborbonds to take advantage of the strong attractive potential.

## 2. 8.16A Periodic Structures

Relaxing an 8:16A periodic structure w ill cause the sam e general relaxations as described in the $4: 08 \mathrm{~A}$ periodic sim ulations. In addition, A latom s in ring $2.5 / \mathrm{ring}$ 3 tended to run to new locations, in which they are displaced in the $z$ direction out of the layers. This puckering develops as a spontaneous sym m etry breaking, local or (usually) global, wherein all displacem ents occur in tw o of the atom layers (identical, except that all the $z$ displacem ents are reversed) while the other two layers are $m$ irror sym $m$ etry planes. The atom ic arrangem ent in either m irror layer looks virtually identical to a 4.08 A structure after RMR, but som e Al sites di er between the tw om irror layers. On the other hand, the TM atom $s$ stay very close to ideal sites, they pucker very little even in layers where sym $m$ etry perm its it, and their positions rem ain practically identical in the tw o m irror layers (i.e. the TM lattice preserves the 2-layer periodicity) U sually, the layer in which a nearby 13A D has its central Al atom becom es a puckering layer, whereas the layer in
which the ring 1 C o atom s sit becom es a puckering layer, as will be justi ed in Subsec V C and A ppendix C.
B. A lum inum Potential M ap

H ere we introduce a general fram ew ork to predict or rationalize the optim um positions of $A$ latom $s$, independent of the xed-site list. It relies on the assertion $m$ ade in Sec. IIB 1]: one rst places the transition $m$ etals (w ith their long-range interactions) into a sort of rigid quasilattice, and then optim izes the arrangem ent of Al (w ith their weak mutual interactions) around the TM s. To $m$ ake this scenario quantitative we introduce the A lpotential function $U_{A 1}(r)$ :
where $\mathrm{fr}^{0} \mathrm{~g}$ and $\mathrm{fr}^{\mathrm{D}} \mathrm{g}$ are C o and N isites. T his is directly analogous to the potential (for a test charge) in electrostatics, w th the replacem ent electron ! A latom, and C oulom b potential! pair potentials. It is convenient to study the potential based on ideal positions for all transition m etals while om itting any A $1^{50}$

F igs. 9 and 10 show tw o dim ensional slices (in planes of local $m$ irror sym $m$ etry) $w$ ith the energies $U_{A 1}(r)$ depicted grayscale. The $U_{A l}(r)$ functions plotted in this paper were produced for $r$ on a discrete grid of points covering the unit œll, taking the TM positions in a low energy con guration from the 4.(A -edge (bilayer) xedsite M onte C arlo sim ulation (Sec. III). This had rst been put through RMR: the only e ect on the A lpotentialm ap is to $m$ ake it slightly $m$ ore realistic, on account of the sm all displacem ents the TM atom $s$ undergo in response to the \typical" A l distribution. The gray scale representing energy was cut o at a maxim um around +1 Ryd to hide the large (and irrelevant) variations of $\mathrm{U}_{\mathrm{A} 1}(\mathrm{r})$ inside the hard core of each $T M$.

How is the potential function intenpreted to yield a set of Al sites? W e start by noticing $U_{A 1}(r)$ has a set of rather sharp and deep local minim a; each is where several spheres coincide, representing $m$ inim a of A l-TM potentials around di erent TM atom s . Each shanp well, starting with the deepest, should get lled with one A l atom. (W hen minim a are separated by less than A, we m ust take into account the signi cant A l-A linteraction, but this is not a serious worry for this stage, since these deep $m$ inim a are well isolated.) T he A l sites lled in this fashion include the central atom and ring 1 of the 13A decagon cluster (at center of $F$ ig. 9 (c) and (a), respectively), or the analogous atom $s$ in the Star cluster (upper left in Fig. [9(a) and (c), respectively), as well as ve of the ring 2 A latom s ( F ig (c) center) 51

The sites associated w ith single, deep wells w ere easily discovered w thout the help of the A lpotentialm ap: they are the unproblem atic Alatom $s$ in the xed-site ideal structure (e.g., A lin ring 1 and 2 of the 13A D ) that w ere obvious even in our rst stage sim ulations. The potential


FIG. 9: (a) A lum inum potentialm ap $U_{A 1}(r)$ in the TM poor layer. The double line show $s$ the intersection $w$ ith the $z$-slice in $F$ ig.10. (b) T he central im age show s the actual atom ic coordinates under $R M$. Sm all circles represent atom $s$ in the $T M$ ridh layer, which will becom e the m irror later under period doubling. Larger circles are in the TM poor layer, which will pucker under period doubling. (c) A lpotentialm ap in the TM -rich layer.


F IG .10: A slice of the A lpotentialm ap along the c direction of the sam e con guration as $F i g$. 9. The $m$ iddle portion is aligned on an edge shared by two 13A decagons. The top double line show s intersection $w$ ith the cut in the right im age of F ig. 9 while the bottom double line show s the intersection w ith the left im age. Atbottom, the color/shade scale (in eV) is given for all our A lpotentialm aps.
$m$ ap o ers the follow ing advantages over sim ulation: (i) it helps explain the structure from m icroscopics; (ii) it show s the energy barriens for an A latom to pass betw een di erent localm inim a, which ilhum inates how A latom s di use between sites during MD and relaxation; (iii) it can locate potentialm inim a that lie outside of the atom ic layers; (iv) it revealspotentialw ells which arem oderately deep, but extended rather than shanp, which requirem ore sophisticated treatm ent (Sec. V C).

The A l potential m ap has a com plem entary relationship to another diagnostic, the \site energies" described in Sec. IIID 3, below. The form er identi es good sites that are currently not occupied; the latter identi es unfavorable sites that currently are occupied. T ogether, they $m$ ay be used to guide $m$ odi cations by hand of idealized structures, so as to im prove the energies.

C . C hannels and puckering

T he isolated deep wells of $\mathrm{U}_{\mathrm{A}}(\mathrm{r})$ do not accom odate all the A latom s. Indeed one-dim ensional \channels" are evident, along which the A lpotential is low and com paratively at. Channels appear betw een two colum ns of TM (especially Co ) sitting in altemate layers, as show $n$ in $F$ ig. 11 (a); the TM are the white disks in the m iddle of F ig. 10. These TM colum ns typically lie (in projection) on adjacent vertices of the 4A-edge tiling. Looking at $F$ ig. 10 , a vertical slice through the periodic layers, we see how the A l has a potential trough which appears in the center as a verticalchain ofdark triangles, pointing in altemating directions. The track of the channelbottom roughly consists of line segm ents form ing a \zigzag" pattem, so as to connect the idealA l sites that fallbetw een the $C$ o chains in each layer. $\mathbb{F}$ ig 11 (a) show show, wherever the channel crosses an atom layer, it passes through an idealAlsite that is nearly at the $m$ inim um of three A I-C o potentials.] O ne expects A latom sw ould be com paratively free to slide along such a channel. O ur plots of $U_{A l}$ are com plem entary to those of the tim e-averaged A ldensity in a m olecular dynam ics sim ulation in Ref.14, from which \channels" were originally inferred to occur (in the \basic N i" structure.)

## D . O rigin of puckering in channels

In such a \channel", the TM interactions do not sufce to $x$ A l sites. W e m ust take A l-A linteractions into account in order to predict the A loccupation. W e start $w$ ith the A lpotential finction $U_{A l}(r)$ de ned in Eq. (2). Let us approxim ate a channelw ith a one-dim ensionalvertical track param etrized by z. A s evident in F ig. $11(\mathrm{~b})$,


FIG. 11: (a). Schem atic of a channel (shaded zigzag line) between two colum ns of $\mathrm{C} \circ$ atom s . The Alin each channel are close enough to feel a strong $m$ utual repulsion (arrows). (b). T he A lpotentialenergy (in R ydbergs) ] along the bottom of an actual puckering channel.
the A l potential variation along the trough is well modeled by

$$
\begin{equation*}
\mathrm{U}(\mathrm{z})=\mathrm{U}_{0} \quad \mathrm{U}_{\mathrm{c}=2} \cos (4 \mathrm{z}=\mathrm{c})+\mathrm{U}_{\mathrm{c}} \cos (2 \mathrm{z}=\mathrm{C}) \tag{3}
\end{equation*}
$$

Here $\quad+1$ (resp. 1) in [B), if the distant $C o$ atom $s$ are in even (resp. odd) layers. From plots like F ig. 11(b) one can read $\circ \quad \mathrm{U}_{\mathrm{c}=2} \quad 3 \mathrm{eV}$ and $\mathrm{U}_{\mathrm{C}} \quad 2.5 \mathrm{eV}^{\mathrm{V1}}$.

Let us explain the coe cient $\mathrm{U}_{\mathrm{c}=2}$ in (3); for sim plicity, we neglect $U_{c}$ until Subsec. C 2. If the adjacent TM colum ns were all Co, and we included only interactions $w$ th them, their tw ofold screw sym $m$ etry would guarantee $U(z)$ has period $c=2, m$ odeled by the rst term of ( $)^{2}$ ). $(\mathbb{N}$ eanby A $l$ in non-channel sites have the sam e sym $m e-$ try.) N ote that along the track, the $m$ inim $\operatorname{of} \mathrm{U}_{\mathrm{Al}}(\mathrm{z})$ lie right at the levelofeach atom layer. (T hose locations are equidistant from three Co atom s at R 2:5A, the very strong $m$ inim $u m$ of $V_{A l c o(r) .) ~}$ (his explains the period and sign of the rst non-constant term .

C onceivably, in som e $m$ aterials puckering could arise because the single-A l potential would have $m$ in im a out of the atom layers; but that is not the case in A $1-C \circ-N i$, so puckering $m$ ust indeed be a consequence of the short range A 1-A l repulsions (com bined with $\mathrm{U}_{\mathrm{A}}(\mathrm{r})$ ).

Ifboth localm inim a w ere occupied in each bilayer, the A l-A lspacing would be not $m$ uch $m$ ore than $c=2 \quad 2:(A)$, which is far too close; on the other hand, if only the best m in im um in a each bilayerw as occupied, and no other A 1 sat close to a channel, the totalA l content w ould be too sm all. T he solution is that there is room for three A lto $t$ in every two bilayers, as shown in Fig. 11(a). Since this $m$ akes the period to be 2 c , it is a sym $m$ etry breaking in each channel. Them ean verticalspacing $2 \mathrm{c}=3 \quad 2: 72 \mathrm{~A}$ is a bit closer than the A l-A l hardcore radius (see Table so the A l-A 1 forces are probably dom inant.
$M$ athem atical details are worked through in Appendix C.
$M$ athem atical details \{ how the collective energy of three atom $s$ in a channel depend on their collective position \{ are worked through in A ppendix C. The $\mathrm{U}_{\mathrm{c}=2}$ term favors atom sto sit in layers. The $U_{C}$ term (as show $n$ in the appendix) favors an individual atom to avoid the
layerw hich is (locally) TM -rich, but when there are three atom $s$ it favors one of them to sit in that layer, which is a point of local $\mathrm{z} m$ irror sym $m$ etry in that channel. The result is that if a layer is globally TM rich, it becom es a globalm irror sym m etry plane.

W e have been deriving the con guration of a channel assum ing it has a xed num ber of A latom s. A ctually, of course, this num ber is variable. T he optim um occupancy of each channelm ust be a function of the Alchem ical potential; equivalently (in our simulationswith xed Al content) it is the result of com petition $w$ ith com peting kinds of Al site (as measured by the site-energies). It w ill certainly change as a function of TM composition (changing the num ber of Cocolumns) and the total Al density (since a hom em ust be found for every A latom).

1. C om parison to $x e d$-site results

It is pro table to revisit the ideal-site m odels (Sec IV) w ith the \channel" picture of the A l placem ent. All of those variable A l's, e.g. those constituting ring $\backslash 2.5$ " in the 13A D, were in fact channelAl. How ever, in the ideal-site $m$ odels they w ere accom odated $w$ ith a periodicity c everyw here: how could that work, seeing that som e channels would have to $t$ in four A latom s? The answer is that the mirror-layer A l's are all in positions o set from channels, like the $m$ erged-A l site to be discussed in SedVIIB. They are never in linew ith the A lin puckering layers (w hich don't pucker in a xed-site approxim ation), and the extra $x y$ displacem ent allow s the mirror-layer A lto be accom odated w thout puckering. Such unpuckered con gurations of the puckering units are observed to com pete w th the puckered con gurations in actual sim ulations using RMR (see Sec. VIII).

$$
\begin{array}{ccc}
\text { VI. LONG RANGEORDER OF } \\
\text { 13A D ORIENTATIONS } &
\end{array}
$$

In referring to the \orientation" of the 13A decagon, we have alw aysm eant that of its $\mathrm{A} 1_{6} \mathrm{C} \mathrm{O}_{5}$ core, since the rest of the cluster, as laid out in Sec. IIIB, is ten-fold screw sym $m$ etric: only the occupation of ring 1 , and levelof the A latom at the center, break the sym $m$ etry. The orientation relationship of neighboring 13A Ds is essential because this w as a prerequisite for extending our sim ulation results to a full- edged decoration m odel (Sec IV), and because it is tied to the di erentiation of layers into $\backslash \mathrm{m}$ irror" and \puckered" layers, once relaxation is allow ed in a structure $w$ ith periodicity four (orm ore) layers (Sec, VI).
$T$ he ring 1 atom $s$ from adjacent clusters are basically too distant to have a signi cant direct interaction: the shortest interatom ic distance betw een the respective rst rings is $2 \cos 18 \quad a_{0} \quad 7: \mathbb{A}$, whereas our potentials w ere cut 0 around 7 A. Hence we $m$ ust look for $m$ ore subtle, indirect $m$ echanism $s$ to favor a relative orientation. Indeed, we have already encountered various ways the
positions of the A latom s in rings 2.5 and 3 , or the substitution of $\mathrm{Co}(3)$ by $\mathrm{Ni}(3)$, is m odulated by the core and thus reduces the sym $m$ etry of the outer portion of the 13A decagon (see Secs. IIIE, IV B 2, and C 2 in particular).
$T$ he interaction $m$ ust be $m$ ediated by other atom $s$ in one of two possible ways. Firstly, neighboring TM atom $s$ in the Star clusters interact w ith each other and also respond to the rst-ring orientations of adjoining 13A decagons: we suggest this is the origin of the \antiferrom agnetic" term (Subsec.V IC 1) Secondly, the variable A latom s in rings 2.5 and 3 are w th in range of ring 1 of both clusters. This contribution appears to favor \ferrom agnetic" order (Subsec. V IC 2) and is probably the $m$ ore important one, both for the $x e d$ site-list and for the relaxed, puckered structures w ith $c^{0} \quad 8: 32 \mathrm{~A}$.

## A. E ective Ising $H$ am ilton ian for orientations

Let us form ulate the problem as an Ising model. We take as given a xed netw ork of $N_{D}$ 13A decagons placed on the \large" vertioes of som e con guration of binarytiling rhom bi. Each 13A D m ay have either orientation, which is labeled by an Ising spin $i=1$ associated with that 13A D.This does not unspecify all the atom $s$ : there are options in the ring $2.5 /$ ring 3 A latom s , explained at length in Secs. IV B and IV C, aswellas TM atom s (especially in the Star clusters). For each of the $2^{N_{D}}$ possible combinations off $i g$, we de ne the orientation e ective Hamiltonian, $\left.H_{\text {or }}(f) i g\right)$, to be the $m$ in $m u m$ energy after all those other degrees of freedom are optim ized ${ }^{52}$ W e presum $e$ the orientation e ective H am iltonian is well approxim ated by an Ising $m$ odel,

$$
\begin{equation*}
H_{\text {or }}=\mathrm{X}_{\text {hiji }}^{\text {or }} i j ; \tag{4}
\end{equation*}
$$

where hiji m eans each nearest-neighbor pair is included once.

If $J$ or $>0$, the ground state obviously has $f{ }_{i} g$ all the same (clusters oriented identically), which we call \ferrom gnetic" (FM) in the Ising model language. If $J$ or $<0$, it favors an \antiferrom agnetic" (A F , also called \altemating") arrangem ent in which neighboring clusters alw ays have opposite orientations; that is possible, how ever, only if the 13A D cluster netw ork is bipartite. That is not alw ays the case on the B inary tiling \{ e.g. groups of ve 13A Ds can form pentagons \{ but in both our sim ulation cells, the netw ork happens to be bipartite.

In the rest of this section, we rst report num erical studies of the energy di erences between di erent arrangem ents, and then give physicalexplanations in term $s$ of the pair potentials and of structure $m$ otifs (identi ed in previous sections). T here is one story for the xed-site sim ulations, and a di erent one for the (physically pertinent) relaxed and M D -annealed sim ulations. A nother com plication is that the answ ers depend on the overall
density. Finally, the results show a strong dependence on the particular sim ulation cell being used. W e used both the standard $32 \quad 23$ celland also the $\backslash W$-phase" (40 23) ©ell.]
B. O rientation dependent energies (num erical)

For the num erical calculation, our procedure was to perform a series of M onte C arlo runs given FM orientations and a sim ilar series under the sam e conditions for AF orientations, recording the low est energy from each run (which is our em piricalapproxim ation of $H_{\text {or, }}$, as just de ned). W e average over tens of runs, since the run-torun uctuation usually exceeds the AF/FM energy difference. Simulations were done for xed-site ( 4 A tiling) M onte C arlo on the 3223 tiling as well as the $W$-phase tiling, and also with the $\backslash$ RMR" procedure (relaxation after M D annealing).

It was sim ple to constrain the orientations ofeach cluster. Recalled that in the mom bus decoration for our 4A M C sim ulations (Sec.IIIE), every 13A D cluster is forced in a particular orientation by the ve Fat 4 r mom bithat ( $w$ ith ve $T$ hin mom bi) $m$ ake up the decagon of $4 A$ tiles. In particular, only one of the two layers is even available as a candidate site for the centralA latom.
$T$ he results are given in Table V . Let $\mathrm{E}_{\mathrm{av}} \quad \mathrm{E}_{\mathrm{AF}}+$ $\left.\mathrm{E}_{\mathrm{FM}}\right)=2 \mathrm{~N}$ at, where $\mathrm{E}_{\mathrm{AF}}$ and $\mathrm{E}_{\mathrm{FM}}$ are the total energies for AF and FM orientations, respectively. A lso, $E_{d i} \quad\left(E_{A F} \quad E_{F M}\right)=N_{D}$, where $N_{D}$ is the number of 13A decagonsper cell.For these particular cells, in which neighbors are always opposite in the AF case, we can $\mathrm{m} m$ ediately extract $J$ or $=2 \mathrm{E}_{\mathrm{di}}=\mathrm{Z}$, where Z is the average coordination num ber of the cluster netw ork. $\mathbb{N}$ ote $Z=3$ in the 3223 tiling and $Z=2$ in the $\backslash W$-phase" tiling, so $J$ or is equal to the num bers in colum ns 5 or 6 , or the num ber in colum n 3 divided by 1.5).

Consider rst the xed-site sim ulations. In the 3223 cell we had $\mathrm{E}_{\mathrm{FM}}<\mathrm{E}_{\mathrm{AF}}$ for 0:068AA ${ }^{3} \ll$ $0: 074 \mathrm{AA}^{3} \mathrm{~T}$ hat is the whole range ofphysically reasonable densities; at higher or low er densities, $\mathrm{E}_{\text {AF }}<\mathrm{E}_{\mathrm{FM}}$ apparently. (O fourcells, the 3223 is the closest approxim ant to vefold sym $m$ etry, i.e. zero perp-space strain.) On the other hand, in the $W$-phase cell, we see $E_{A F}$ was alw ays lowest \{ though for $0: 070$ A A $^{3},^{\prime} \mathrm{E}_{\mathrm{FM}}$ was nearly as low. In other words, the concentration dependence is sim ilar in both cases, exœept

$$
J^{\text {or }}\left(\begin{array}{lll}
\mathrm{W} & \text { œell }) & J^{\circ r}(32  \tag{5}\\
\text { 23cell }) & 0: 2 \mathrm{eV}: \\
\hline
\end{array}\right.
$$

On the other hand, when the relaxed energies are com pared, we found $E_{F M}<E_{A F}$ in allcells and at allrealistic densities. In all cases, the interaction $J{ }^{\circ r}$ is of order 0:1 eV .

|  | 3223 |  | W -cell |  | W -cell | (rel.) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ( $\mathrm{A}^{3}$ ) | $\begin{array}{r} \mathrm{E}_{\mathrm{av}} \\ (\mathrm{eV} / \mathrm{at}) \end{array}$ | $\begin{aligned} & \mathrm{E}_{\mathrm{di}} \\ & (\mathrm{eV}) \end{aligned}$ | $\begin{array}{r} \mathrm{E}_{\text {av }} \\ (\mathrm{eV} / \mathrm{at}) \end{array}$ | $\mathrm{E}_{\mathrm{di}}$ <br> (eV ) | $\mathrm{E}_{\text {av }}$ | $\mathrm{E}_{\mathrm{di}}$ <br> (eV) |
| 0.66 | 0:471 | 0:101 | \{ | \{ | \{ | \{ |
| 0.68 | 0:453 | $0 \cdot 259$ | 0:447 | 0:007 | \{ | $\{$ |
| 0.70 | 0:430 | 0.181 | $0: 431$ | 0:123 | $0: 561$ | 0.1 |
| 0.71 | 0:414 | 0.197 | 0:410 | 0:083 | $0: 5445$ | 02 |
| 0.72 | 0:395 | 0.142 | 0:394 | 0:089 | $0: 5365$ | 02 |
| 0.74 | 0:348 | 0.012 | 0:335 | 0:143 | \{ | \{ |

TABLE V : Energies depending on 13A decagon orientations, as a function of num ber density. H ere E av is the m ean energy/atom [averaged over the cases of altemating (AFM) and identical (FM) orientations]. A lso, $\mathrm{E}_{\mathrm{di}}$ is the energy cost (per 13A decagon) of opposite orientations. T he num ber of atom $s$ in the sim ulation cell is $N_{\text {at }}=207$ for the 3223 sim ulation cell and $N$ at $=268$ for the W -phase (40 23) cell, while the number of clusters $\mathrm{N}_{\mathrm{D}}=4$ for both cells. The rst four colum ns are xed-site sim ulations, the last tw o colum ns w ere relaxed after M D.

## C.Explanations of orientation interactions

Now let us try to explain the above results. In the xed-site case, the data indicate the sign of $\mathrm{E}_{\mathrm{di}}$ \{i.e., thee ective interaction \{ variesw ith com position. It suggests $J$ or (for the xed-site case) is a sum of com peting term s of opposite sign, and we indeed identi ed both an FM and an AF contribution (below). The relaxed case is sim pler, since the result is $m$ ore straightforw ardly FM.

The enorm ous di erence, in the xed-site sim ulations, betw een the 3223 cell and the $W$-phase cell, is ascribed to the quite di erent relative ratio of 13A D s to Star clusters in the respective cells. T hat m eans that, if the stoichiom etry is constrained to be the sam e, the actual TM content of the Star clusters is quite di erent, which presum ably a ects the interaction term described next.

## 1. \A ntiferrom agnetic" cluster interaction via Star clusters

W e use D ecoration II (Sec.IV E). Let us assum e each nearest-neighbor pair of N i atom s in a Star cluster has a repulsive energy $\mathrm{V}_{\mathrm{N} i}$. ( T his distance is around 2.9A, which is not very good w ith the N i-N ipotential: see Table l.) H ow does this energy depends im plicitly on the orientations of nearby 13A decagons?

First, where a N iN i pair is present on an overlapping of tw o Star clusters, it alw ays sits at the center of a Thin mom bus of the 10.5 A -edge B inary tiling. In this environm ent it can be shown that we get exactly $2 \mathrm{~V}_{\mathrm{N} i}$ from N i pairs in the respective rings, independent of the orientations of the 13A D's centered of the far tips of that Thin rhombus, so this contribution is an uninteresting constant.

O therw ise, it can be show $n$ that every pair of ad joining 13A decagons, w ith the sam e (FM) orientations, creates one N iN inearest neighbor costing an additional $\mathrm{V}_{\mathrm{Ni}}$ (not
present in case of AF orientations). That gives $J$ or $=$ $\mathrm{V}_{\mathrm{N}}$ i, favoring AF arrangem ent.
$N$ otice that if the TM content were to be changed, there would be additional opportunities for optim izing the N iarrangem ent in the Star cluster. T hus thee ective interaction of 13A decagon orientationsm ay involve the
i for all 13A decagons surrounding the Star cluster. In that case, it is not clear if thee ective interaction rem ains pairw ise, nor w hether it rem ains A F in sign.

## 2. \Ferrom agnetic" cluster interactions via A l channels

C lusters want to have the sam e orientation for about the sam e reason that tw o steel balls, rolling on a m attress, want to be at the sam e place. (H ere TM 's in the clusters distort Alatom $s$ in channels in the sam e way the steelballs distort a m attress.) W e can understand it $m$ athem atically in term $s$ of Eq. (refeq: z ). W hen there are two distant TM colum ns near a channel in layers labeled by i, $j$, then the second coe cient in (3) becom es $\left(i^{+}{ }_{j}\right) U_{c}$. In the xed-site case, when each channelhas only one A l atom per bilayer strictly speaking, its position $w$ illlbe determ ined by $m$ in im izing (3). T he low estenergy is a term nearly independent of iplus $U_{c} j_{i}+{ }_{j} j$ which is the sameas $U_{C}\left(1+{ }_{i}{ }_{j}\right)$ when $i=1$,sowe read $\circ J^{\text {or }}=j_{c} j$ favoring the $\backslash F M$ " relation.

In the puckering case, a generalization of the last term of (C 4) is proportional to $(i+j)^{2}$, so we obtain a cross-term proportional to i j again favoring \ferrom agnetism ."

Now, $\mathrm{V}_{1}{ }^{\infty}$ depends very sensitively on how close $2 \mathrm{c}=3$ is to the A 1-A lhardcore radius, and consequently so does $J$ or. A corollary is that sm allchanges in the layerspacing can have large e ects on the orientation order.

## VII. SYSTEMATICSOF THE PUCKERING PATTERN

W e now retum to the thread of Sec. V : there we understood puckering w ithin an isolated \channel" betw een two colum ns of TM (usually Co ) atom $s$ in altemating layers A lled channel contains three A latom s per four atom ic layers. one in a mirror plane and two atom s assigned to the \puckered" layers above and below it. $T$ his picture does not specify which of the two $m$ irror layers gets occupied (which determ ines the out-of-layer displacem ents of the other tw OAl): this is a localtw ofold sym $m$ etry breaking. In this section, we address the puckering correlations, in particular the relation of the local pattem to the localgeom etry of tile packing/cluster network, and whether long range order of the sym $m$ etry breaking can be propagated. An e ective Ising model helps de ne the question, but is inadequate to answer it. Instead, we focus on \puckering units" de ned as the (up to ve) channels surrounding a Cocolum n, and their A l atom $s$, which are sub ject to strong steric constraints.

To explore the puckering pattems, we perform ed RM R on two bilayers, starting from a (4A periodic) xedsite con guration (of Sec IV), using the decoration of Fig. 7 Several independent relaxations (w ith MD annealing from $T=700 \mathrm{~K}$ to $T=0$ in stages of 50 K ) in the $\backslash \mathrm{W}$-phase" unit cell. gave substantially sim ilar arrangem ents ( F ig. (12). ( N ote m any channels had $\mathrm{n}=4$ A 1 , suggesting either the A lcontent w as too large, or the MD time was insu cient to allow Alatom s to di use betw een channels.) W ew ill analyze (in Subsec. VIIC) the typical pattems in the puckering units, and discover the key role of Star clusters in organizing longer-ranged correlations.

## A. Ising-spin variables and channeloccupancies

O neway to form ulate the puckering problem is to represent the sym $m$ etry breaking in each A lchannel.by an Ising spin-like variable ${ }^{53}=1$. (Here the index runs over all $\mathrm{N}^{\mathrm{ch}}$ distinct channels.) A rbitrarily designate one of the $m$ irror layers as layer 0, consistently throughout the system. W here layer 0 is occupied and layer 1 puckers upward, we de ne $\quad+1$; where layer 2 is occupied and layer 1 puckers dow nw ards, (Layer 3 alw ays puckers in the direction opposite to layer 1.) An Ising value $=+1$ corresponds on F ig. 12 to $\mathrm{a}+$ sym bol and a blackened circle, usually on a 4A tile edge and alw ays betw een a pair of $C$ o (identi ed in the lower panel) in di erent layers; sim ilarly $=1$ appears as an symbol and a white circle.

Now im agine com puting the total energy for every one of the $2^{\mathrm{N}^{\text {ch }}}$ channel con gurations. The result, one hopes, is well approxim ated using pair interactions between nearby channels, giving an e ective \Ising m odel" H am iltonian

$$
\begin{equation*}
H_{\text {puck }}={ }^{\mathrm{X}} \mathrm{~J}^{\text {puck }} \text { : } \tag{6}
\end{equation*}
$$

The e ective interactions $f J^{\text {puck }} g$ would depend on the locations of channels and relative to 13A decagon clusters, and also on the choige of TM occupancy of nearby sites $(\mathbb{N}$ i versus $\mathrm{C} \circ$ in m any places, but also N i versus A lin Star clusters.) The nal ground state would be determ ined by $m$ inim izing (6).

T he realstory is m ore com plex. W e have presupposed a xed set of channels, each containing $n=3 \mathrm{Al}$ and thus having an Ising \spin" degree of freedom. But if an A latom is moved in or out of a channel (so $n=2$ or 4), the atom s are locked in unpuckered layers. In the case $\mathrm{n}=2$, both Algo into a puckering layer since we found (see A ppendirC) the A l potential is low er there, but they need to pucker only negligibly (in response to distant Al). In the case $n=4$, som e of the Alm ust deviate sidew ays and the atom sites are essentially an arrangem ent (using \ring 2.5") of the xed-site structure of Sec. IV, so again there is no local sym $m$ etry-breaking


FIG.12: Puckering of 8A structure in a sim ulation in the $W$ phase cell (after RM R relaxation from a 4A periodic structure, a realization of the sam e decoration as in $F$ ig. 7. (a). Puckering pattem, show ing three of the four layers. The $\backslash$ " and \+ " sym bols represent, respectively, atom $s$ in $m$ irror layers 0 and 2. W hite (resp. black) led circles are atom $s$ in puckered layer 1, deviating in the plus (resp. $m$ inus) sense, where the circle radius is proportional to the displacem ent; gray circles have sm all puckering displacem ents. P uckered layer 3 has atom $s$ in the sam e places (apart from a handful of defects), each deviating in the opposite sense from layer 1. (b). O ne bilayer, show ing relaxed positions and atom chem istry w ith our usual conventions. The other bilayer is sim ilar, except at atom $s$ where the $m$ irror layers di er; those are alw ays A land can be identi ed from places in (a) where $\backslash$ " and $\backslash+$ " do not overlay. Locations ofpuckering units are show $n$ by circles, labeled A, $B_{0}$, and $B_{1}$ according to their environm ent in the tiling, as described in Sec. V IIC 1.
by puckering; in either case, there is no longer a spin at that place. ( O f course, a new w ill have appeared som ew here else, if $n=3$ now as a consequence of the m ove.)

Thus, the channeloccupation num bers $n$ are a separate degree of freedom. W e presum $e$ that, in $m$ ost channels, the optim um is $n=3$ and the energy cost of $n$ deviating is $m$ uch larger than the - interaction. But when the total A l available to channels is (say) less than 3 N ch, this forces a \doping" by $\mathrm{n}=2$ channels, and there are $m$ any nearly degenerate ways to place them. Since the puckering e ective H am iltonian depends on the con guration fn $g$, wem ay very easily nd that tw o separated variables are favored to be the sam e or opposite, depending on the occupancy of som e intervening


F IG . 13: Puckering in a typical 2.45A star. C olored circles (using the same conventions for species and layer) are the optim um con guration assum ing a bilayer (c 4A) period, given ideal quasilattice sites as used in lattice-gas sim ulation. $N$ ote that channel interpretation is valid here as well. If we draw lines from the center of the 2.45A star to the nearest TM atom s (3 are already draw $n$ as 13A $D$ edges, four channel form ations can be seen. ( $a, b$ ) E ach im age is two layers in a structure w ith 4-layer (c 8A) stacking period. T he large em pty circles represent locations achieved after relaxation. $T h$ is particular 2.45 A star is on a vertex shared by two 4.0A decagons (solid lines). (c). Side view; the z-direction scale is increased by a factor of 1.44 . Six TM atom $s$ are depicted from each bilayer as X's. Faded indicates that the TM atom lies behind the A latom in this projection.
channel. (T he location of channels $w$ th puckering also depends on the presence of N ineighbors to the C 0 atom s in the central colum $n$; that is also highly sensitive to com position and density, see Sec. IIIF)

Furtherm ore, under our protocol \{ M D sim ulations at $m$ oderate tem peratures, starting from an arrangem ent on ideal sites $\{$ the occupancies fn $g$ are $m$ ainly quenched, after the ring $2.5 /$ ring 3 A l atom s have found their way into neanby channels; di usion of A from one puckering unit to the next seem $s$ to be suppressed. C onsequently we cannot trust M D sim ulation to discover the optim um arrangem ent; since the $f J^{\text {puck }} g$ are not only random but frustrated, the puckering e ective $H$ am iltonian in fact describes a spin glass.

## B. Puckering units

A description in term sofindependent channels is problem atic not only because of their variable occupation, but also (aswe shallsee) not every set off $g$ values ism eaningfulow ing to steric constraints.

Instead, our approach to $m$ ake sense of the puckering pattem is to de ne the \puckering unit" (Fig. (13), which consists of all channels (usually ve) centered on the sam e C o colum $n$, and their A lcontents. In ourm odels, each puckering unit is centered on a 13A decagon vertex and occupies one of the 2.45A HBS tiles introduced in Sec. IV B, which encircle the decagon center in the DHBS picture. In fact, the puckering units are alw ays on 13A D comers aligned (in pro jection) w th the ve core C o atom s , and the 2.45A tile is usually a Star. (T his is a consequence of how the latter $\mathrm{C} \circ$ atom s determ ine m irror layers, as expained in Sec. V C. The strong interactions betw een adjacent channels a sm all m enu of congurations for each puckering unit, from which one can build the larger-scale pattems of $f g$ in the structure.

Now, the channels around one Co column come very close in the ideal mirror-layer Al sites are $2^{1} \sin (2=10) a_{0}=1.79 \mathrm{~A}$ from each other and cannot sim ultaneously be occupied. \{ adjacent channels m ust have opposite signs of . But if (as usual) there are
ve channels, this altemation is frustrated. T he resolution is that tw o adjacent values are the sam $e$, but the two m irror-layer A l sites get m erged into one A lat the m idpoint. There is practically zero cost in the Alpotential for such a deviation: $F$ ig. [9(c) show $s$ the channels are actually connected by ring-shaped troughs in them irror layers, which include the fused Al sites. As for the puckering-layer A latom $s$, since they sit farther from the central axis, there is no steric rule against adjacent ones having the sam e puckering sign

Thus, in a fully puckered con guration, a puckering unit has room for only two Al atom s in either mirror layer, a total of four. These atom s generally arrange them selves into a m otif we call a \crooked cross" (see Fig. (13). In projection, one arm of the cross (consisting of two channel A l sites) is bent to an angle $2(2=5)$; it is bisected by a straight arm, consisting of a channel site on one side and a m erged site opposite to it. [If there were just four channels, both arm s of the cross are liable to be bent at angle $2(2=5)$ :]

> C. C on gurations in puckering units

In this subsection, we rst classify puckering units according to their environm ent $w$ ith respect to the 13A decagon-Star cluster geom etry (or equivalently the 10.4A -edge B inary tiling); we also classify the resulting pattems of A loccupancy and puckering in each puckering unit. Then, studying plots like Fig. 12 from separate RMR relaxations, we count the frequency of puckering pattems in each kind of location; indeed, the pattems
are nearly determ ined by the environm ents (especially if the placem ent of TM atom $s$ in nearby Star clusters is taken into account).

Besides the $W$-cell, we also perform ed RM R relaxations (starting from a di erent decoration) in the $32 \quad 23$ cell (not show $n$ ); in this case, the initial xed-site structure was the result of a lattice-gas M C sim ulation (using 4A tile decoration), rather than an idealdecoration rule. The behavior of puckering centers was di erent in the two approxim ants; one reason is that our 3223 structure ( $w$ ith a totalpoint density $0.068 \mathrm{~A}^{3}$ ) is packed w ith a much lower density of Al atom s than the $W$-oell (at density $0.070 \mathrm{~A}^{3}$ ).

## 1. $N$ om enclature for puckering units

W e categorize the puckering-unit centers on the $13 A$ decagon edge astype $A, B_{0}, B_{1}$, or $B_{2}$, according to where they fall on edges of the 10 A -edge B inary T iling. Type \A " sits on the interior of a Fat rhom bus of the B inary tiling; $m$ ore im portant, it is a vertex shared betw een two 13A decagons. A type $B$ site is along a ray connecting the 13A D center to that of a Star cluster, which is alw ays an odd Star cluster in the assum ed schem e of orienting the cluster centers. That ray is an edge of the 10.4A B inary tiling; the cases that it goes betw een Thin/Thin, Fat/Thin, or Fat/Fat rhom bide ne environ$m$ ents $B_{0}, B_{1}$, and $B_{2}$, respectively. The environm ent $\mathrm{B}_{\mathrm{k}}$ has at least 5 k colum ns of TM neighbors (in the other layer) from the 13A D itself, each of which creates one channel in betw een. It $w$ ill have $m$ ore channels (up to ve), whenever TM occupying the right candidate-TM site (s) of the neighboring Star cluster supplies the necessary second TM column.

In pro jection, the positions of them $m$ irror-layer atom $s$ next to the centralCo (appearing as + or symbols in Fig. (12) are the best way to visualize the con guration adoped by a puckering unit; So, we label the possible A l con gurations in a puckering unit by a letter \p" or \u" for \puckered" or \unpuckered", follow ed by the num ber $m$. \U npuckered" $m$ eans all the + and symbols are superposed in pairs (som etim es the pairs are not quite lined up); \puckered" $m$ eans the A 1 in one $m$ irror layer is $m$ issing, in at least one place. Farther out from the puckering unit's center, there are alw ays tw o puckeredlayer A l sites in every channel, each of which follow s the closest $m$ irror-layer A isite (s): displaced in a determ ined sense (large black or white circles in the gure) if the latter is puckered, undisplaced if it is not.

Finally, we som etim es add a + or superscript to the label, to record the parity of the puckering sense under the (vertical) $m$ irrorplane of the 13A decagonthat passes through the 13A D center and the Co puckering-unit center. (T he parity appears $m$ ore frequently.) Thus, a typical shorthand sym bol is $\backslash p 4+$ " . Still, som e of our labels refer to $m$ ore than one con guration. A unique way to nam e any puckering-unit con guration is given in

| Location type | C ell | N um ber <br> in cell | Frequency |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Ni | p4 | p5 | u6 |
| A | W - ell | 4 | 0 | 0 | 0.6 | 0.4 |
| A | 3223 | 6 | 0 | 0.6 | 0.4 | 0 |
| B 0 | W-mell | 4 | 0 | 0.9 | 0.1 | 0 |
| $\mathrm{B}_{1}$ | W - ¢ell | 8 | 0 | 0.1 | 0.5 | 0.4 |
| $\mathrm{B}_{1}$ | 3223 | 4 | 0.25 | 0.5 | 02 | 0.3 |
| $\mathrm{B}_{2}$ | $32 \quad 23$ | 4 | 0.75 | 0 | 02 | 0.8 |

TABLE VI: Frequency of local puckering con gurations (p4, p5, and 46 ) in puckering units, classi ed according to location type in the large tiling; these add to 1 . C olum $n \backslash N$ i" gives fraction where the central Co has a nearest-neighbor N i atom. T he total num ber ofdistinct puckering units w as 16 in the W -celland 14 in the 3223 cell. Each frequency is based on 20-50 exam ples of the puckering unit, in di erent places $w$ ith in the cell and/or from di erent runs.

## A ppendix D.

## 2. Results: statistics of puckering units

O ur observations need to be prefaced by a caution. The idealized decoration, when applied to di erent approxim ants, w ill lead \{ in view of the locally inhom ogeneous densities of species and of the binding energy in our model \{ to di ering densities and com positions for the approxim ants, and $m$ ay destabilize som e nite approxim ants $w$ ith a decoration that would be stable in the them odynam ic lim it. A s a corollary, if the sam e com position and density is forced on the di erent approxim ants, it m ay occure.g. that one of them is overpacked w ith Al atom $s$ and the other one is undenpacked.

Table VI sum $m$ arizes the statistics we found; they should be taken only as rough num bers, especially as runs taken under di erent conditions were com bined. Each colum n lum ps together several distinct pattems, distinguishable by the long nam es from A ppendix (if not by parity).

In the $\backslash \mathrm{A}$ " environm ent, half the units were p5, and the rest were p4 or u6, depending on A l density. Both $B_{0}$ and $B_{1}$ environm ents show a \crooked cross" pattem, in two variants oriented di erently $w$ th respect to the 13A D: B 0 has p4 while $B_{1}$ has p4 ${ }^{+}$A ctually, in the $B_{1}$ case, $A 1$ in the neighboring candidate-TM site in an $O$ dd Star cluster (which counts as a m erged $m$ irror-layer channel site) strongly tends to be unpuckered: thus the crooked-cross gets modi ed to p5 . Finally, the $\backslash \mathrm{B}_{2}$ " environm ent is typically an unpuckered u6.

How ever, the overwhelm ing factor a ecting puckering is whether the central Co has a Ni neighbor in the candidate-TM site of an adjoining O dd Star cluster, which is a merged-type site if there are channels on that side. In any case, the N i alw ays occupies both m irrorlayer sites, so that tends to favor unpuckered channels all around this puckering unit. A $\backslash \mathrm{B}_{2} "$ environm ent is typically unpuckered mainly because it typically has a N i
neighbor (at least in the 3223 cell). $N$ ote also that if the neighboring candidate-TM site of the odd Star cluster is not TM, then one or both of the candidate-TM sites one step aw ay probably is TM, which increases the num ber of channels in this puckering unit and (probably) $m$ akes it likelier to adopt a puckered con guration.

In TableVI, both A and B 1 environm ents are packed w th m ore $A$ lin the case of the $W$-phase cell, re ecting its higher overallpacking. D espite this, them ean occupancy m is practically the same ( 5.0 in the W -phase cell, 4.9 in the 3223 cell). The reason is that the $W$-phase cell contains another environm ent $\mathrm{B}_{0}$, which usually hasm $=$ 4 , while the 3223 contains $\mathrm{B}_{2}$, which usually has $\mathrm{m}=$ 6. If the overall density of Al (and hence its e ective chem ical potential) were set the sam e, we iam gine each environm ent type would show sim ilar behavior in both cells.

## D . Puckering around Star clusters

In any Even Star cluster, there tend to be TM atom s on all ten vertioes of its 4A -edge Star tile (of the DHBS tiling): most of them are 13A decagon vertices, while the others are candidate-TM sites where two Star clusters touch; as noted in Sec.III, the latter often have a TM $-T M$ pair. If furtherm ore the latter sites are $C O$, and som e candidate-TM sites of the Star cluster's interior are also occupied by TM, then the Star vertices not on a 13A D becom e puckering centers too, and all ten exterior edges have channels. This happens in the special decoration of F ig.7.

O $n$ the two edges $m$ eeting at a $2=5$ comer, the puckering sense should be opposite due to the steric constraint. At an indented [angle $3(2=5)$ ] comer, the sense is also opposite, i.e. the parity (w ith respect to the adjacent decagon) is , consistent w ith the usual tendency (noted above). Thus, the puckering sense altemates as one passes all the way around the Even star's exterior edges, producing a striking pattem in im ages of the puckering. (Such pattems are even $m$ ore prom inent in the real W (A IC oN i) structure: see Sec. V III.)

Furthem ore, when there is a chain ofStar clusters (as in the $W$-cell), the interaction betw een successive E ven Star clusters is such that their pattems have the sam e puckering sense. This accounts for m ost of channels around every 13A decagon (all those in puckering units of types $\mathrm{B}_{0}$ or $\mathrm{B}_{1}$ ). It leaves unspeci ed, how ever, what happens along the edge shared by two 13A decagons. $T$ he non-channel atom s nearby are perfectly sym $m$ etric under the (vertical) localm irror plane that includes the shared edge. A nd, follow ing the star rule just described, the puckering sense will be opposite on the adjacent unshared edges of the respective 13A decagons. Thus the puckering sense on the shared edge is necessarily given by a local sym m etry breaking, and cannot propagate the pattem from the Star cluster chain on one side to the Star cluster chain on the other side.

W ith the altemative decoration ofSubsec, IV E, the 4A edge star would not have C o on every vertex (nor would the 13A D, for that $m$ atter), and the puckering pattems just $m$ entioned would, one expects, be disnupted. On the other hand, in a m odelbuilt from disjoint 20A decagons (see A ppendix E), the Star cluster chains are more extensive and $m$ ight propagate a puckering sense globally. C onceivably, the puckering interactions $m$ ight be strong enough to tip the balance betw een di erent placem ents of TM atoms (e.g. altemative decoration) or between di erent basic structures (e.g. the 20 A decagon structures). The approach we follow ed in the present work could not answ er such questions, since the positions of all TM atom $s$ (and som eAl) are perm anently determ ined at the $x e d$-site stage of $m$ odeling.

## VIII. SIM ULATION OFEXPERIMENTAL APPROXIMANTW (ALCONI)

In this section, we com pare our prediction w the approxim ant structure $W$ ( $A \mathbb{C} \circ \mathrm{~N}$ i), currently the only re ned A l-C o-N istructure on the Co-rich side. The solution of of atom ic positions was done by Sugiyam a et ag using direct $m$ ethods (the $S \mathbb{R} 97$ package).

> A. A ttem pted prediction of $W$ (A 1 C oN i) by sim ulation

For our simulation, we used the same 4A rhombus tiling which optim izes the decagon density, as explained in Subsec. IIIE 1. A s inputs, we took the experim ental lattice param eters $23: 25 \mathrm{~A} \quad 39: 560 \mathrm{~A} \quad 8: 16 \mathrm{~A}$ and the experim ental reported point density and com position. ( $T$ his di ers from the standard com position and point density from Sec.IIB 2 that we have used up till now in this paper.) By com parison, the decoration of Fig. 7 has atom content $\mathrm{A}_{188} \mathrm{CO}_{60} \mathrm{~N}$ i20, which is too rich in Co com pared to real W ( $\mathrm{A} \perp \mathrm{C} \circ \mathrm{N}$ i), while its density of $\mathrm{n}=0: 071 \mathrm{~A}^{3}$ is slightly denser than real W ( $\mathrm{A} \mathbb{C} \circ \mathrm{N}$ i) (See table III).

The result of our discrete-site sim ulation \{ which our Fig. 7 was devised to idealize \{ looks quite sim ilar (in c-axis projection) to the experim entally determ ined W (A IC oN i) cell. ${ }^{9}$ H owever, a signi cant number of A l atom s present in the di raction re nem ent could not be found in our simulation result. A lso, the TM arrange$m$ ents in our Star clusters do not agree w ith those in the W -phase.

W e next apply the \relaxation-m olecular dynam icsrelaxation" (RMR) protocol de ned in Sec.V; in the $m$ olecular dynam ics portion, the tem perature was initially $\mathrm{T}=600 \mathrm{~K}$ and w as then cooled in gradual stages to $T=50 \mathrm{~K} . \mathrm{T}$ he RM R structure show s the usual puckering (Sec.V) sim ilar qualitatively to the prom inent puckering of the actual approxim ant.


FIG.14: P uckering in the $W$ ( $A \mathbb{C} \circ$ in i) structure, using sam e conventions as Fig. 12
B. P entagonalbipyram id cluster

The actualW phase di ens from our decoration (such as Fig.7) essentially by the follow ing modi cation: half of the Even Star clusters are replaced by a new cluster which is just the \pentagonalbipyram id" (PB) chuster ${ }^{23,38}$ identi ed long ago in $\mathrm{A}_{7_{3}} \mathrm{C} \mathrm{O}_{5}$ (and other decagonal approxim ants). W hereas the original (Even) Star cluster is N i-rich and 4A periodic in the stacking direction, the PB is A l-rich and strongly puckered (so it is 8 A periodic).

O ne novelfeature is that the apex TM atom (on thePB axis) puckers notioeably, which has not been true for any TM atom sup till now (even the ones in puckering layers, which are allowed by sym m etery to pucker). In fact, the arrangem ent around the PB center is quite sim ilar to that around a 2.45 A Star; indeed, the central TM colum $n$ is a new kind of puckering center that is not on any 13A decagon. The m irror-layer channelA ladopt a new puckering pattem, in which all ve go to the same layer and sit in $m$ erged sites.

T hem odelofR ef. 49 (elaborated here in A ppendix E 3) adopted the P B as its findam entalclusterbecause, in the realW phase, vefold sym $m$ etry extends quite far from its center. W e m ust disagree w ith their assignm ent of atom s of the innerm ost $P B$ ring as $m$ ixed $A 1 / T M$ : these are right in a channel, and should in fact be Al. C onceivably in a realstructure, there is som e disorder in the placem ent of the tw o w ays of decorating E ven Star chus-
ters. Since the TM ring of the \standard" Even Star cluster (ofF ig.7) occurs in the sam e place as the A l ring of the PB, that would give an averaged structure as if there were A I/TM substitutions.
C. Puckering propagated by Star clusters and PB s

Fig. 14 show s that the actualW -A 1 C oN istructure has a m ore pronounced and better propagated puckering pattem, as com pared to ourm odelstructures such as F ig $\sqrt[12]{ }$. The key to this is the PB which is, in a sense, one big puckering unit. T he three Alpentagons in the middle all belong to channels along the interior 4.0A edges in the ve-rhombus star containing a PB (the A lpentagon in a m irror plane consists of allm erged sites). A lthough the edges of the 4.0A -edge star have altemating puckering senses, just like the ordinary Even stars did, these are not the key atom $s$ for propagating the sense, The key atom $s$ are those $m$ irror-layer A l visible (in the top panel offig. (14) just inside the tips of that ve-rhom bus star, which lie in the sam e layer as the m irror-layer A l pentagon in the $m$ iddle.

These tip A latom s correlate the PB puckering w ith the adjoining Star cluster cluster, which puckers in the sam e pattem discussed in Sec. V IID, and thus propagates a well-de ned puckering pattem along each chain of Star clusters in the underlying tiling. Inside the 13A decagons, unlike Fig. 12, the ring 2 A latom s (not in a mirror layer) pucker strongly. Each (along with ring-2 .5 A 1 in the sam e channel) adopts a sense opposite to the nearest puckering atom $s$ from the Star chustersor P B's: the ring-2 A l facing Star clusters altemate while those facing PBs allhave the sam e sense, producing the com plicated pattem of white and black circles inside the 13A decagonsin] the top panel of Fig .14. H ow ever, just as in the PB-less case of Sec. V IID, it is hard to see how the pattem actually propagates from one chain of P B sand Star clusters, through the 13A D s, to the next chain over.

## IX . D ISCUSSIO N

In conclusion, we have carried out the m ost extensive prediction ofa quasicrystalstructure that $m$ akesm inim al assum ptions and com bines lattice-gas M onte C arlo w ith relaxation and $m$ olecular dynam ics. T he overall story of this project is that our approach, on the one hand is fruitful at producing atom ic structures w ith very good energies and very good local order (i.e. consistent w ith structural experim ents). On the other hand, its application is an art rather than an algorithm, and there is no guarantee of discovering the absolute best solutions. D i culties are to be expected especially when we must discem betw een variants that have sim ilar energies, yet cannot easily transform to each other: brute-force M onte $C$ arlo is not su cient to overcom e this energy barrier.

| T ile edge | T iling | Sections |
| :---: | :---: | :---: |
| 2.45A | rhom bus (tw o layers) | IIA (F ig. (1), IIIAA (F ig. (2), IIIB (F ig. 3 (a) only) |
| 2.45A | HBS (basic N | IIIG |
| 2.45A | D HBS | $\begin{aligned} & \text { IIID, IV B (F ig. 77), } \\ & \text { IV C (F ig. } 8 \text { ) } \end{aligned}$ |
| 4.0A | mom bus | $\begin{aligned} & \text { IIIB (F ig. } 3 \text { (b) on ly), IIIE, } \\ & \text { IIID (F ig. } 5 \text { on } \mathrm{ly} \text { ), } \\ & \text { V II (F ig. } 12 \text {, V IID } \end{aligned}$ |
| 4.0 A | D HBS | IV B 3 |
| 6.5A | D HBS | A pp.E 2 |
| 10.4A | $B$ inary <br> (nhom bus or HBS) | IIIC (Fig[4 (c) ), IV A 2, IV C (Fig. 8 , IV F, V IA, V IIC 1, A pp. B 3 (F ig. (15) |
| 17A | any | IV F, A pp. ${ }^{\text {E (F ig. } 17 \text { ) }}$ |

TABLE VII: Di erent tilings used in this paper to describe $d(A \mathbb{N}$ iC 0 ), w ith the sections (or gures) where they are referenced.

The \basic Co" structure tumed out to involve substantially m ore com plications than the \basic N i" case studied previously. O ne $m$ easure of the com plexity is that, at di erent places, it was convenient to introduce tilings on ve di erent length scales (related by powers of ). Table V Il gives sort of index to the sections where they were de ned or used.
$T$ here are three features of $\backslash$ basic $C o$ " that $m$ ade it $m$ ore com plex than \basic $N$ i", even at the stage ofm odeling lim ited to discrete ideal sites (sections [ I - IV): (i) a larger cluster unit (13A decagon), introduced in Sec. IIIB; (ii) a set of sites (the ring 2.5 and 3 Al ) which break the sym $m$ etry of the basic cluster; to rst order, these give rise to a high degeneracy, which is broken in fairly subtle ways (Sec. (IV). (iii) the orientational ordering pattem of the clusters, which strongly a ects the decoration even though it involves relatively sm allenergy di erences, that depend on com position and density in com plex ways (Sec. VII).

Sections V VV III developed a second layer ofsim ulation, the use of relaxation and $m$ olecular dynam ics to obtain $m$ ore realistic con gurations. This tums out to $m$ ake a fundam ental di erence in the \basic Co" case, because $m$ any of the A latom $s$ deviate from their xed positions to break the 2-layer ( A ) stacking periodicity down to 4-layer periodicity. T his happens (Sec. V) in \channels" due to colum ns ofC o atom sthat run perpendicular to the layers and are lled w th three A latom s each that de ne $m$ irror planes and puckered layers. We have explained this behavior in term s of the potentials (A ppendix C) \{ this work ${ }^{16}$ appears to be the rst tim e any explanation has been given for such period-doubling, a very com $m$ on phenom enon of period-doubling in decagonal quasicrystals. To understand the correlations of the puckering deviations (w hich create the structure in well-known layers of di use scattering seen in decagonals), yet another fram ew ork w as needed of the \puckering center", (up to)
ve mutually constrained channels around a single colum $n$ of Co atom $s$ (Sec.V III).

In this latter half of the paper, two sections are included that are not specially focused on relaxation and puckering, but which could not be form ulated in term $s$ of just the xed sites. First, in Sec VI we found that puckering drives the clusters' orientational order (which breaks the sym $m$ etry dow $n$ to pentagonal). Second, in Sec. V III we show that our approach goes a long way towards successfiully predicting the structure of the phase W ( $\mathrm{A} \perp \mathbb{C} \circ \mathrm{Ni}$ ), and in tum $W(A \perp C \circ N$ i) $O$ ens additional clues for future $m$ odeling of $A$ l- o-N idecagonals.
$M$ assive as it is, this study is still far from a de nitive answer about the $d(A \mathbb{C} \circ \mathrm{~N}$ i) structure. A though the atom ic structure we presented is unquestionably a good one, we suspect there exist com peting structures (built from sim ilar local structure) that are just as good. In part, our failure to study these is an intrinsic weakness of the initial approach via discrete site lists, when we know puckering is a key feature of the structure. But to a greater extent, it stem s from sm all m isapplications of the technique. A though we used $m$ uch larger cells for the discrete sim ulation than in previous work ${ }^{13}$, we should have used even larger cells; furthem ore, the degrees of freedom w ere too quickly reduced when we passed to a description based on 4A, or really 10.4A, tiles (Sec. IIIE) . These adjustm ents would have revealed the altemative fram ew ork based on 20A decagon clusters (A ppendix E). B ased on this experience, we anticipate that fiuture applications of the $m$ ethod $w$ ill evade these pitfalls.

In the rest of this section, we exam ine som e of the im plications or future possibilities in $m$ ore detail.
A. P itfalls of discrete site list

From some view points, one $m$ ay be surprised that constraining sites to atiling works at all, or suspicious whether it is transferable to pther quasicrystals. P erhaps it is that, in order to form a high-qually quasicrystal, the atom ic con gurations already have to be tiling-like. [T he identicallocalpattem has to be com patiblew ith di erent environm ent pattems.]

W e still believe we it was e ective to initially sim ulate using a 4.08A period, in order to discover the m ain features, and to re ne this later on. In part, this was justi ed by som e sim ulations using 8.16A periodicity, in which we saw that 4.08 A periodicity persists for a large subset of the atom $s$.

H ow ever, the dangerous step is elim inating sites: w ithout care, an unjusti ed assum ption can get built into later stages. In particular, there are subtle issues in connection $w$ ith the density $T$ he candidate site list for M C lattioe-gas sim ulations on the 4A edge rhombiwas constructed to elim inate sites that were observed to be unused in the previous stage of sim ulation using 2.45A rhombi. This is valid, so long as we retain the original com position and density in the nalm odel. U sually, how -
ever, as we grow to understand the structure better, different com positions and densities recom $m$ end them selves for the idealized $m$ odel, because the $m$ odi ed atom decoration (i) is simple to prescribe, or (ii) is favorable energetically. In the present work, the intial explorations were conducted at a density $0: 068 A^{3}$, which is a bit loosely packed, whereas the idealized $m$ odel of $F$ ig. 7 at
$0: 07 \subset A^{3} \mathrm{~m}$ ay be som ew hat overdense. Thus, when M C annealing of Fig . 7 fails to nd any better con $\mathrm{g}-$ uration, it $m$ ight be an artifact of the poverty of the candidate site list for this higher density. The moral is that the initial exploratory runs ought to be done w ith (at least) tw o densities; to ensure a conservative choice of site list in later stages, one of the densities $m$ ight be higher than the expected real one (though not too high, as that would slow dow $n$ the lattioe-gas annealing).

A lthough natural, doing (alm ost all) our xed-site sim ulationsw ith a \standard" density and com position (see Sec.IIB and IIIA equal to those of $\backslash$ basic $\mathrm{C} \circ$ " $\mathrm{d}-\mathrm{A} \mathbb{I C}$ oN i was an unfortunate choice. For one thing, the nom inal com position and density are unlikely to m atch exactly those in our ultim ate idealized decoration.) M ore im portantly, even if they do match, one cannot rely on such sim ulations to infer the appropriate site-list for later stages, since the later stages w ill explore variations in density and com position. There is a chance the preferred sites for the variation already got elim inated at the earlier stage, since they were not being occupied in the initial sm all-tiling sim ulations. Instead, the initial exploratory sim ulation should run at a density chosen higher than the expected value, indeed higher than the largest density variation to be tried in subsequent runs. (O r, even better, at densities and com positions bracketing the expected ones.)

## B. A dapting the $m$ ethod to puckering?

Yet another reason that the \basic Co" story is m ore complex is that relaxation and the form ation of \channels" that violate the layering (Sec. $V$ ) have $m$ ore dra$m$ atic e ects than they did in the \basic $N$ i" casd ${ }^{14}$. Perhaps the reason is sim ply that \puckering centers" form around colum ns of Co atom s ; they are present in both phases, but since \basic $N$ i" has half the density of C o atom s , its puckering centers are su ciently separated that their interactions are unim portant. Them ost serious issue here is that relaxation $m$ ight reverse the sign of a sm all energy di erence betw een com peting variants of the detailed atom ic structure \{ w e encountered such a sign reversalw hen com paring di erent cluster orientation orders (see TableV). Thus, one m ust w orry whether our recipe $m$ ay converge to a non-optim alansw er, having discarded the correct one in the early xed-site stages. A re there any technical w ays to inconporate puckering, while still using discrete $M$ onte $C$ arlo sim ulation? O ne may distinguish three points in our story at which one could ask for such a rem edy.

The rst point is in the in itialsm all-tile stages of C C, where we would w orry that we m ight $m$ iss a nice form of local order, due to the unphysical xed-site and layering constraints. Obviously, this should be perform ed using a four-layer unit cell, but that is insu cient by itself: if atom s cannot reduce their energy by deviating o layers, the 4A symmetry rem ains unbroken (as we veri ed by som e trials). The key to im provem ents $m$ ust be the understanding that puckering is built from an alphabet of in discrete entities \{ channels (Sec. $V$ ) or puckering units (Sec. V IIB) \{ which are put together, som ew hat as tiles are put together in a tiling.

O ne approach, at the raw 2.45A rhom bus level, is to add a correction to the H am iltonian which models the energy reduction that w ould occur under relaxation. $T$ his would have im portant negative contributions only in casesw here atom $s$ in adjacent layers are stacked nearly on top of each other (e.g., one of the \short bonds" recounted in A ppendix B 1), but are not thus constrained by other atom s on the opposite side from the close neighbor. This would have exactly the form of a three-atom interaction. T he coe cients in this e ective H am iltonian could be tted to the relaxed energies for a database of random 2.45 A con gurations.

A ltematively, we could approach the problem at the level of the 2.45A DHBS tiling (see Sec. IV B; this tiling has not yet used for M C for the present $m$ odel system .) W e found that the 2.45A HBS tiles, each centered by a C o colum n, correspond closely to the puckering units. Thus, we might inconporate e.g. 2.45A Star tiles of several di erent avors, corresponding to the comm on puckering pattems (e.g. Table V IIII). W ithin each tile, the puckering-layer A l w ould be displaced, but other A l would lie strictly in layers. This would undoubtedly be a crude $w$ ay to represent the continuum ofpossible A lpositions, but the existing $m$ ethod is $m$ uch cruder (in forcing them to lie in the layers).

A second point where we need a technical adaptation was the stage where we conducted molecular dynam ics and relaxations, to obtain con gurations such as Fig 12, or relaxed energies such as those in the right colum ns of Table $V$. We were ham pered by using starting con gurations that alw ays have the w rong num ber of atom $s$ in every channel: there ought to be three, but tw o copies of a bilayer necessarily have an even num ber (tw o or four). W e worry that the channels $m$ ay get stuck w ith random, non-optim al pattems of occupancy (see Sec.VIIA) and this $m$ ay obscure any pattem that would em erge.

At this stage, it doesn't $m$ atter greatly how well the m odel positions approxim ate the real ones, since we are not com paring energies of the unrelaxed con gurations. Instead, we just need $m$ ore of an ideal decoration $m$ odel sim ilar to Sec.IV, but having four layers, such that the two $m$ irror layers di er in places. T he $m$ odel should ad$m$ it variants, so that we could discover which rule allow s for the best relaxed results.

A nal stage where puckering should be represented has been reached in the $\backslash$ basic $N$ i" case ${ }^{13}$, but not yet
for \basic C o" : a determ in istic decoration for quite large tiles (4A or probably larger), allow ing discrete M onte C arlo sim ulations in which only these tiles were reshufed. O ne approach that was used in Ref. 36 to devise such a decoration is \constrained relaxation", whereby all atom $s$ in the sam e \orbit" (quasi-equivalent sites generated by the sam e decoration rule) are forced to $m$ ove in the sam e exact $m$ anner relative to the tiles they decorate, de ning a sort of consensus relaxation.

## C. Long-range order of the puckering pattern?

O ur structure m odel develops very robust puckerings (Sec.V) with a 8A period in the c direction. A ssum ing the $m$ otifs that we discovered and built our description on, the puckering interactions are frustrated and sensitive to the A l density and to the Niplacem ents in Star clusters, which together (see Subsec.V IIC 2) determ ine which channels pucker. T he disorder inherent to any real quasicrystalm ight introduce su cient random ness that the Ising e ective H am iltonian of Sec V IIA would be a spin glass $m$ odelhaving $m$ any alm ost degenerate $m$ inim $a$. If so, our attem pts to discover the true ground state are rather academ ic. as the realm aterialw ould probably get trapped in (som ew hat higher) $m$ etastable states.

W ithin each \channel", the correlations should extend far in the c direction; yet our tentative conclusion is that the puckering order propagates poorly within the xy plane. The consequence of this would be di use scattering concentrated into \pancakes" in thin layers close to $q_{2}==c$ and (stronger) $3=c, m$ idw ay betw een the $B$ ragg layers, but rather broad in the $x y$ direction in reciprocal space.

H ow ever, the observed di use scattering associated w th the 8A periodicity tends to show longer in-plane correlation $5^{54,55}$. In fact, $m$ any $d-A \mathbb{N}$ iC o modi cations propagate true long-range order of the puckering, as shown in di raction pattems have sharp B ragg spots in the interm ediate layers (that appear betw een the m ain layers associated with c periodicity). So, when the real m aterialdoes have long-range puckering correlations, one m ay wonder if it inchudes som em otifbeyond our $m$ odel.

In fact, the $W$ ( $\mathrm{A} \mathbb{C} \circ \mathrm{N}$ i) phase does propagate a wellordered puckering, and $m$ anages this by replacing half of the even Star chustersw ith anotherm otif, the pentagonal bipyram id (see Sec V IIIB). So, a plausible con jecture is that the PB is the $m$ issing $m$ otif which is responsible for extended puckering correlations (in the $m$ ore $C o$-rich modi cations of A l-C O-N i).

## D. Relation to decagonal A l-C o-N i at other com positions

A variety of $s m$ all-grained, apparently $m$ etastable, crystalline approxim ant phases are found alongside quasicrystals at com positions near $d\left(A h_{0} \mathrm{C} \mathrm{O}_{15} \mathrm{~N}\right.$ i $\left._{15}\right)$; it was
suggested that the presence of quenched-in vacancies $m$ ight tilt the balance to stabilize one of the approxim ants against the quasicrystal ${ }^{56}$. The di culty of determ ining stability suggests that these related phases are very close in free energy. Since the decagonal dom ain of the AlN i-C o phase diagram is bracketed by phases we studied ( $\backslash$ basic N i" in Ref. 13) and \basic C o" in this work), can we say $m$ ore about those interm ediate phases?

O ne clear conclusion ${ }^{13}$ is that special com positions are stabilized, in large part, because each species is lling a particular type of site. Thus a sm all com position di erence (density or stoichiom etry) can cause certain onbits (classes of quasi-equivalent sites) to becom e occupied or to change species. At a higher level, the interactions of these atom swill then change the tile H am iltonian of the tiles they sit on; and that can $m$ ake a big di erence in how these tiles freeze into supertiles at even larger length (and sm aller energy) scales, hence the variety ofm odi cations.

W e can speculate how changes in com position might change the whole geom etry of our structure, e.g. between the \basic Ni", 13A decagon, or 20A decagonbased structures. The heart of our understanding of the physical relationship betw een the atom ic interactions and large-scale geom etry is the 2.45A D HBS tiling of Sec. IV. There is no reasonable way to increase the frequency of 13A D s. (Recall the arrangem ents in Fig. $4(a, b)$ violated strong interactions, nam ely the TM-TM second well.) But perhaps replacing Co w ith N i in the com position would induce replacing 8 A decagons by $2: 45 \mathrm{~A}$ HBS tiles. Indeed, if w e elim inate the 13A D s altogether, this is essentially the structure of $N$ i-rich $d-A \mathbb{N}$ iC $c^{13}$. So m ight interm ediate com positions like $d-\mathrm{A}$ h $_{0} \mathrm{~N}$ i $_{15} \mathrm{C}_{\mathrm{o}_{15}}$ be described by a sm ooth gradation in which the frequency of 13A Ds dim inishes?

W e can speculate on how the inexactness of our pairpotential description $w$ ill distort the com puted phase diagram s . The fact that supertiles form $m$ eans that what decides the large-scale geom etry is the e ective tile-tile interactions ( $\backslash$ tile H am iltonian"). In this picture, over a range of com positions the sam e supertiles are valid, but the species lling certain sites on them changesw ith com position and consequently so do thee ective interactions in the tile H am iltonian. At this level of description, errors in the potential them selves w ould shift the graph of the interactions as a function of com position, but probably not change its gross shape. The corollary is that the phase diagram of our toy system $m$ ight well have the sam e phases, in the sam e topology, as the true one, but w ith the phase boundaries shifted.

A particular application is to the issue of the 20A decagon (A pp. $\mathbb{E}$ ). The m odels based on 13A and 20A decagons are very sim ilar in structure, and (not surprisingly) very close in energy. O ur view point is that both are physically relevant. Slightm odi cations of the potentials, or of the assum ed com position and density, m ight well tip the balance between these two models (or other related ones, in particular those incoporating the PB)
(Sec. V ITII) .

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## APPENDIX A:CODEAND DECORATIONS

In this appendix, we described som e technical aspects of the code. ${ }^{58}$

W ebegin with a tiling le that de nes a (2-D) unit cell in term s of $P$ enrose rhom bi. ' $W$ e then assign a scale to the unit cell, identifying the physical length of rhom bus edges as well as xing a certain periodic lattic constant betw een adjecent $P$ enrose tiling layers. T he full 3-D unit cell is then speci ed by providing the num ber of layers we w ant before periodic boundary conditions.

The decoration le speci es objects by looking for speci ed pattems (called \ob jects") in the tiling geom etry, speci cally groupings ofrhom busedgesw ith speci ed orientations relative to each other. An \ob ject" can be as sim ple as two edges at 144 from each other, or as com plicated as full decagon traced out by all interior and exterior edges. A tom ic sites can then be placed on each ob ject, and all ob jects of a given class w ill get equivalent sites.

The decoration also allow s energies to be assigned to ob jects. For exam ple, when a tile ip occurs, the energies of the atom ic interactions and the energy of any geom etry created are taken into account. W e use this option only for tiling purposes (there are no atom $s$ on our tiles when we use ob ject energies) as we search for tiling which satisfy the large scale ( $\mathrm{a}_{0}{ }^{3}$ ) binary tiling. A fter we nd such a con guration of Penrose mombi, we then use a separate decoration to create a site list.

The decoration le also lists any sym $m$ etries of the tiles and obj jects de ned therein. If an object has a re ection sym $m$ etry and the sym $m$ etry is de ned in the decoration then adding a site on one side of the ob ject will add a $m$ irror site to the other side.

It is also possible to assign a label to each vertex of a tiling through the decoration le. The label assigned is the sam e as the discrete com ponent of the penpendicular space'of a decagonal tiling. W e shall called these labels levels.

The random Penrose tiling allow s , in principle, an unlim ited num ber of levels; our other tilings typically have vertices on tw o to vedi erent levels,w hich are treated as di erent avors of vertices. For example, the HBS tiling has tw o levels ${ }^{33}$ the binary tiling has three levels;and the
original (quasiperiodic) Penrose tiling has four levels, as does the HBS tiling when the interior vertex of each tile is led in57. It $m$ akes sense to assign di erent decorations to vertioes depending on their level in the tiling, or to tiles depending on the levels of their vertices. W hen these levels are taken into account, not all rhom biof the sam e shape on our tilings are equivalent.

These levels allow m ore speci c control over the location of atom sites. In the tilings $w$ ith a bounded set of levels, there is a (statistical) sym m etry operation which com bines a 180 point rotation of the tiling $w$ th a re ection in levelspace. In our decorations of decagonals, this sym $m$ etry $m$ ay be com bined w ith a vertical shift of $c=2$ to form a kind of screw sym $m$ etry. (It is statistical in the sense that a random tiling ensemble is invariant under it although paricular tiling con gurations are not; also, it is local in the sense that clusters can be found within which the screw operation is an exact sym $m$ etry.
$T$ he sim ulation uses $M$ etropolis $M$ onte $C$ arlo ${ }^{59}$ to perform atom swaps between nearby atom $s$ or hops to nearby vacant sites (generally w ith a sm aller num ber of long-distance swaps/hops included). A novel aspect of the procedure of $R$ ef. 13 is that concurrently, tile reshuf-
ing is also perform ed: this means a hexagonal con $g$ uration of three rhom bi (two thin and one fat or vice versa) is rearranged. T he tile reshu ing has the e ect of a num ber of atom Sw aps and $m$ oving atom ic sites around. B ecause a tile ip generally causes a large change, its acceptance rate is relatively low and virtually nil at low er tem peratures. T he low acceptance rate causes the tiling to freeze at low tem peratures.

A variety of other $m$ ethods w ere used to alter and test certain aspects of the sim ulations in a controlled $m$ anner. $T$ his included, but is not exchusive to a) a series ofm anual swaps, b) m anual tile ìps, c) analysis of atom ic pair distances and pair potentials along with site energies to determ ine frustrated sites, and d) direct modi cation of data les to obtain custom con gurations.

## APPENDIX B:TESTS OFCLUSTER-CLUSTER GEOMETRY

This appendix reports tests perform ed to elim inate various possibilities in Sec. III, nam ely short bonds and altemate cluster linkages (Sec.IIIC) . W e treat these as technicalities since they do not enter our nalm odel.

## 1. Short bonds

A notew orthy issue in our simulation was the \short bond", an A l-C 0 in adjecent layers, with an xy displace$m$ ent of ${ }^{2} a_{0} \quad 0.935 \mathrm{~A}$, hence a total separation of 2245 A . This is so short as to be up against the hardcore of the pair potential $V_{A 1 c} \circ(r)$, hence questionable. Indeed, in A l-TM quasicrystal-related alloys, som e exceptionally short A l-TM bonds have been notioed for a
half-century ${ }^{60}$ : in particular, A -C o pairs exist in $\mathrm{A} \mathrm{I}_{5} \mathrm{C} \mathrm{O}_{2}$ at 2.34 A and in $\mathrm{Al}_{3} \mathrm{CO}_{4}$ at 2.25A. But our pair potentials are not very trustw orthy when the closeness of the cores enhances covalent e ects. $W$ e still suspect that our short bonds are artifactual as for as our sim ulation potentials are conœmed; the short bonds appearing in nature have a som ew hat di erent explanation.

A m ost every con guration from the initial sim ulation stage using 2.45A tiles contained som e A l- 0 o short bonds; they could appear in any ring of the 13A D, but are particularly problem atic in ring $2.5 /$ ring 3 where A 1 positions deviate from sym $m$ etry in any case. O ur initial guess w as that the short bonds w ere artifactual, being our lattice gas's attem pt to approxim ate a m inim um -energy position that actually fellbetw een tw o discrete candidate sites. T herefore, our canonical 4.0A -tile decoration om itted candidate sites that allow short bonds.

H ow ever, as a variation we did augm ent the 4.0 A -tile site list so as to allow short bonds $w$ ith ring $2.5 /$ ring 3 Al . W hen we tested this in the 23324 unit cell, about ve short bonds appeared in each sim ulation run, furtherm ore the totalenergy w as lower than in the 4.0A tile sim ulations w ithout short bond sites. That would suggest the short-bond Al positions are approxim ating the true relaxed positions better than the non-short-bond sites did.

W hen relaxation was perform ed (Sec. V A 1), shortbond A lC o distances increased, while non-short-bond A I-C o distances decreased. The relaxed con gurations were still distinguished, in that (w ith a sm all sam ple of three runs), the energy w ere higher (w orse) when relaxed from the short-bond con guration; in other words, under pure relaxation w thout M D annealing, the A latom sapparently get stuck in shallow localm inim a. On the other hand, after $\backslash R M R$ " sim ulation (in a unit cell of periodicity 2c, as in Sec. V A 2 seem sto reach the deeperm inim a: initial short-bond or non-short-bond con gurations gave results indistinguishable in energy and con guration ( $m$ odulo some e ectively random choices of which direction to pucker).
$T$ he short bonds are $m$ ost clearly understood using the fram ew ork introduced in Sec.V C of \channels" \{ approxim ately vertical troughs in the potential function for an A latom. If an A l-A l hardcore distance of $2: 8 \mathrm{~A}$ is enforced, there is room for just two A l per four layers on the xed sites, or three A l per four layers once puckering is allowed. The \short-bond" observations in bilayer
xed-site sim ulations suggest it $m$ ay after allbe tolerable to place four A l per four layers (in preference to the sites where the A lw ould otherw ise be forced to go, at the A l density being assum ed).

W e conclude that allow ing short bonds in sim ulations does not help us to capture the true order any better.


FIG. 15: Test of the overlapping linkage in F ig. 4 (a). T ile edgesm arked are 4A long; heavy edgesm ark 13A decagons(or 4A-edge Star and Boat tiles that 11 the space between 13A D s). A tom colors indicate species as in Fig. 2 B lue and red circles indicate $T$ hin red arrow s, fat red arrow, and blue arrow indicate hypothetical linkages of length ${ }^{3} a_{R}$, 1:176 ${ }^{2} a_{R} R$, and $\overline{5}^{2} a_{R}$, respectively.
2. O verlapping cluster-cluster linkage?

As a test of the overlapping linkage in Fig. प(a), we made use of the 4A decoration of Sec. IIIE, using the tiling shown in Fig. 15 which violates the binary-tiling rules for placing the clusters. Only three 13A decagons(indicated by circles) are de ned by this tiling (four nom ally $t$ into this cell); the extra space has been lled by $\mathbb{A}$-edge Stars, B oats and H exagons.

The gure shows a typical con guration that form ed at low tem perature. A fourth 13A decagon has spontaneously m aterialized on a grouping of a 4A-edge Star tile and tw o H exagons in the upper left comer. The outer border of th is tile chuster form sa decagon, but its interior (and the associated site list) lacks decagonal sym m etry, forcing ring 1 to form w ith a sm allm istake.

N ow, the red circle in F ig 15 show s an altemative place where the site list would have allowed a 13A decagonto appear instead, overlapping as in $F$ ig. 4 (a) w ith two other 13A decagons; indeed, w ith the tiling show $n$, the site list in fact favors this altemative location. H ow ever, in a few tries of this sort, that cluster w ith the overlapping linkage never form ed.

The blue circle in $F$ ig. 15 show $s$ another hypothetical cluster location form ing a di erent linkage as indicated by the thick red arrow. It corresponds to edge sharing by the 2.45A -edge decagons; in this case, the 13A D overlap form s a thin 4A Hexagon.

A nother test involved the simulations on the the 20384 tiling $m$ entioned at the end of Subsec.IIIC. A fter short-tim e anneals on the sm all 2.45A tiling, the con gurations contained $m$ any $A \not \mathrm{ZTM}_{5}$ (ring 1) m otifs, but the 13A decagonsw ere in perfect and often interpenetrating, in contrast to the good ordering observed after


FIG.16: Test of the \mom bus diagonal" linkage in F ig. (4) (b). The rhom bus center is just below the cell's upper-right comer (the fourth decagon, seen at lower-right comer; its copy by periodic boundary conditions is outside the upper fram e.)
sim ilar annealing on the 3223 tiling. H ow ever, such con gurations were 2 eV ( $0: 02 \mathrm{eV} /$ atom ) higher in energy than the 3223 tiling best energies. Furtherm ore, after 5 qpu hours of high-tem perature ( $\mathrm{T} 0: 5 \mathrm{eV}$ ) annealing, these sam ples evolved to a proper con guration of 13A decagons, which was in fact lower in energy than on the 3223 cells ( $w$ ith the sam e volum e and atom content).

## 3. R hom bus cluster-cluster linkage?

$N$ ext we test the linkage shown in $F$ ig. 4(b) In the 3223 cell, w th content $A \nexists_{45} \mathrm{Co}_{41} \mathrm{~N} \mathrm{i}_{21}$ (hence density $0.0682 \mathrm{~A}^{1}$ ), a follow up xed-site simulation was done, using the standard site list which avoids short A l-Co bonds. Three di erent $\mathbb{A}$-edge tilings w ere tried, each w th four 13A D sspeci ed per œell. O ne of these tilings ( $F$ ig. 16 has four clusters at the vertices of a Fat rhom bus. Its energy is roughly $2 \mathrm{meV} /$ atom higher than the others. (W e averaged this di erence over the two cases where the 13A D center orientations are all the sam e and where they are altemating). Since there is one $1.176 \mathrm{~b}^{\infty}$ linkage in that cell, this am ounts to a substantial cost of roughly 0.4 eV for each such linkage.

## APPENDIX C:OPTIMUM CONFIGURATION IN CHANNEL:ANALYTIC CALCULATION

$T$ his A ppendix augm ents the $m$ athem atical details of the story in Sec. V C, which are all consequences of the
form ofA lpotential function $U(z)$ in a channelasw ritten in Eq. (3). W e assum $e$ the channel has three atom $s$, and derive the consequences.

1. Three-A l collective coordinate and localm irror layer

The $m$ ain freedom of the three A latom $s$ in a channel is the collective $z$ coordinate $z$. Let the respective A l positions as

$$
\begin{equation*}
z_{m}=(2 c=3) m+z+u_{n} \tag{C1}
\end{equation*}
$$

$w$ ith $u_{m+3} \quad u_{n}$, and constraining ${ }^{P}+1{ }_{m=1} u_{m}=0$. [T he m ean displacem ent is accounted in the collective coordinate z.] The total energy (per Al) i 82

$$
\begin{equation*}
\text { E } \quad \frac{1}{3}_{m=1}^{X^{1}} \mathbb{U}\left(Z_{m}\right)+V\left(Z_{m}+1 \quad z_{n}\right): \tag{C2}
\end{equation*}
$$

W ewant to nd the best energy, given that $z$ is $x e d$ at a certain value. Taylor expanding C 2 to second order in $f u_{m} g$ yields

$$
\begin{gather*}
E=E_{0}+\frac{1}{3}_{m=1}^{X^{1}} \mathbb{U}^{0}\left(z+\frac{2 c}{3} m\right) u_{m}+  \tag{C3}\\
U^{\infty}\left(z+\frac{2 c}{3} m\right) u_{m}^{2}+V^{\infty}\left(\frac{2 c}{3}\right)\left(u_{m}+1 \quad u_{n}\right)^{2}
\end{gather*}
$$

where $E_{0} U_{0}+V(2 c=3)$. If we om it the $U_{c}$ term in (3), the $m$ inim um of the quadratic form (C 4) is ${ }^{63}$

$$
\begin{equation*}
E(z)=E_{0} \quad \frac{1}{6} \frac{B_{U}^{2}}{K_{V}^{2} K_{U}^{2}} K_{V}+K_{U} \cos \frac{12}{c} z ; \tag{C4}
\end{equation*}
$$

Where $K_{V} \quad 3 V^{\infty}(2 \mathrm{c}=3) \quad \mathrm{K}_{\mathrm{U}} \quad(4=\mathrm{C})^{2} \mathrm{U}_{\mathrm{C}=2}$, and $\mathrm{B}_{\mathrm{U}}$ $\overline{3=2}(4=c) U_{c=2}$. T he e ective potential $\mathrm{E}(\mathrm{z})$ in general has a period $c=3$, one-third of the unit all periodicity, since sliding the A l chain by $2 \mathrm{c}=3 \mathrm{w}$ ould m ove each A l atom to the old position of its neighbor, and additionally the potential is invariant under a shift c. IT he period in Eq. ( 4 4 is $\mathrm{c}=6$, not $\mathrm{c}=3$, since we assum ed as a simpli cation that $U(z)$ has period $c=2$, not $c$.] Them inim um con guration can be written $z=0$ or $c=2$, with $\mathrm{u}_{1}=\mathrm{u}_{1}$ and $\mathrm{u}_{0}=0$, so the channelhas a localm irror layer at $z=z$.

A though the local minim a of (3) as a function of the single-atom $z$ are quite strong, the e ective potential $E(z)$ is $m u c h$ atter as a function of the collective coordinate, since the three atom $s$ are constrained to sam ple di erent, counterbalanced parts of the potential. O ne can quantify $\backslash m$ uch atter", using the assertion above that Al-A linteractions are stronger (w ithin a channel) than the Al potential due to A l-TM interactions. i.e. that $U^{\infty}(2 c=3)=V^{\infty}(2 c=3) \quad K_{U}=K_{V} \quad 1$.

This im plies via (C4) that the ratio of the energy variations of the collective to those of the one-body potential is $E(z)=U(z) \quad\left(K_{U}=K_{V}\right)^{2}$. Thus, it is conceivable that the A latom $s$ in each vertical channel have, at $m$ oderate tem peratures, considerable freedom to uctuate (collectively) in the $z$ direction.

## 2. Further sym m etry reduction by TM -rich layer

$W$ e now address the role of the $U_{c}$ term in eq. (3). It often happens that (in the language of the 4.0 A tiling) there are two tile edges form ing a 72 angle, w ith a Co colum $n$ over each of the three vertioes, and channels on both the $m$ id-edges. (For exam ple, this can involve ring 1 and ring 3 Co atom s in the 13A D). From the view point of one channel, one Co colum n is distant and breaks the $\mathrm{c}=2$ periodicity: this is the justi cation of the last term in (3). To explain the sign of that term, note that if an A lin the channel is in the sam e layer as a distant C 0 , the separation is $R=3: 80 \mathrm{~A}$, close to a local maxim um of the A l-C o potential, whereas if Al is o set by one layer then $R=4: 47 \mathrm{~A}$ to the distant $\mathrm{C} \circ$ atom s , close to a local $m$ inim um (see Table I).

Now consider the implication for the collective coordinate, when we include the $U_{c}$ term of (3). That $w$ ill generate an additional contribution to $E(z)$ of form
const $\cos \frac{6}{c} z$. A s it tums out, the sign of this term favors the $m$ irror atom to sit in the same layer as the distant column of TM atom $s$ (this is reversed from the layer preferred by the single-atom potential). Sim ulations show it is favorable for the atom occupancies to arrange them selves such that one layer of the tw o layers is richer in TM, which causes the puckering to develop such that this layer is a m irror layer globally. T hat is directly associated w ith the long-range order of decagon orientations (Sec. VII) and of puckering VII.)

## 3. Transverse displacem ents in channels

In the above account, the displacem ents of A latom s in channels to balance the \extemal" A l potential w ith A l-A lrepulsionsw ere represented aspurely in the $z$ direction, only to allow a transparent analytic description. A $m$ ore exact analysisw ould need to consider the transverse variation of the potential trough, for the A I-A 1 repulsion obviously should be based on the total A l-A l distance, and not just its $z$ com ponent. In fact, the transverse undulation of the channel (bottom) line as a function of $z$ [see Fig. 11(a)], as well as the xy deviations of the atom $s$ from the channel line, $m$ ay well $m$ ake a contribution to the totale ( $z$ ) com parable to the dependence in (C4). For exam ple, to $m$ ake all three A l-A 1 separations be equalat $R=2: 87 \mathrm{~A}$, the puckering displacem ent must be (c R)=2 $=0: 645 \mathrm{~A}$, and the xy di erence betw een the puckered-layer site and the $m$ irror-layer site should be $\overline{R^{2} \quad \text { (c } \quad R=2 \gamma}=0: 90 \mathrm{~A}$. For com parison,
the channel's extrem es are practically on ideal sites, separated in the xy direction by ${ }^{2} a_{0} 0: 94$. The actual xy displacem ent would be only $2 / 3$ that $m$ uch if A lare assum ed to stay on the bottom line, where the latter is approxim ated a \saw tooth" pattem of straight segm ents and the Al z com ponents are approxim ated as equally spaced.

## APPENDIX D: LABELS OF PUCKERING

 PATTERNSIn this appendix, we give detailed ways to label and enum erate possible con gurations of a puckering unit (the short labels w ere explained in Sec. V IIC 1) .

To exhaustively specify the puckering con guration around the center, we list the m irror-layer A 1 atom s , giving the angular placem ent 1 of each [m eaning angle ( $2=5$ ) 1], and its puckering sense ( + if found in $m$ irror layer 0 , or if in $m$ irror layer 2 ): The zero angle is de ned as the shared 13A D edge (for type A puckering unit) or the ray through the 13A D center (for any type B puckering unit). An integer-plusthalf angle is a $\backslash \mathrm{m}$ erged" channel site, as discussed in Sec.VIIB. T he constraints on these sequences are (i) two atom $s$ in the sam e layer m ust di er in angle by at least 1.5 steps; (ii) for every $l=0 ;::: ; 4$ at least one atom $m$ ust either have that 1 , or else have $10: 5$.

The short nam eofa $B$ pattem can have a parity superscript $\backslash+$ " or $\backslash$ " added, $m$ eaning that the atom $s$ at (or near) angles 1 and 4 (on the 13A D edges) have the sam e or opposite puckering sense, respectively: this indicates how the puckering sense propagates around the 13A D. A swe noted in Sec. V IIC 1, the parity is com m onest, suggesting $J^{\text {puck }}$ is \antiferrom agnetic" for second nearest neighbor channels around a puckering unit øenter. A straightforw ard explanation w ould be that the ideal sites ofm irror-layerA latom s , tw o angle steps apart, are separated by $2 \sin (=5) \quad{ }^{1} a_{0} \quad 2.88 \mathrm{~A}$, which is close enough that the A l-A l repulsion is signi cant. In an \A " pattem, the parity is unde ned, since it would be + on one of the 13A D s and is on the other one. (T hat follow s since the m irror-layer A 1 atom s at angles 2 and 3, over the unshared 13A D edgesm eeting at the vertex, alw ays have opposite puckering senses.)

Som e com m on arrangem ents are listed in T able V III. The two standard kinds of \crooked cross" appear here as $\backslash p 4^{+}$" (one arm aligned radially and the other tangentially) , or $\backslash p 4$ " (arm s about 45 from the radial axis). ( $T$ he p4 pattem in the $\backslash \mathrm{A} "$ environm ent is a $\backslash$ crooked cross" which, when labeled as if on an unshared vertex, would be p4 ${ }^{+}$from one cluster's view point and p4 from the other's.) The comm on A (p5) pattem could be described as another way to resolve the frustration of the puckering sense. As in Subsec. VIIB), im agine we altemate puckering senses around the ve channels, necessarily w ith one adjecent pair having the sam e sign. Instead of $m$ erging these atom $s$, keep all ve and acco-


TABLE VIII: Com m on puckering pattems.
$m$ odate the steric constraint by displacing one of them by half an angle step.

## APPENDIX E:20A DECAGON MODELS?

In this appendix, we com pare our results to three recent experim ent-based structure m odels, all based on som e sort of 20A diam eter decagon (the rst two being sim ilar to the Burkov cluster of Subsec. IV F). W e then report on a trial sim ulation of our ow $n$, using the $m$ ethods ofSec IIIbut w ith an enriched site list for the lattioe gas, from which a 20A decagon packing em erges that is com petitive in energy w th the 13A m odel developed in this paper.

## 1. Structure m odels based on PD 4 approxim ant

A fter most of our work was completed, a tentative structure solution appeared for the approxim ant PD 4 of the Co orich phase ${ }^{65}$ w ith nom inal com position $\mathrm{Al}_{2: 5} \mathrm{Co}_{18} \mathrm{~N} \mathrm{i}_{9}: 5$. The c projection (see their F ig. 3) clearly show $s$ an arrangem ent of decagonal clusters of diam eter 20A (larger than the 13A decagon by exactly the factor ). This 20A cluster appears practically the sam e as the Burkov cluster which \{ as we explained in Subsec. IV F \{ appears in our structure $m$ odel. $N$ am ely, this decagon has rings 1,2, and 3 like our 13A D ofSec.IIIB; their ring 3 Al show deviations into ring 2.5 , sim ilar to what occurs in our structures. In half of their clusters, ring 1 is $m$ issing a couple of A latom $s$; these have $m$ ore irregularity of their ring $2.5 / 3 \mathrm{~A}$ latom s .

The big di erence is that, in PD 4, the 20A decagons do not overlap; instead, they decorate a Fat rhom bus with edge 10.4A. Thus, the cluster-cluster linkages in this m odel are of length ${ }^{3} \mathrm{a}_{0}=10: 4 \mathrm{~A}$, for 20 A decagons sharing an edge, or $1: 176{ }^{3} \mathrm{a}_{0}=12: 2 \mathrm{~A}$, for 20A decagons related by the short diagonal of a Fat rhom bus. It m ay also be noted that the cluster orientation pattem in PD 4 is nether \ferrom agnetic" nor \antiferrom agnetic"; this would suggest that (in term sofSec. VI the 12 2A linkage induœes an \antiferrom agnetic" interaction.

A lthough the \Star cluster" $m$ otifs no longer sit at vertioes of this 19.7A edge network, that atom cluster is
still in evidenc. The di erence is that in the PD 4 structure, every 13A D is encircled by ten such Star clusters, whereas this num ber was sm aller in ourm odel of $F$ ig. 7 . The PD 4 atom ic structure, like the rigid-site-list m odels of Sec. IV, can be decom posed into a DHBS (D ecagonH exagon-B oat-Star) tiling w th edge $\mathrm{a}_{0}=2: 45 \mathrm{~A}$.

In fact, a decagonalm odelbased on PD 4 is a concrete exam ple of the structure $m$ odels interm ediate betw een the \basic $N$ i" decoration of Ref. 13 and the decoration of our Sec. IV. Such a hybrid model would have 8A decagons, which are absent in the form er decoration, but have a larger proportion of 2.45A HBS tiles than in the latter decoration. (In particular, every edge of the 20A decagon is the centerline of a 2.45A H exagon, decorated typically by a N i-N ipair.) W e expected such an interm ediate $m$ odelto be favored at an interm ediate com position such asA $h_{0} \mathrm{Co}_{15} \mathrm{~N}_{1} \mathrm{i}_{5}$, but the energy di erences are quite sm all, so it m ay wellbe com petitive at the com positions the present paper focuses on.

## 2. Structure model from $A l_{11} N i_{22} C O_{7}$ approxim ant

A nother decagonal approxim ant was discovered with com position $\mathrm{Al}_{1} \mathrm{~N}_{22} \mathrm{C} \mathrm{O}_{7}$, close to the \basic N i" phase, and a structure $m$ odel developed based on electron di raction and $Z$-contrast im aging ${ }^{66}$. This m odel consists of edge-sharing 20A decagons of the kind we have been describing. They have $A I_{6} \mathrm{TM}_{5}$ cores, altemating in orientation (the cluster netw ork happens to be bipartite). There are no ring 2.5 A l ; about half the edges of the 13A decagons (contained in the 20A one) have two ring $3 \mathrm{~A} l$, the other half of the edges have only one ring 3 Al. The edges of the 20A decagons, w thout exception, have two TM atom s.

A good intenpretation of the cluster netw ork in Ref. 66 is that the 20A (edge 6.4A) decagons occupy the Large sites of a B inary tiling w th edge 16.8A, while pentagonal bipyram ids (PB s) occupy the Sm all sites. The vertioes of the 20A decagons, as in the PD 4 m odel, are occupied by m otifs like the Star cluster. Such Star clusters also occur betw een pairs of adjacent PBS. There, they de ne additionaltile vertiges which divide the area betw een the 20A decagons into H exagons, B oats, and Stars w ith edge 6.5A.

> 3. Structure m odelbased on $W$ (A $1 \mathrm{C} \circ \mathrm{N}$ i) approxim ant

D eloudiet a ${ }^{249}$ have presented a structure $m$ odel (formulated in a 5D-cut fram ew ork) for the same Co-rich com position we address here. They form ulate a 20A pentagonal cluster, which is built around the W -phased pentagon cluster; these can overlap in various ways. T he A $1 / T M$ assignm ents in the $m$ odel are based entirely on those reported in Sugiyam a's W (A IC oN i) re nem ente.

Exam ination of their $F$ ig. 1 reveals the relation between their chister and our 13A decagon motif. Take each vertex of their 20A decagon that is not a vertex of the inscribed large pentagon, and draw an arc around it through the adjacent decagon vertices (w hich are vertioes of the inscribed pentagon); this arc encloses $3 / 10$ of a 13A decagon. Their m odel, being based on a stacking period 2c 8 A, accom odates not only the pentagonal bipyram id (PB), but also the puckering of the A latom s we called ring $2.5 /$ ring 3 (orbetter, channelatom $s$ ) along the arcs just $m$ entioned.

In $F$ ig. 3 (a) ofR ef. 49 it can be seen that 13A decagons, although not recognized at all in their form ulation, are naturally generated in the interstioes betw een the large pentagons. The overall pattem could be decribed as a packing ofedge-sharing 32A super-decagons (in ated by one factor of ), w ith PBs placed on the super-decagon centers and odd vertioes, and 13A decagons on the superdecagon even vertioes. (It is not surprising to nd descriptions on di erent length scales: their model, being essentially a decoration of the quasiperiodic $P$ enrose tiling, acquires its in ation sym $m$ etry.)

W equestion whether the details of this m odelare good energetically. O ur study suggests that good $m$ odels are built by com binations ofthe 8A decagon (the centralpart of the 13A decagon), of 2.45A edge HBS tiles, plus the PB. To the extent that this m odel appears to have incom plete fragm ents of the 8A decagon, we suspect it will have an increased energy. It is conceivable that only A l atom s are w rong, and the TM atom s are correctly placed, which would still give good agreem ent w ith electron $m$ icrographs of all kinds.

The 13A decagons show up prom inently in the experi$m$ entalHAADF-STEM im age ofR ef. 49 (their Fig. 3 (b)) as white pentagons, alloriented the sam e way. These are not as frequent as they would be in the decoration of our Fig. 7 , suggesting that our $m$ odel is not correct for that com position.

## 4. P relim inary sim ulations w ith 20A clusters

Fig. 17 show s an exploratory xed-site lattioe-gas sim ulation on a 4A tiling in the $32 \quad 23$ all, sim ilar to Sec. IIIE, but w ith a richer set of candidate sites decorating the tiles, and a much longer annealing tim e. Two 20A decagons are seen in this con guration, in place of the four 13A decagonsthat typically em erged in ourm ain sim ulations. The atom ic structure is quite sim ilar to those described above; a $m$ inor di erence is that every edge of the 13A decagon has exactly one ring 3 Al , and their placem ent altemates perfectly. (T hat altemation w as necessarily disnupted in our m odel of Sec. IV, wherever the 13A D's shared edges.) A lso, the edges of the 20A decagon are not only N i-N i, but often A LC o or N iCo in Fig. 17. It w ould take much m ore work to settle the optim um decoration of these sites, and the optim um atom content for a decoration based on such con gura-


FIG.17: Fixed-site sim ulation in which 20A decagonsem erge.
tions.
The 20A based con guration of F ig 17 is low er in energy by $1.8 \mathrm{~m} \mathrm{eV} /$ atom as com pared to the best result of the 13A sort produced by our 4A sim ulations, if ideal-site con gurations are com pared. H ow ever, after the RMR protocolin an 8A cell (see Sec.V), the 20A type structure was slightly higher in energy, by $0.6 \mathrm{~m} \mathrm{eV} /$ atom, than the 13A type structure. (T he latter probably contains m ore A lchannels, and thus o ers m ore opportunity to reduce energy by puckering.)

## 5. W ays our approach can $m$ islead

FROM em ail: m vic-colong-disc.out0622)
O verall, it is our im pression that \{ despite the de ciencies (known and still unknown) in our potentials, the biggest problem for achieving a correct structure is the search pathway to nd it. On the one hand, we think our $m$ ethod has been rem arkably successful at predicting characteristic features such as the appearance of the 13A decagonin Corich com positions.

On the other hand, we have recounted four ways in which our procedure $m$ isled us: (i) the xed site list (ii) the 8 A periodicity (iii) the possibility of a larger cluster than 13A D (iv) the cluster orientation order

A separate note is that our calculations are good only to predict stability between sim ilar decagonal approxim ant structures. $M$ any de ciencies of our potentials \{ the dependence on electron density (and hence on com position, in principle); inaccuracies in the nearest-neighbor TM -TM and TM -A l potential wells; cuto $s$ at som e interaction radius; om ission of three- or four-body term $s$; and poor handling of vacancies \{ w ill tend to cancel, in such a com parison. But any phase $m$ ay, of course, be preem pted by a coexistence of tw o dissim ilar phases that happens to have a slightly low er energy; our pair potentials are m ore likely to give a w rong answ er in this situation. To construct a globalphase diagram, it is necessary
to follow up the kind of search described in this paper, by ab-initio totalenergy calculations, $w$ ith an attem pt to im agine all possible com peting phases and include them in this database. Since it would be prohibitive to try
out a large set of candidate structures w ith the ab-initio codes, the present sort of study is a prerequisite to the phase-diagram studies.

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51 O bserve how the ring-1 A l well extends in the xy plane outw ard from the cluster center (in the Star clusteras well as 13A D). helping explain shifts in the position under relaxation (subsec. V A 1), and predicting an anisotropic D ebye $W$ aller factor in di raction experim ents ow ing to uctuations in that well.
52 If we sim ply take the idealized m odel of F ig. 7, and rotate every altemate 13A D core by the 10-fold screw axis w ithout any otherm odi cation, the energy increases by by

1 eV per cluster. This con m show the ring 3 and Star cluster atom s adapt to various 13A D orientations so as to $m$ ake them nearly degenerate.
${ }^{53} \mathrm{~N}$ ote that $=1$ is not the sam e as the variable $=1$ that was de ned in Sec. V C and used in A ppendix C. In fact, the f $g$ are well-de ned only if certain layers (w hich we called 0 and 2) are $m$ irror layers globally, and that happens only when takes the same value everywhere. In term s of the collective coordinate $z$ de ned in eq. C 1 to param etrize the sliding of three Alatoms in a chan-
nel, we could say $\quad \cos \frac{6}{c} z$, whereas (assum ing a rst
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